

# Numerical study of the influence of ion-induced electrons on the dynamics of electron clouds in gyrotron-like geometries

S. Guinchard<sup>1</sup>, G. Le Bars<sup>2</sup>

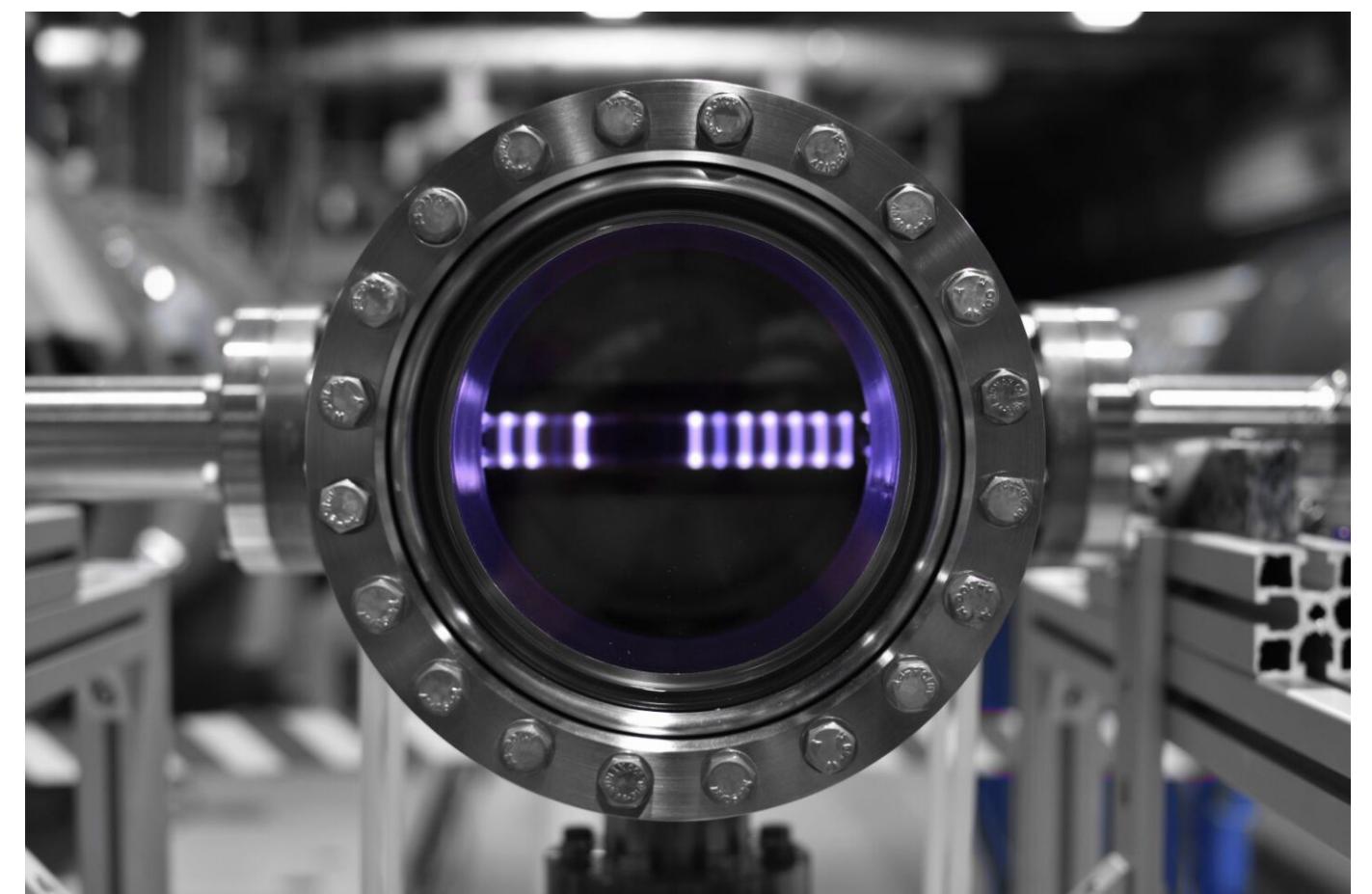
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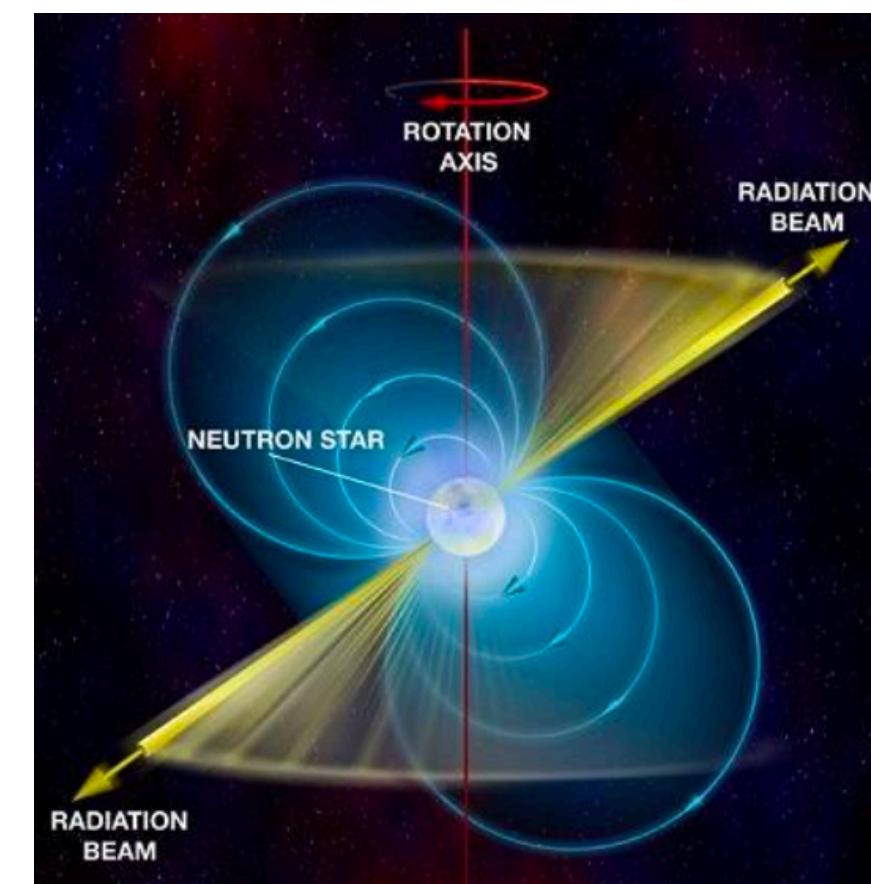
<sup>2</sup> Ecole Polytechnique Fédérale de Lausanne (EPFL), Swiss Plasma Center (SPC), CH-1015 Lausanne, Switzerland

- Introduction
- II - Theory
  - Choosing a model
  - Implementation
- III - Results
  - Module testing
  - Cloud formation and dynamics
    - TREX *slanted*
    - TREX *extrude*
    - GT-170
- Conclusion

- Collection of charged parts s.t. overall no charge neutrality [DS]
- Non-neutral plasmas relevant to many fields of physics: Astrophysics, atomic clocks, particle accelerators, surface engineering & **ECRH**.
- Electron Cyclotron Resonant Heating, for which **gyrotrons** are needed.



C sputtering in a plasma cell [Cern]



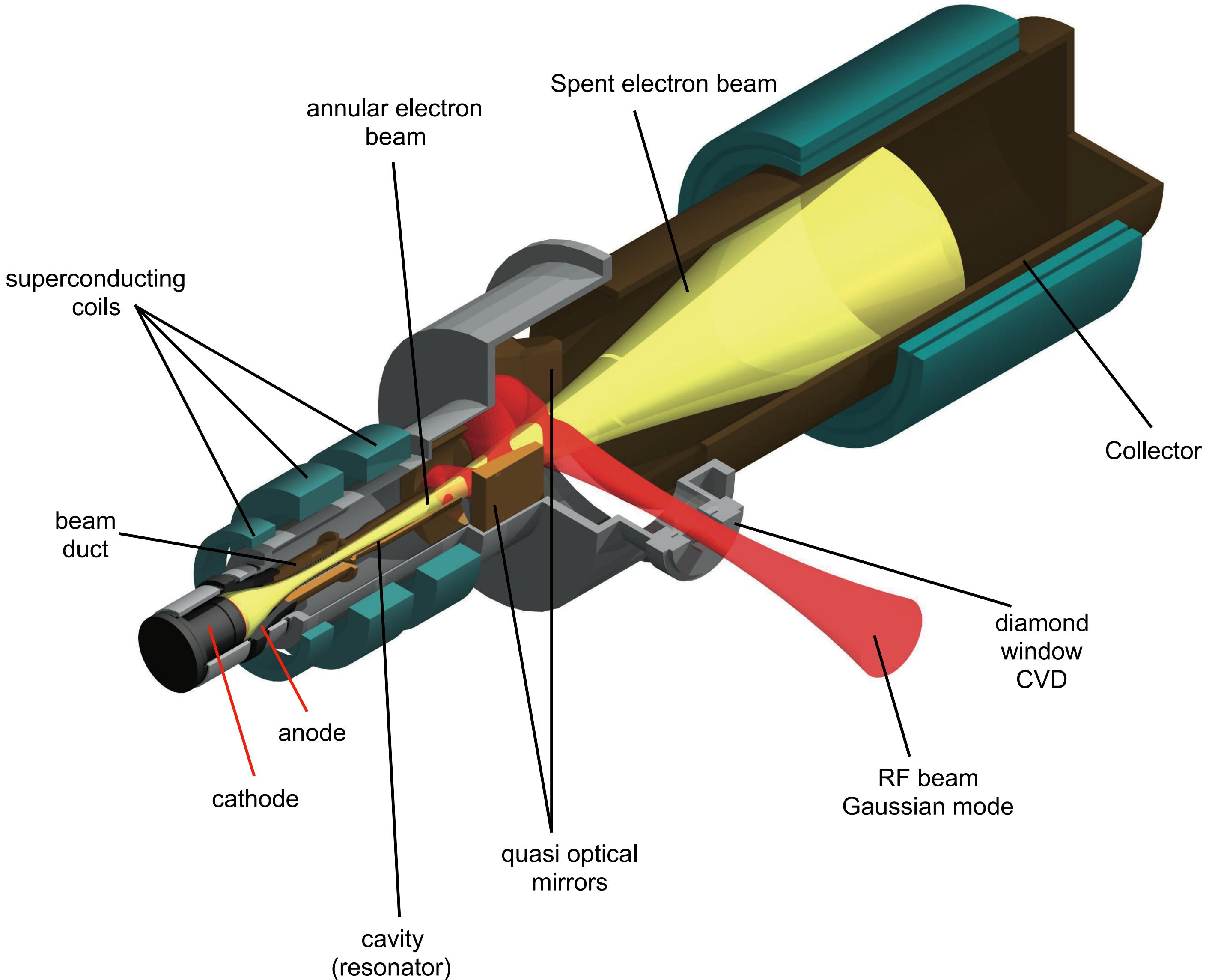
Neutron star  
magnetosphere



TCV gyrotron for ECRH

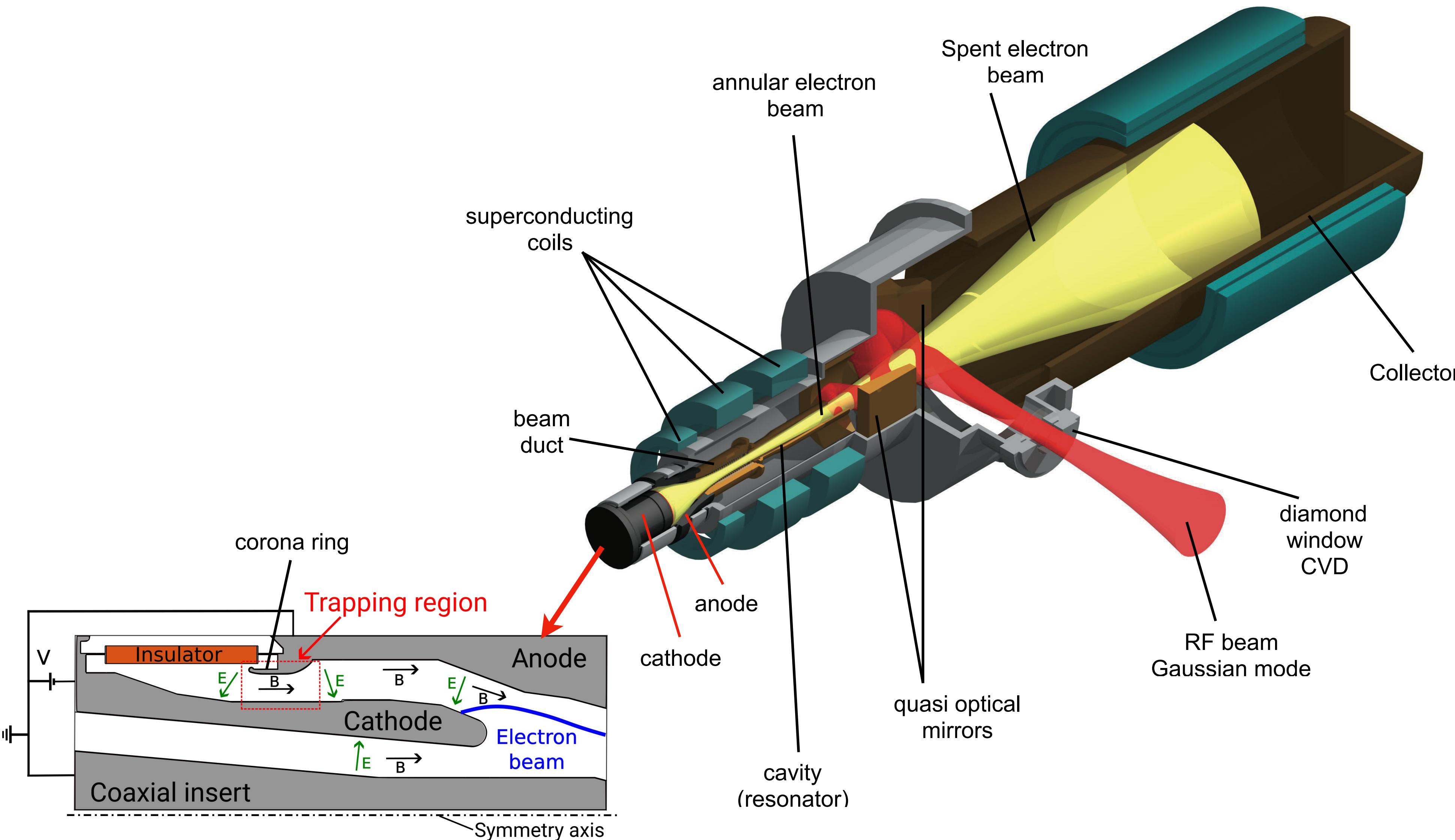
# EPFL Introduction - The gyrotron as a high power mm wave source

- Micro-waves for ECRH
- 1 MW, 170 GHz continuous beam
- 24 1MW gyrotrons for ITER ECRH



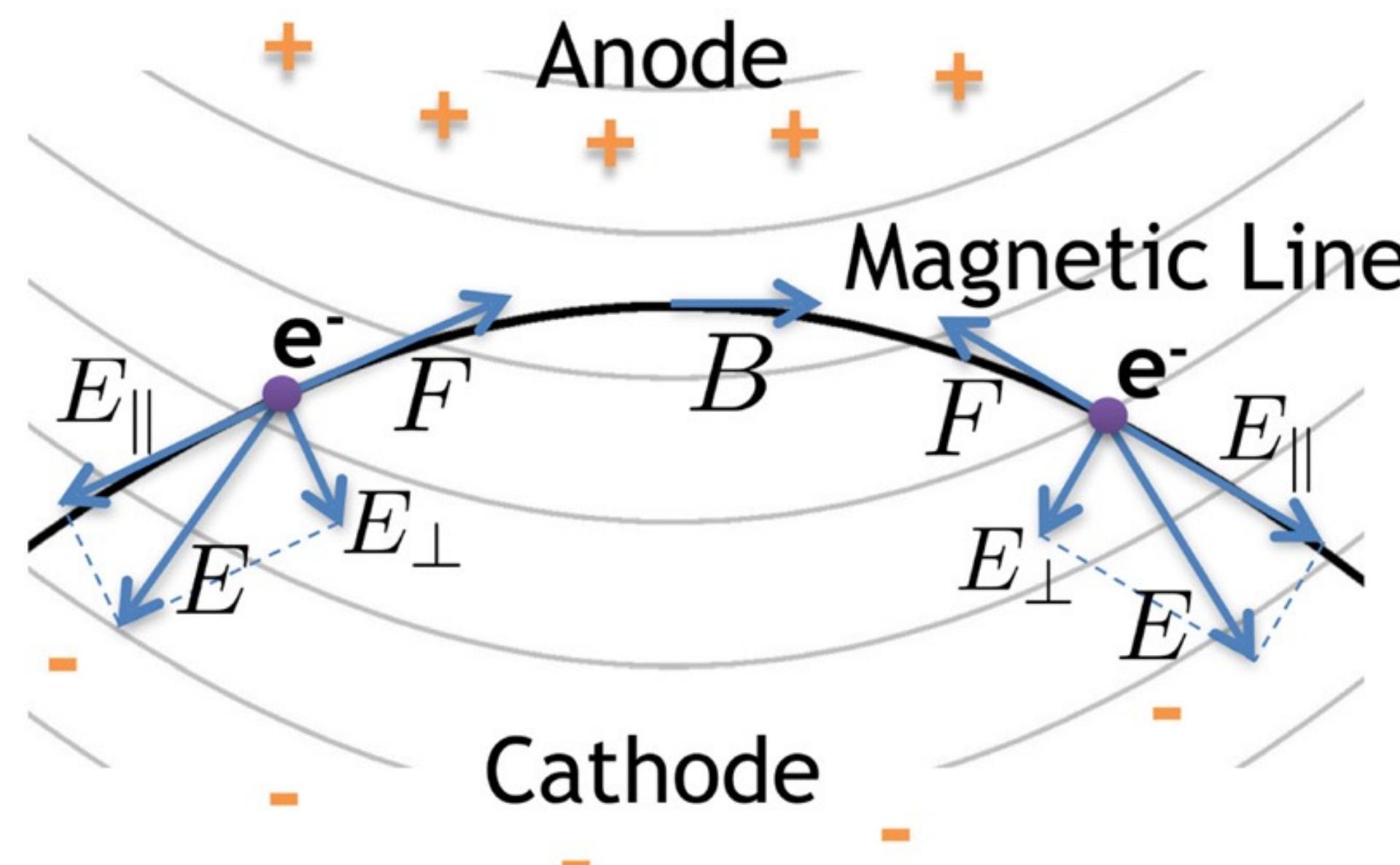
Source: Courtesy of S. Alberti

# EPFL Introduction - The gyrotron as a high power mm wave source



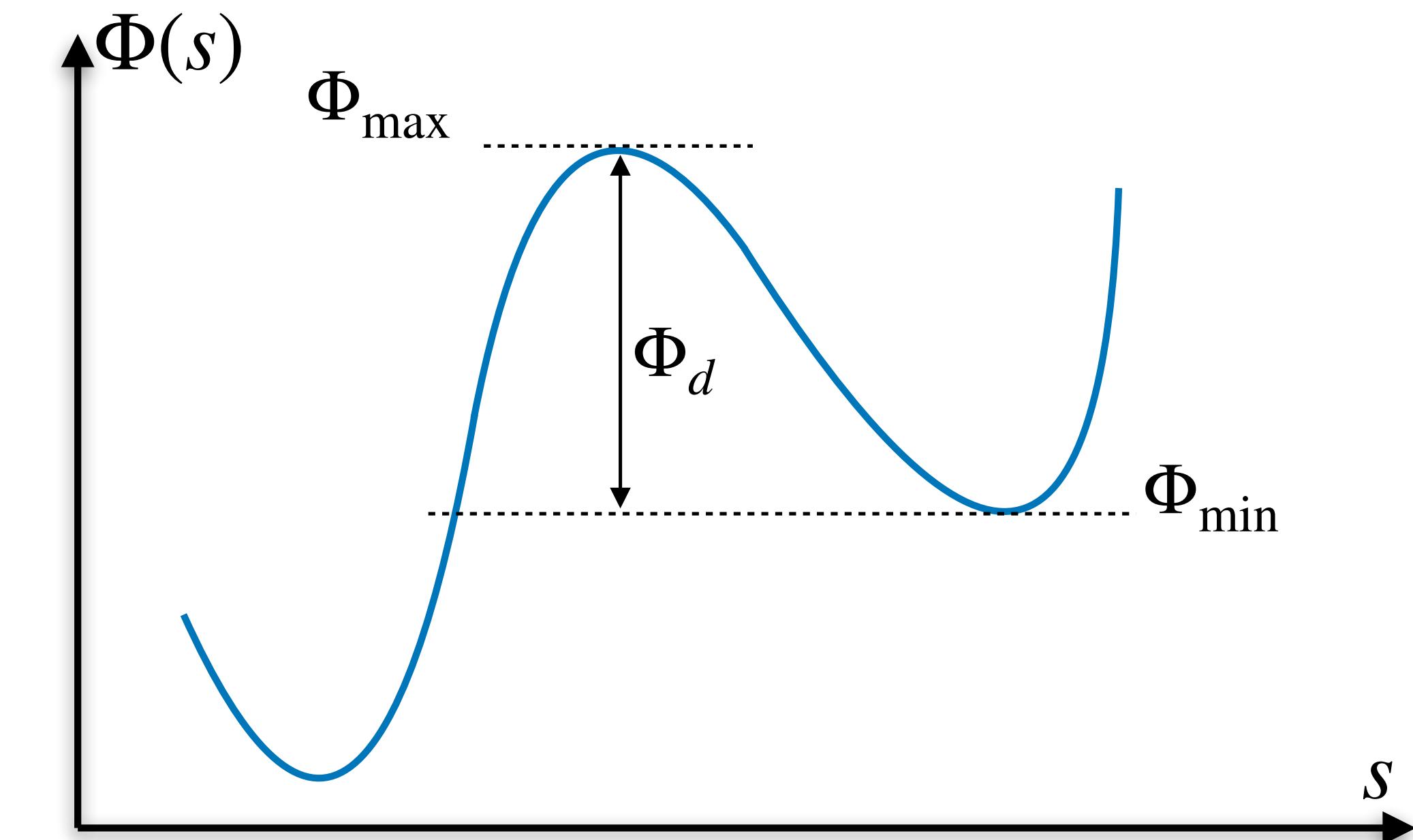
Region of interest

- Due to **magnetic** and **electric** fields topology, some magnetic potential **wells** can form.
- Magnetic field line crosses twice an equipotential.
- Directional force keeps electrons **in the well** while they drift **azimuthally**.



Config leading to magnetic well [PPZ+16]

$$F_{||} = - e \cdot E_{||}$$



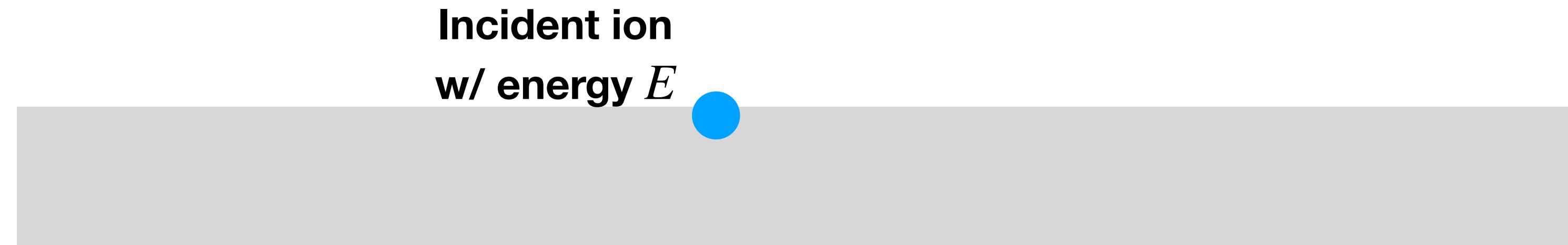
# EPFL Theory: Choosing a model for IIEE

- We seek an expression for  $\gamma$ , the **electron yield per incident ion**.



# EPFL Theory: Choosing a model for IIEE

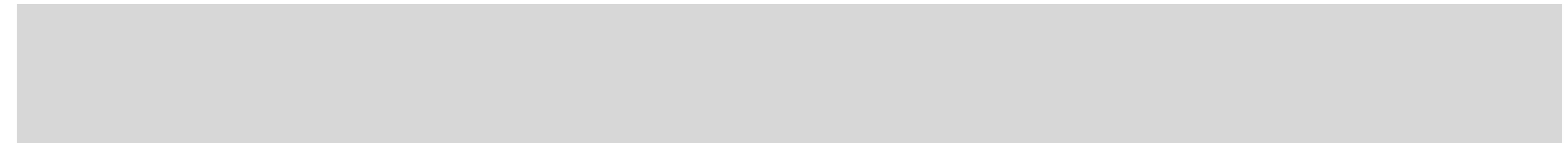
- We seek an expression for  $\gamma$ , the **electron yield per incident ion**.



# EPFL Theory: Choosing a model for IIEE

- We seek an expression for  $\gamma$ , the **electron yield per incident ion**.

$$\bullet \quad \begin{array}{l} k \text{ emitted } e^- \text{ s.t} \\ < k > = \gamma(E) \end{array}$$



# EPFL Theory: Choosing a model for IIEE

- We seek an expression for  $\gamma$ , the **electron yield per incident ion**.
- $\gamma$  is expected to depend on the **incident particle energy**, some **material parameters** (target density, transport phenomena for produced electrons).
- Semi-empirical (kinetic) model: Schou - 1988 [DH]

$$\gamma = \Lambda \cdot \beta \cdot \frac{dE}{dx} \Big|_i,$$

where  $\Lambda$  contains the **cross-sections** dependence for energy deposition,  $\beta$  accounts for **energy transport** of the produced electrons, and  $\frac{dE}{dx} \Big|_i$  corresponds to the **energy loss** of ions in the solid, per unit distance.

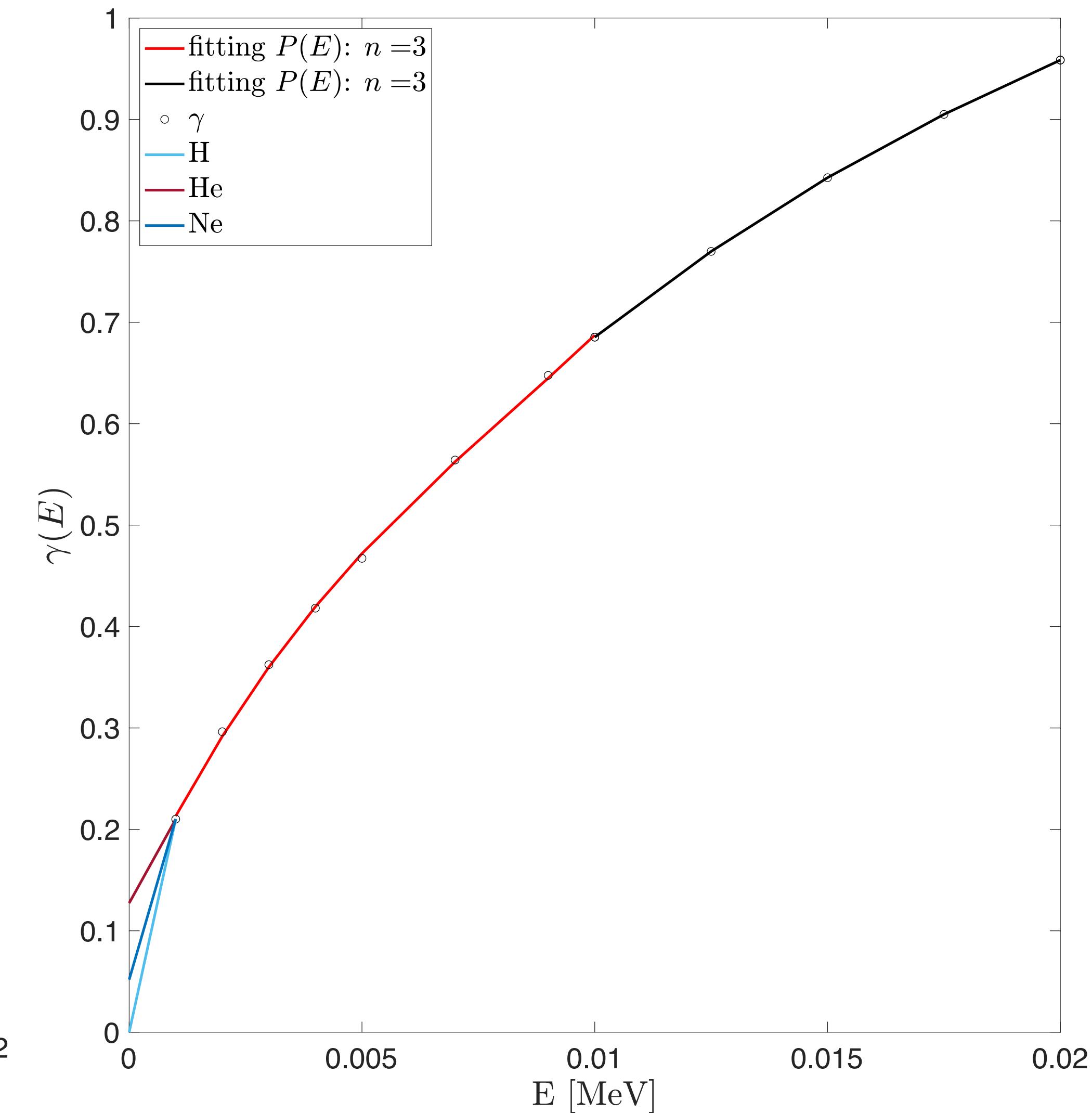
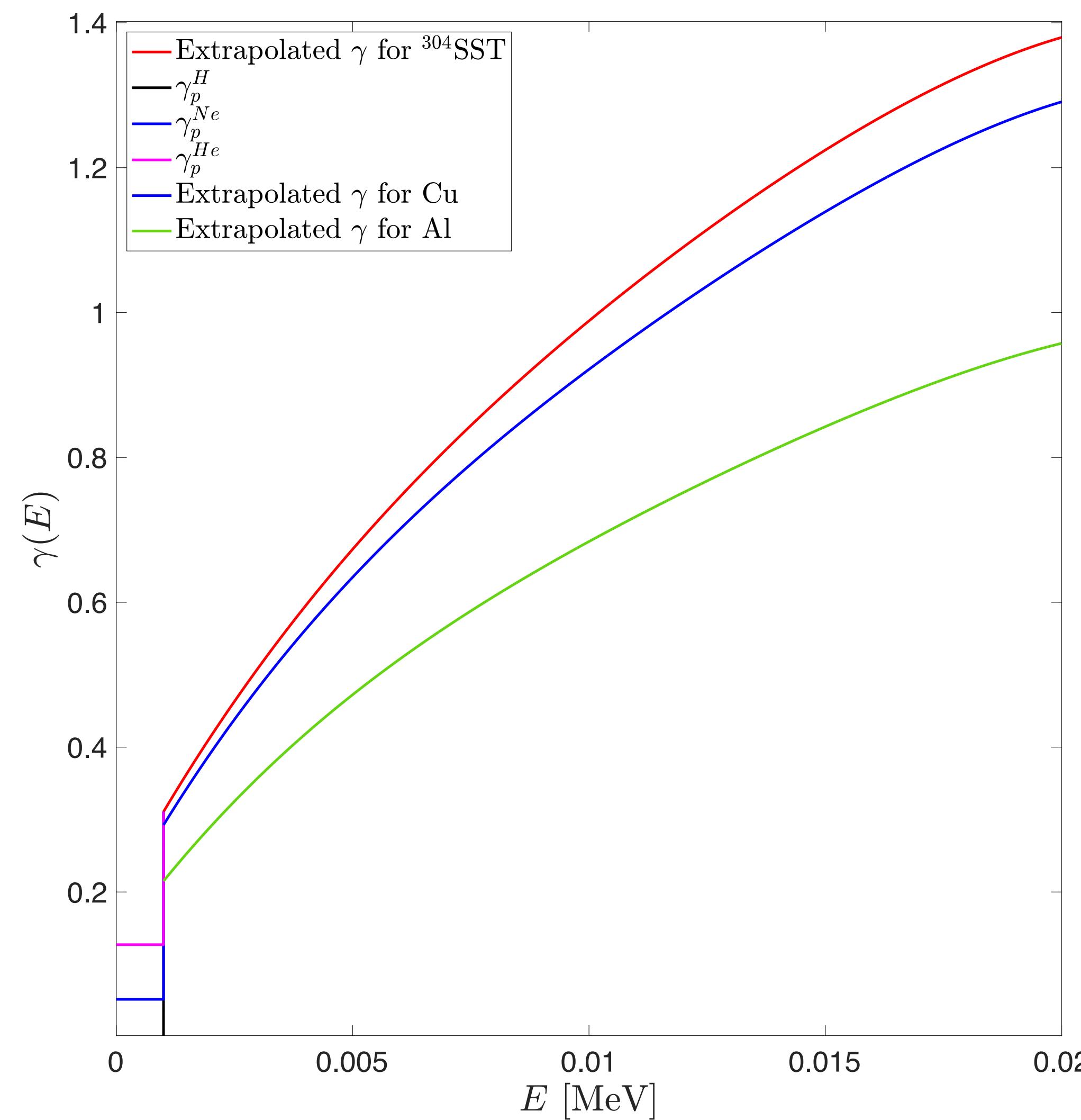
- For ions like  $H^+$ ,  $H_2^+$ , the product  $\Lambda \cdot \beta$  has been measured indep. of the metal and of approx.  $10^{-3} \text{ cm/MeV} = 10^{-6} \text{ cm/keV}$ .
- Hence our kinetic model reads  $\gamma(E) = 10^{-6} \cdot \frac{dE}{dx} \Big|_i$ , with  $E \in [1,50] \text{ keV}$ .
- Potential emissions:  $E \in [0,1] \text{ keV}$ , we need another model
- *Hagstrum - 1954 [Kis73]*:

$$\gamma \sim \frac{0.2}{\epsilon_F} (0.8 \cdot E_i - 2\phi),$$

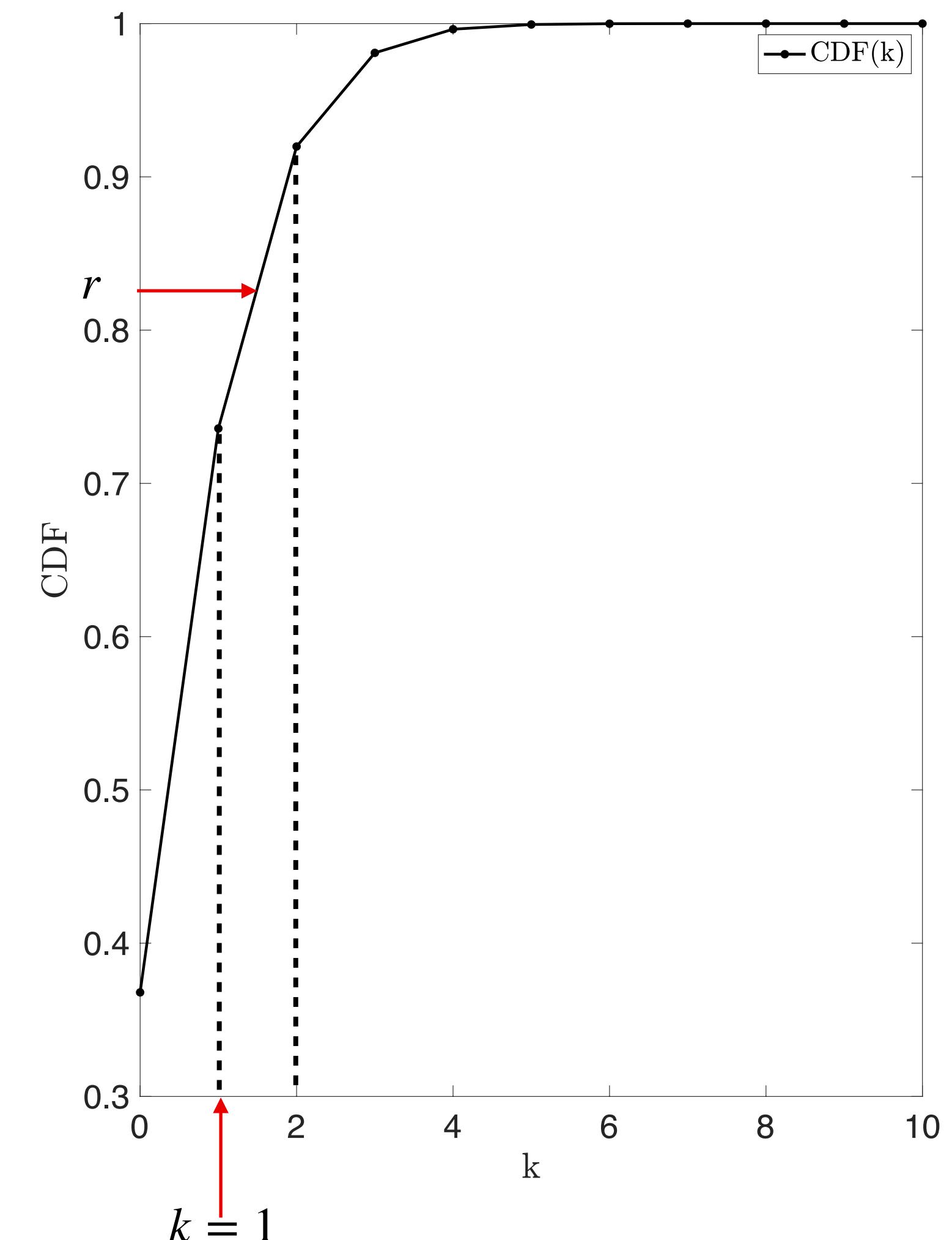
where  $\epsilon_F$  denotes the **Fermi** energy of the solid,  $E_i$  the energy to produce the **incident ion**, and  $\phi$  the **work function** of the metal.

- Schou's model: **kinetic**, holds for  $E \in [1,50]$  keV
- Hagstrum's model: **potential**, holds for  $E \in [0,1]$  keV, constant  $\gamma$
- **Transition between the two models** ? Linear interpolation between bottom of kinetic region and constant  $\gamma$ , so the yield is decreasing continuously on the whole range.

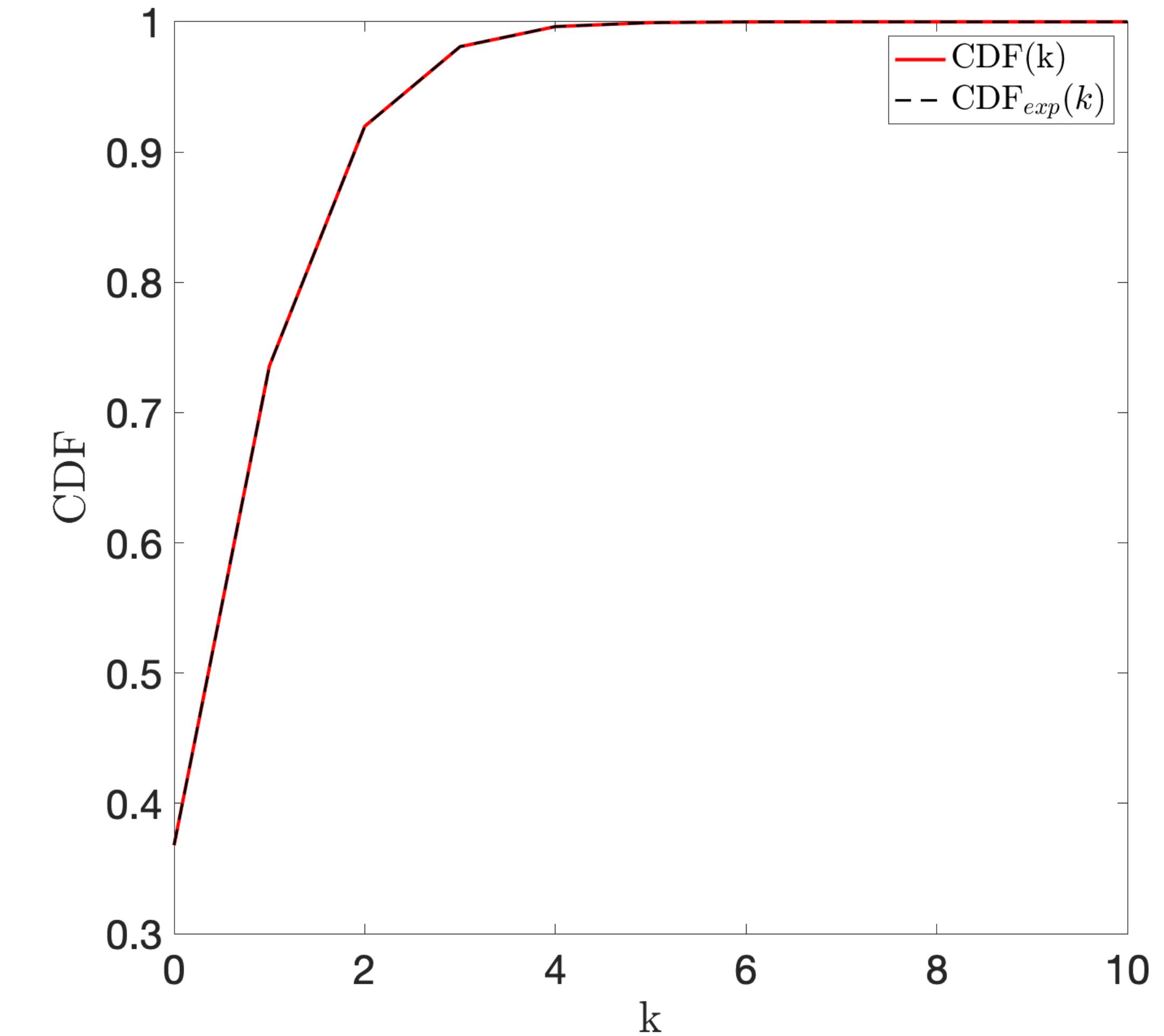
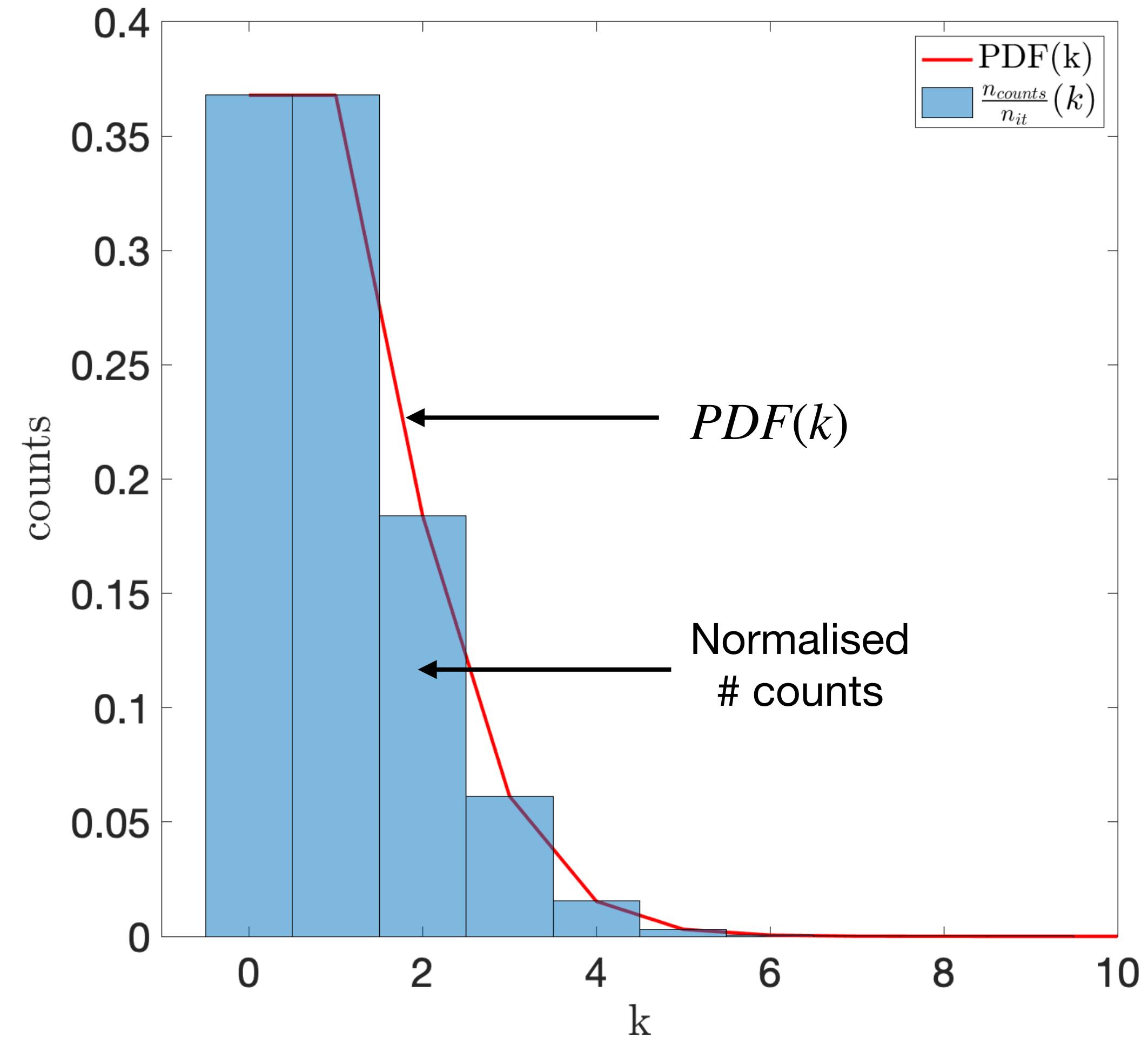
- Yield curve obtained by interpolating the points with cubic polynomials
- Right plot shows transition between Hagstrum's and Schou's model



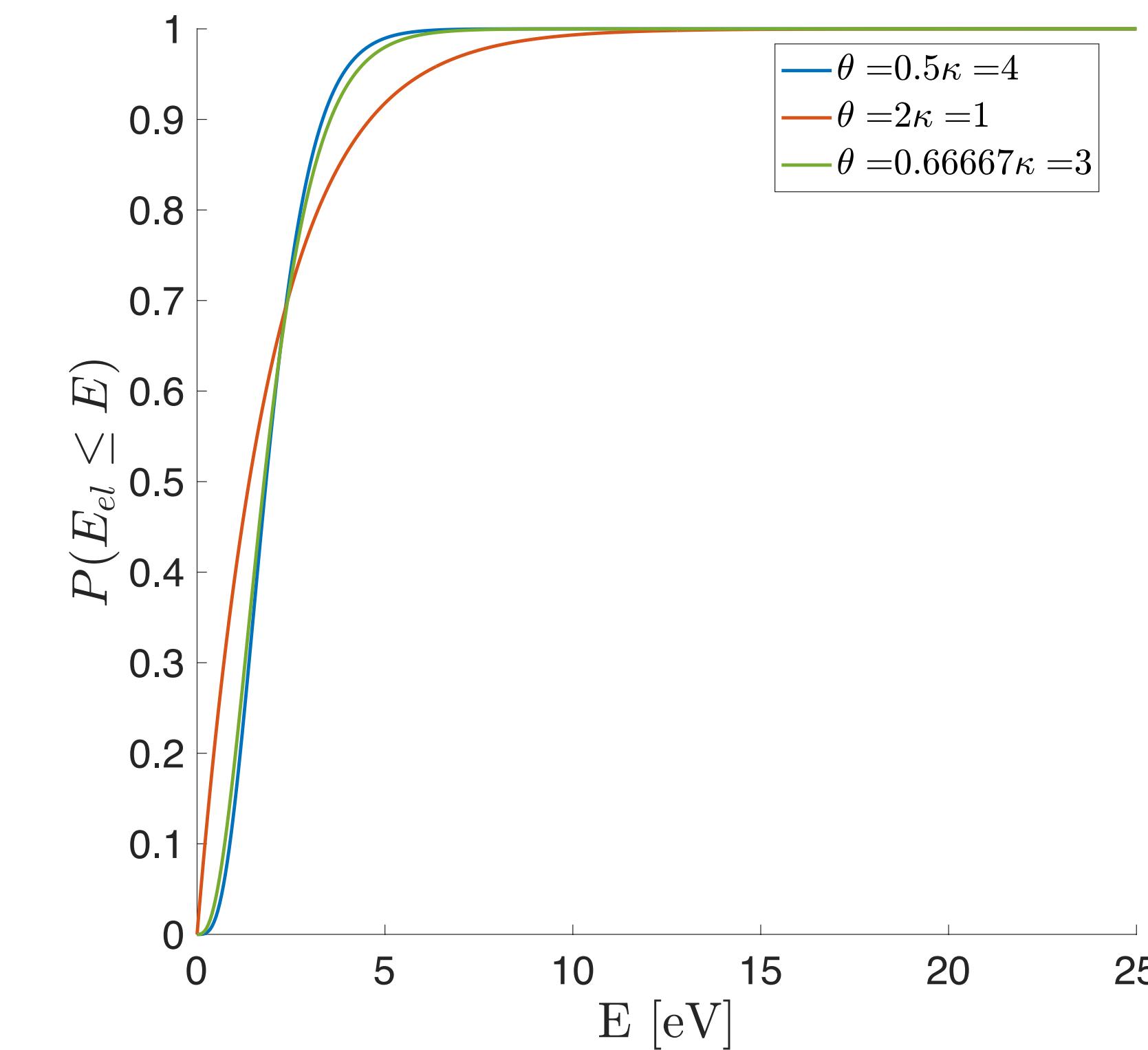
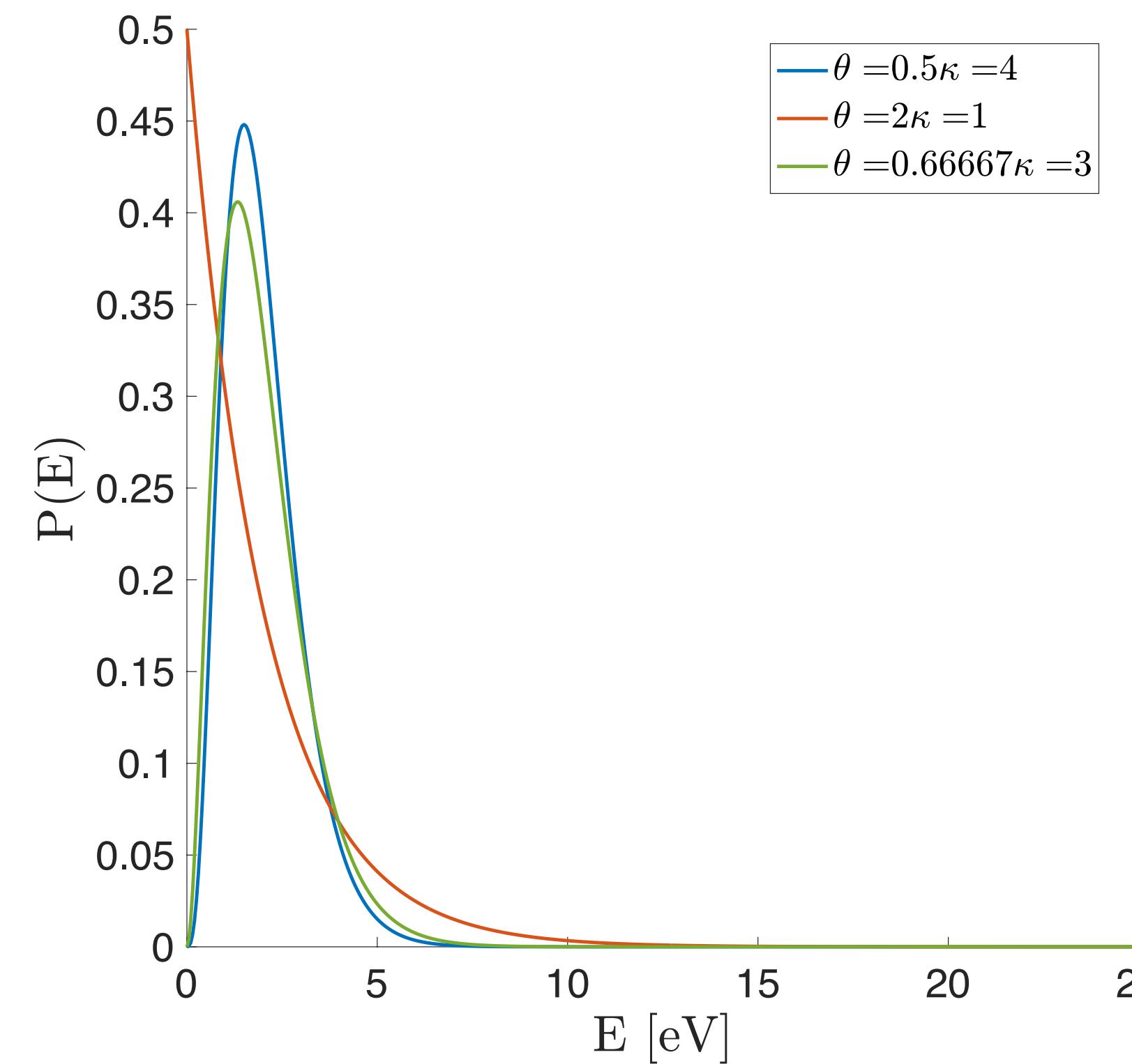
- Electron generation: discrete ‘rare’ events  $\Rightarrow$  **Poisson** distribution for the number of electrons generated per incident ion (parameter  $\lambda$ )
- Poisson s.t.  $\lambda(E) = \gamma(E)$
- $P(k) = \frac{e^{-\gamma(E)}}{k!}$ , and CDF:  $C(k) = \sum_{j=0}^{\lfloor k \rfloor} \frac{\gamma(E)^j}{j!}$
- Procedure:
  - Generate a random number uniformly in  $[0,1[$
  - Evaluate C with  $\lambda = \gamma(E)$
  - If  $r \in [C(\tilde{k}), C(\tilde{k} + 1)[$  then  $k = \tilde{k}$ .



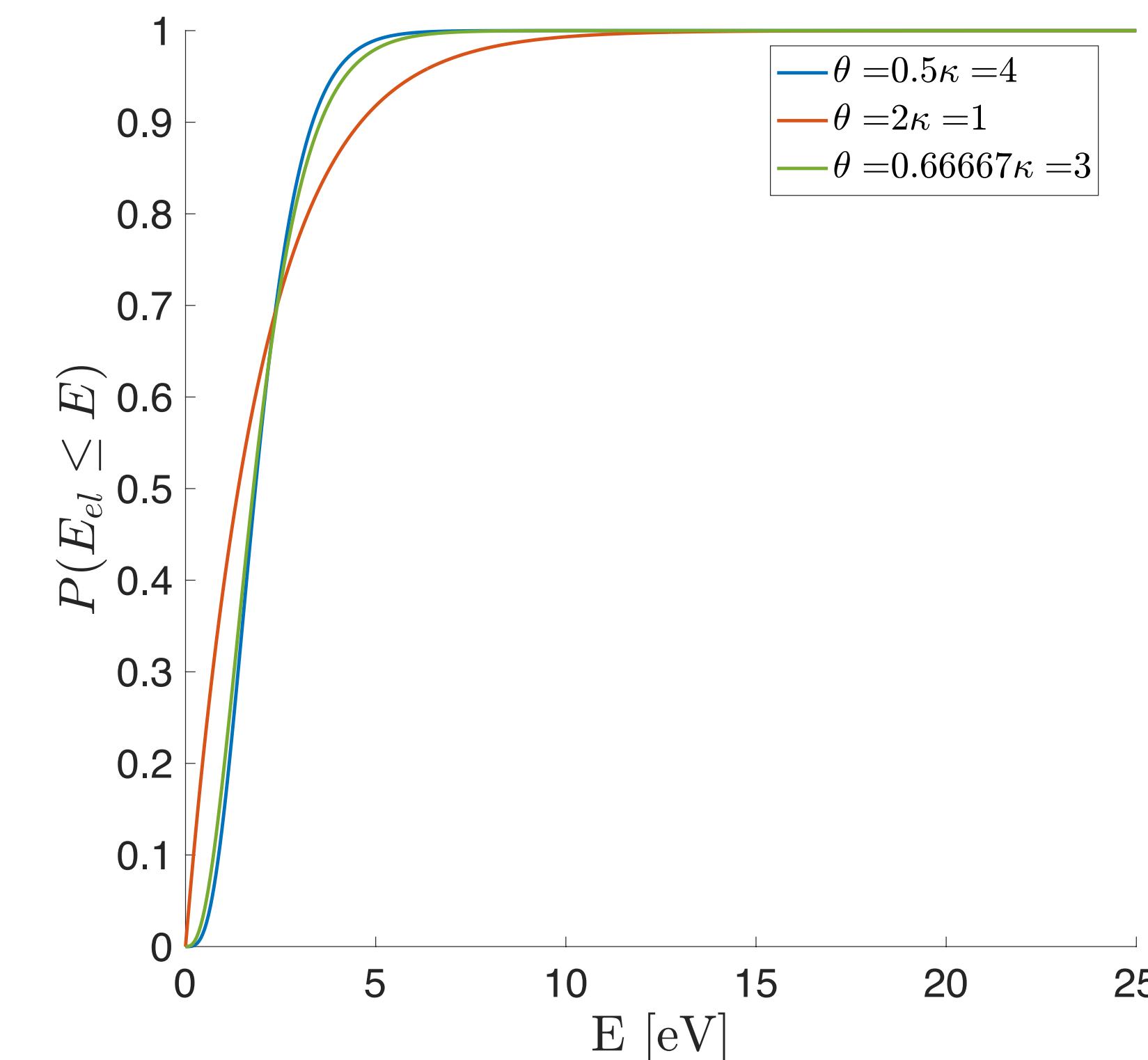
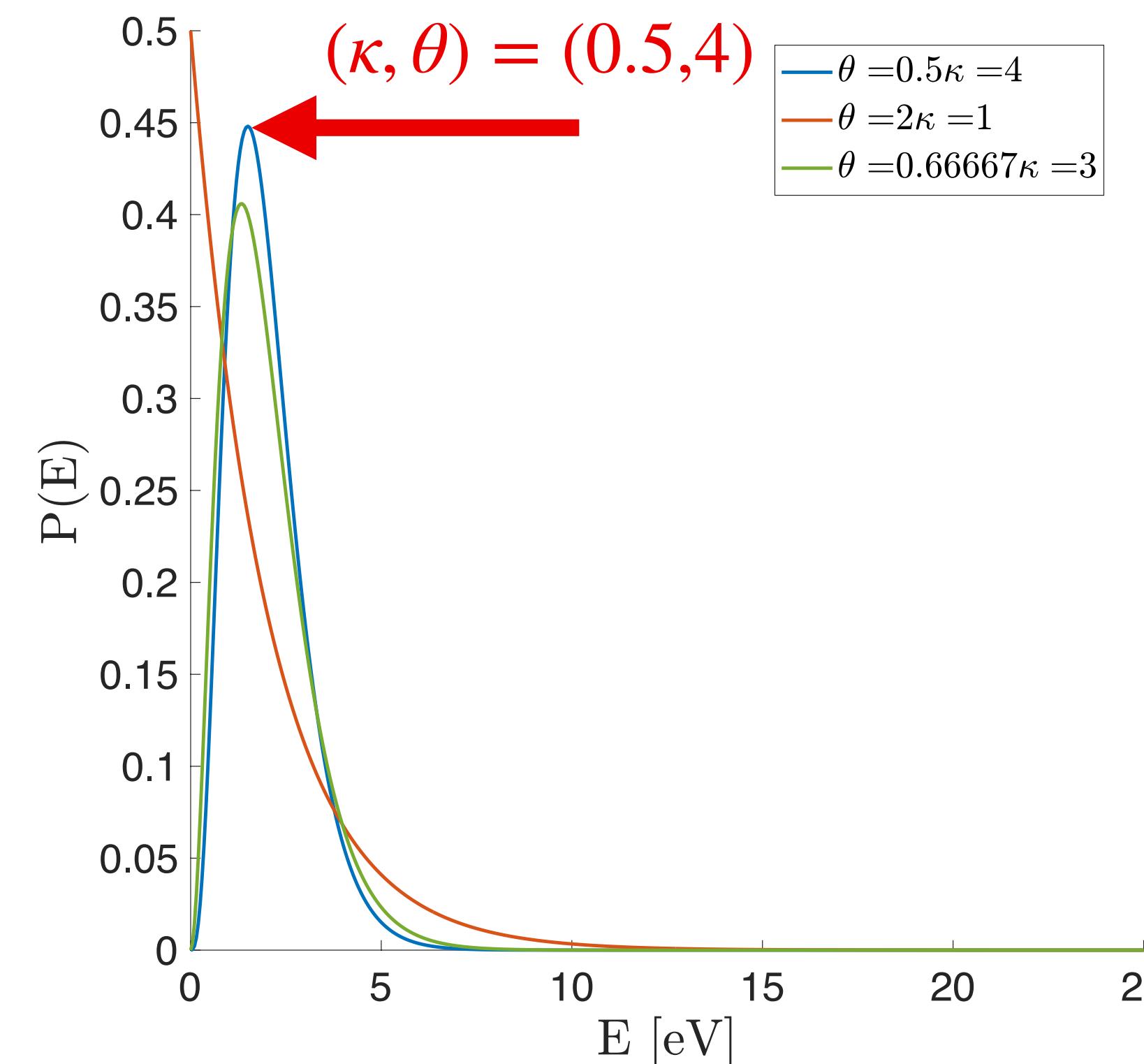
# EPFL Electron generation - Test of Poisson generator



- According to [DH] and [PPZ+16]: follows a gamma distribution that averages at 2 eV.
- Recall the two parameters: **shape** param.  $\kappa$  and **scale** param.  $\theta$  s.t average  $m = \kappa \cdot \theta$

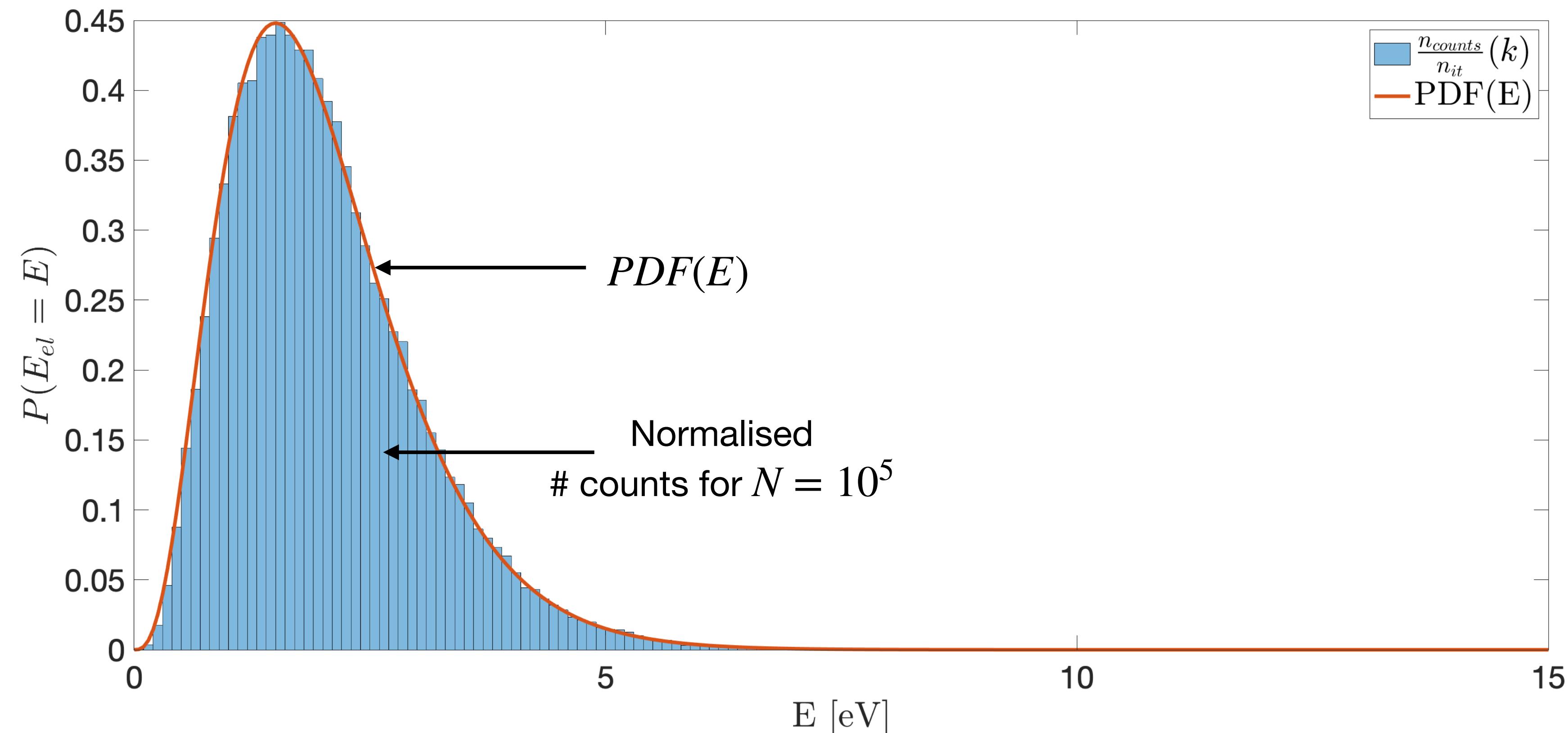


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- Chose  $(\kappa, \theta) = (0.5, 4)$  so that peak prob closer to 2

- Procedure: generate a random number  $r$  uniformly in  $[0,1[$
- Evaluate the CDF in the range  $[0,15]$  eV with  $N = 500$  points
- Take  $E$  as  $E := \min_{\tilde{E}} |r - C(\tilde{E})|$



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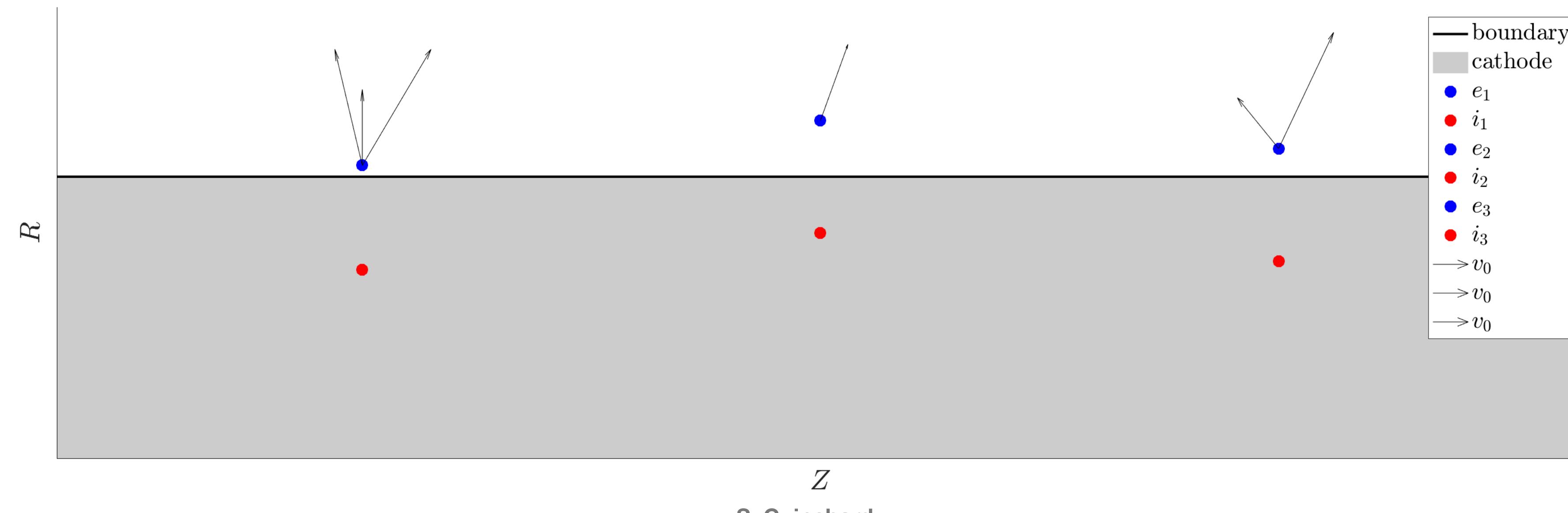
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- Ion safely removed from the simulation

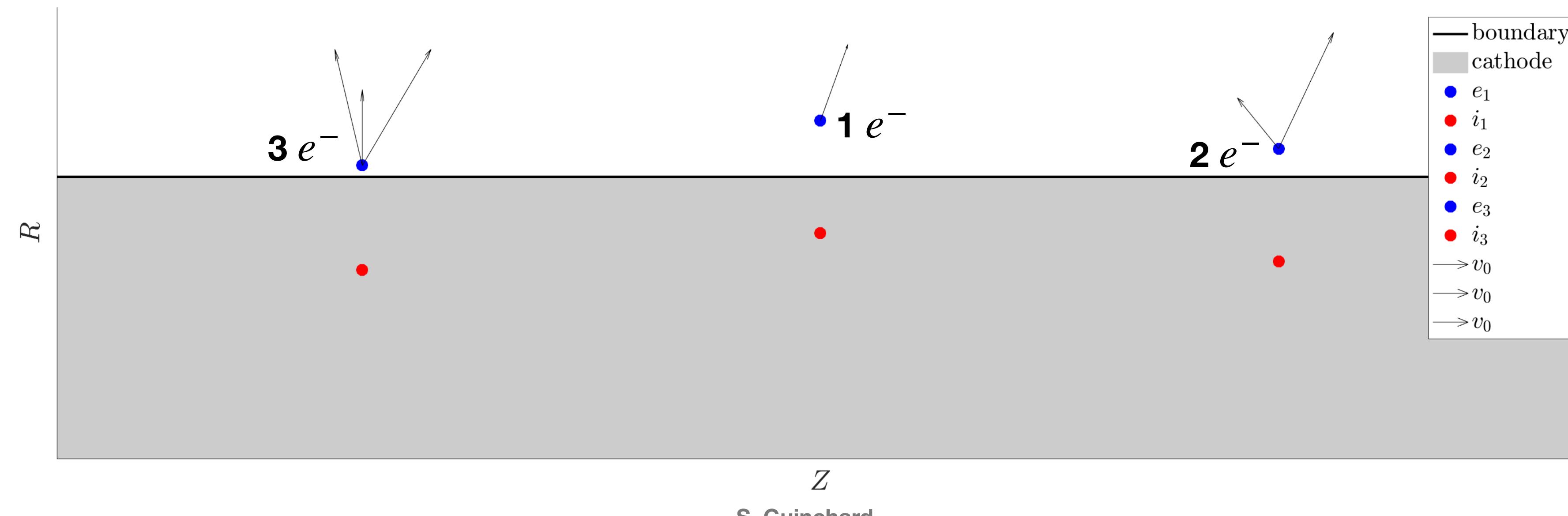
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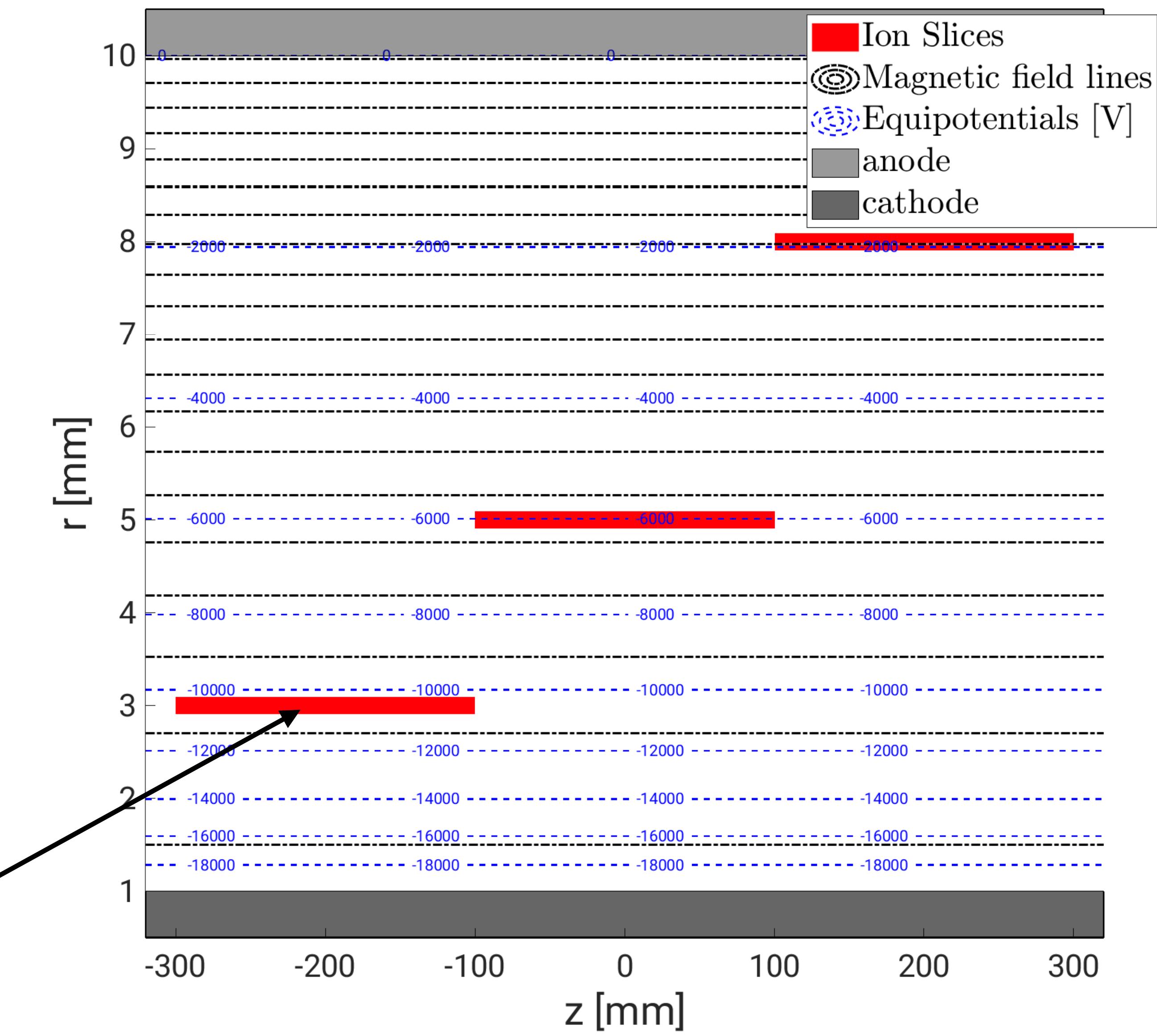
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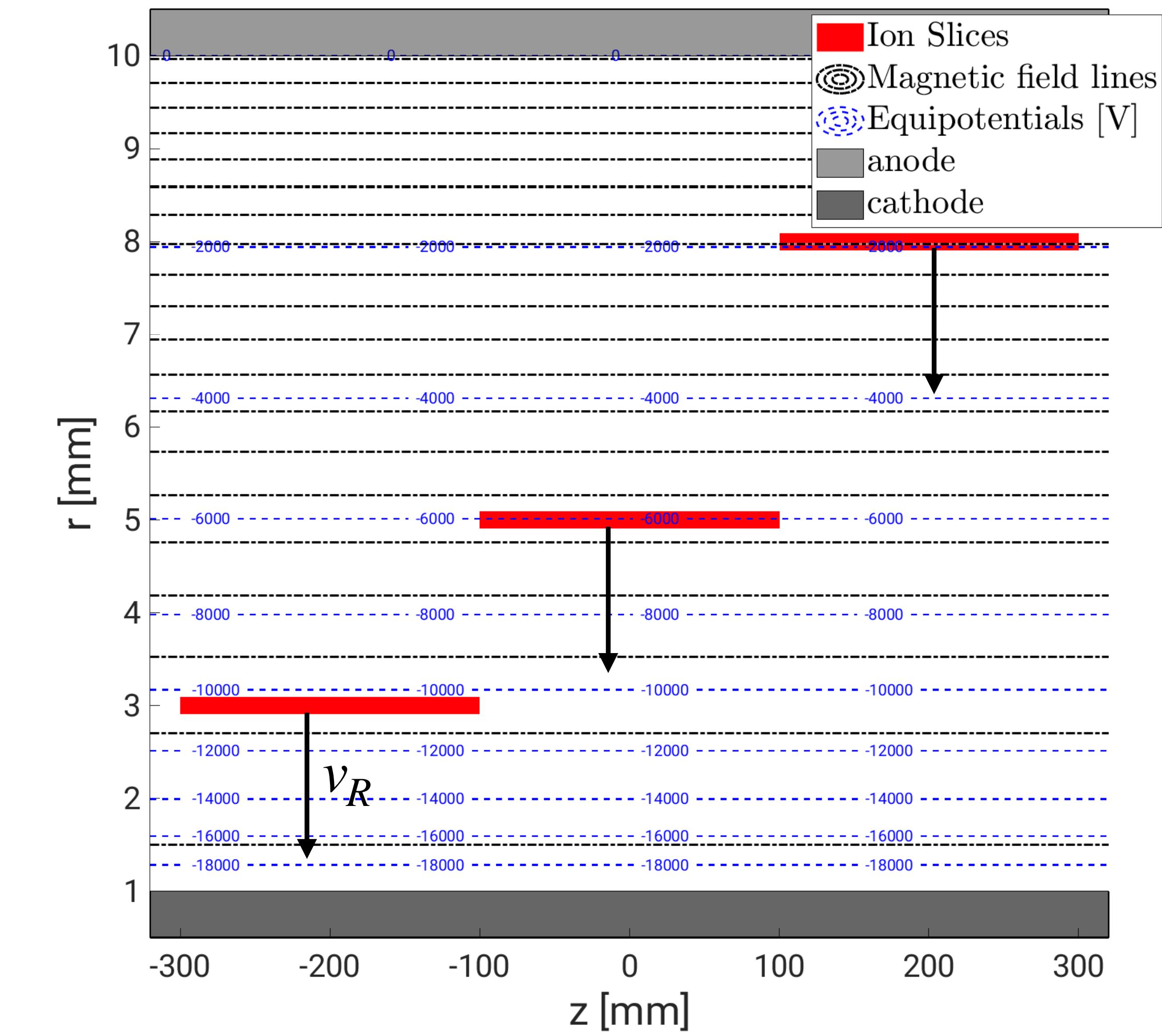


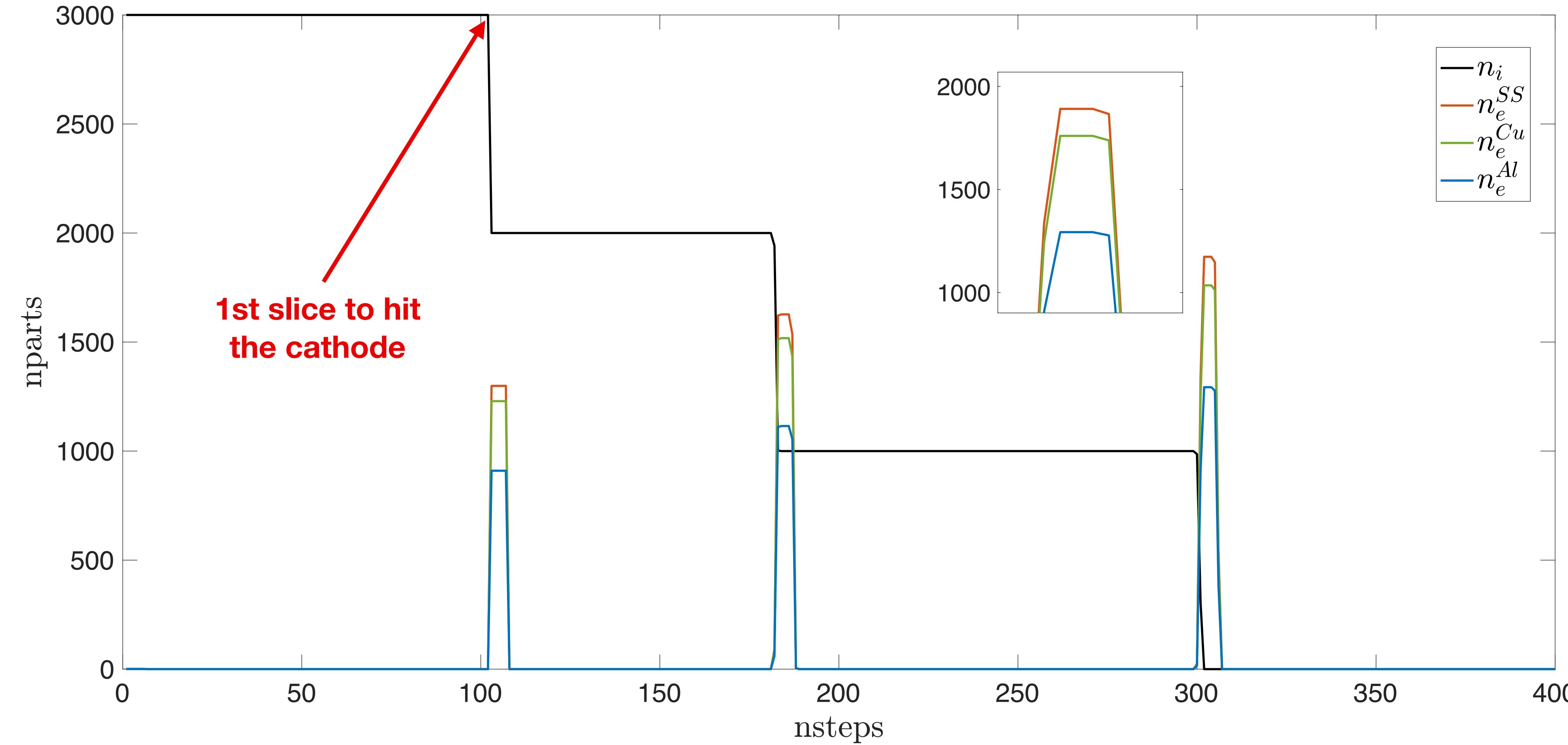
- Initial configuration: 3 horizontal slices of  $H_2^+$  ions - SS, Al and Cu.
- $\Delta\Phi = 20 \text{ kV}$ .  $B = 0.21 \text{ T}$ .
- $r_a = 10^{-3} \text{ m}$ ,  $r_b = 10^{-2} \text{ m}$

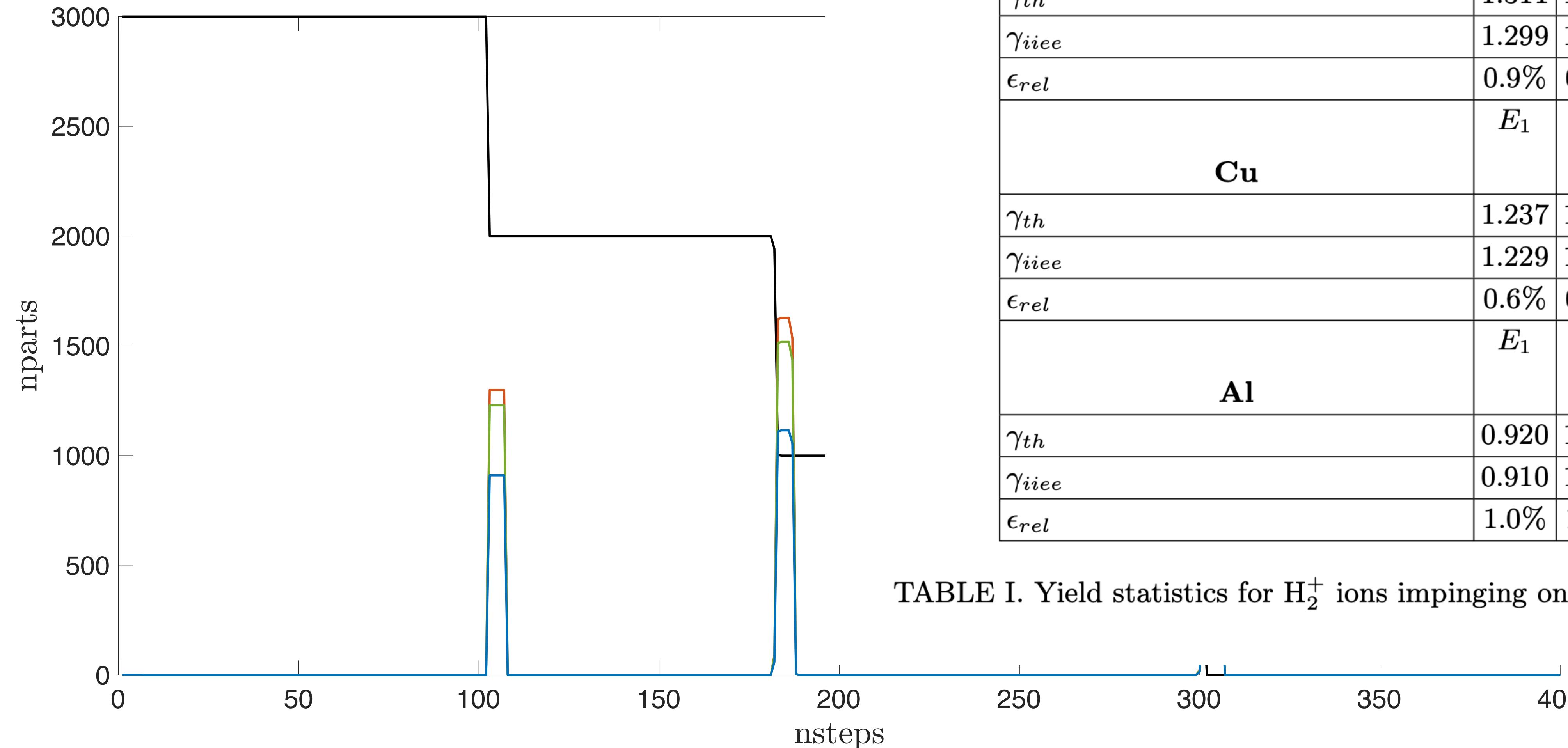
1000 ions



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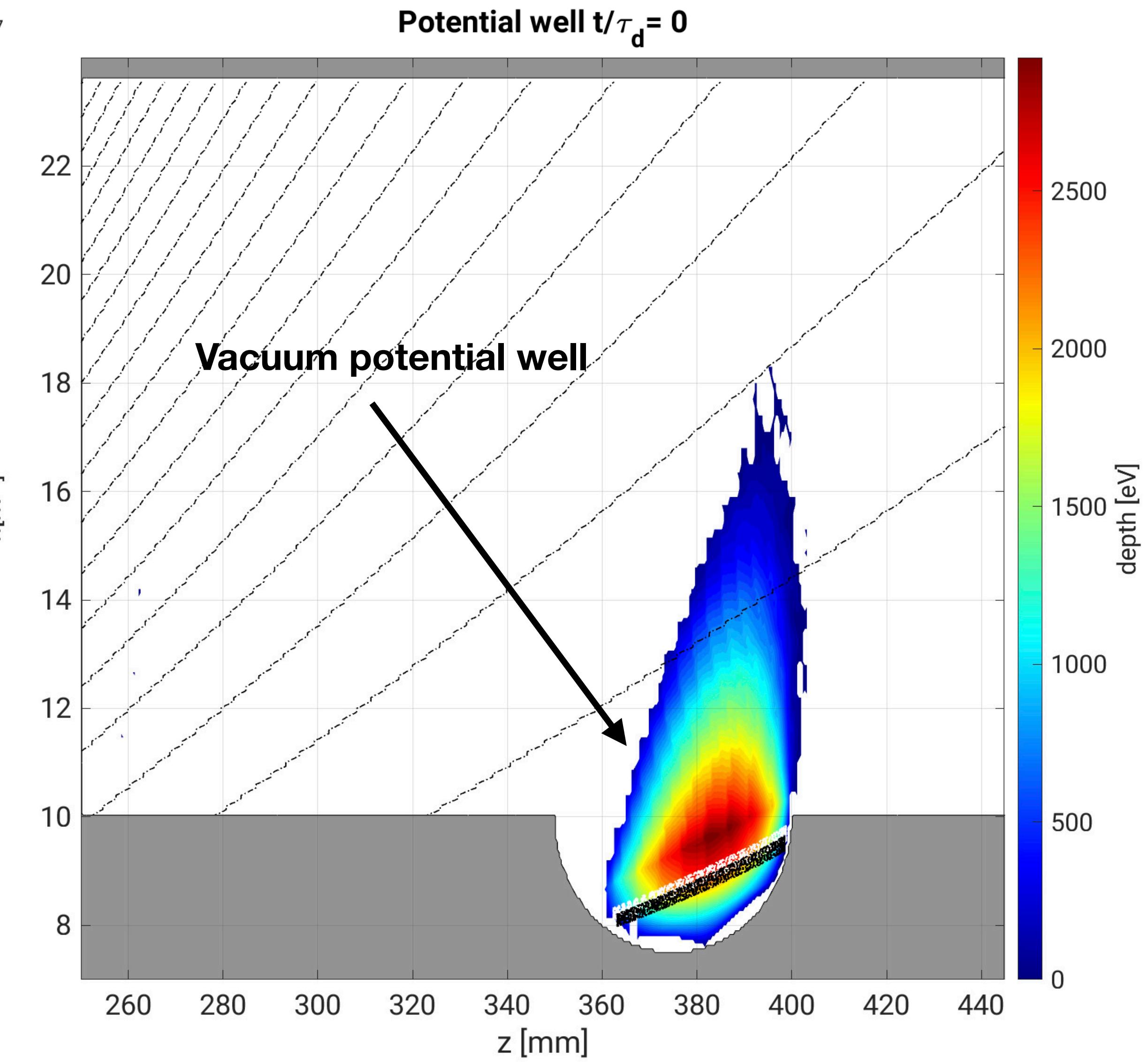
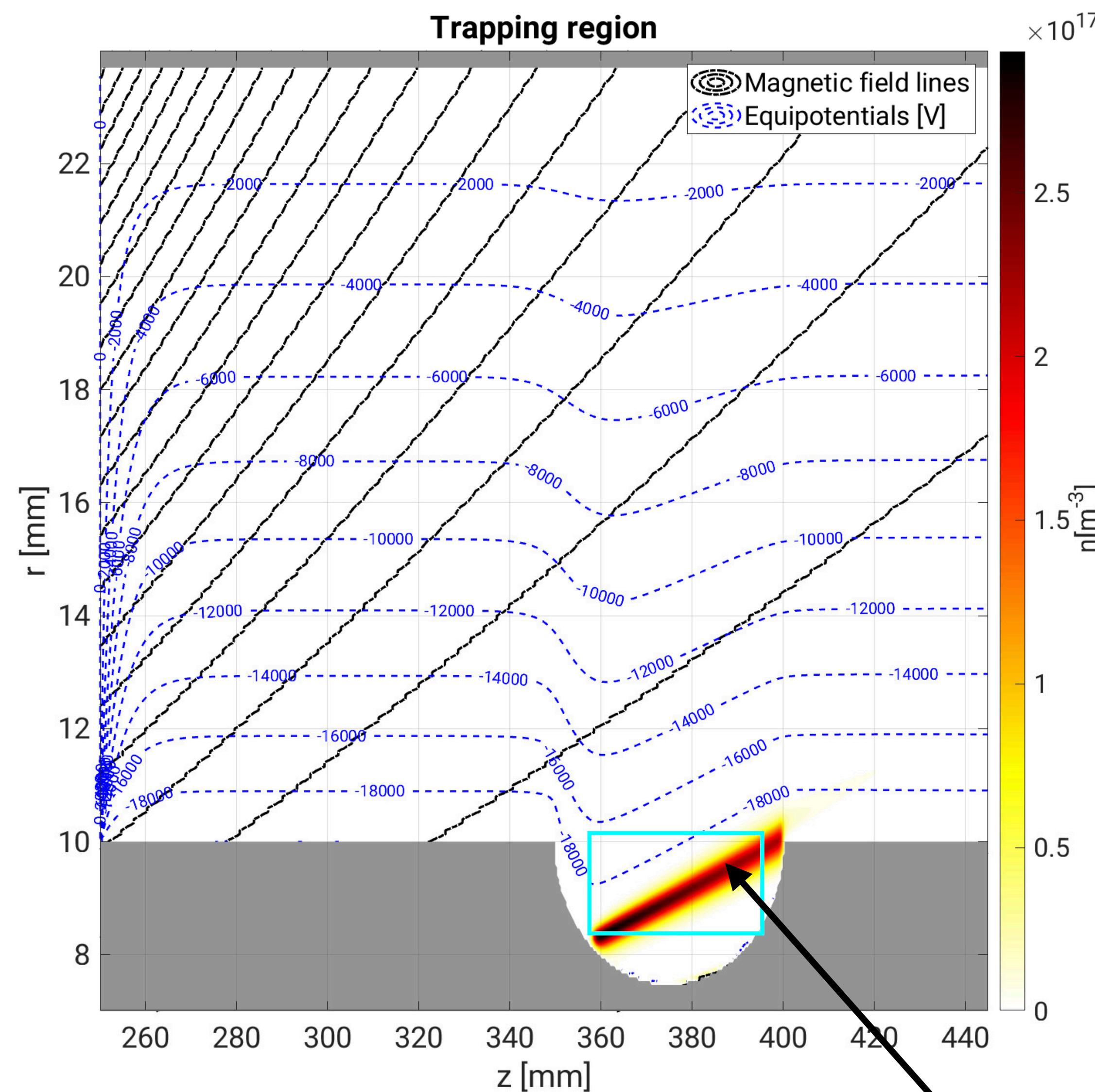






	$E_1$	$E_2$	$E_3$
<b><math>^{304}\text{SS}</math></b>			
$\gamma_{th}$	1.311	1.623	1.870
$\gamma_{iiee}$	1.299	1.627	1.891
$\epsilon_{rel}$	0.9%	0.2%	1.1%
<b>Cu</b>			
$\gamma_{th}$	1.237	1.522	1.746
$\gamma_{iiee}$	1.229	1.518	1.760
$\epsilon_{rel}$	0.6%	0.3%	0.8%
<b>Al</b>			
$\gamma_{th}$	0.920	1.133	1.297
$\gamma_{iiee}$	0.910	1.115	1.293
$\epsilon_{rel}$	1.0%	1.6%	0.3%

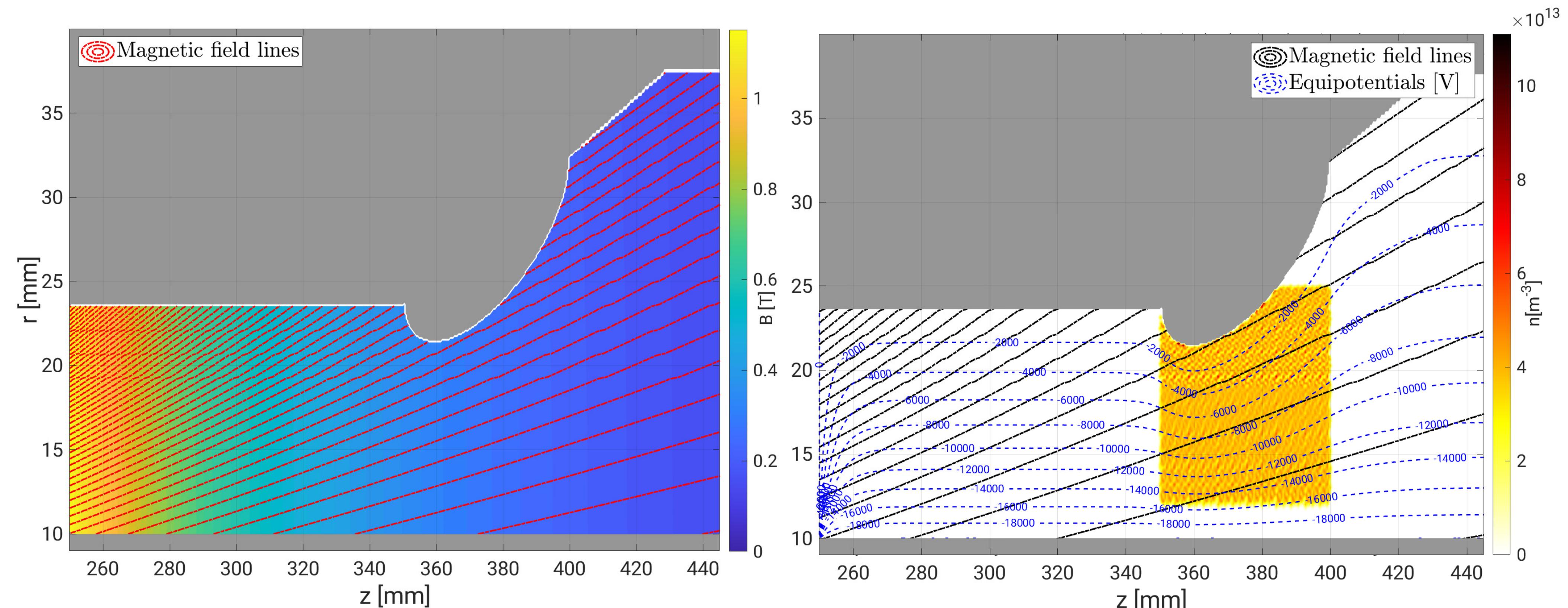
TABLE I. Yield statistics for  $\text{H}_2^+$  ions impinging on the three materials



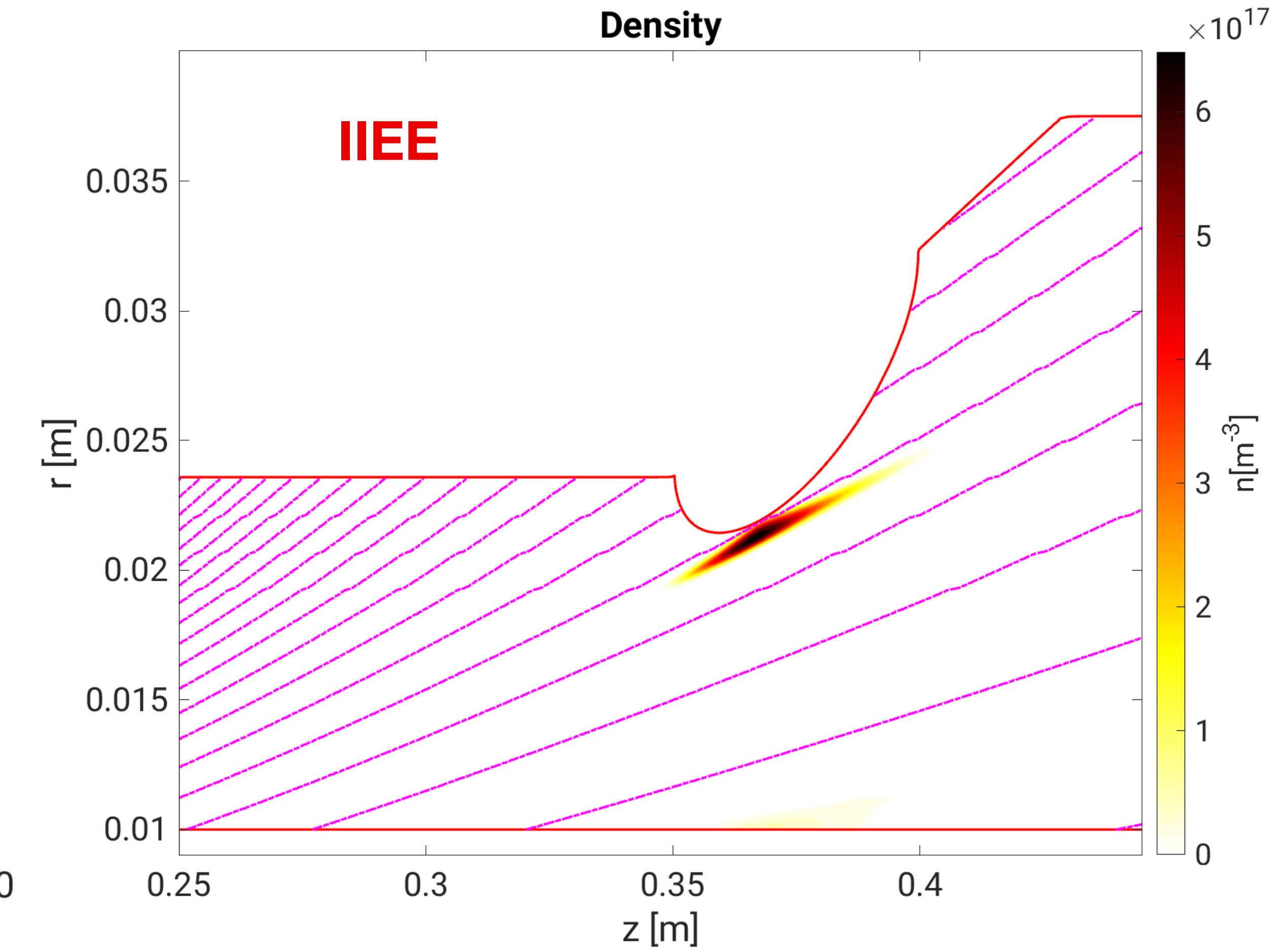
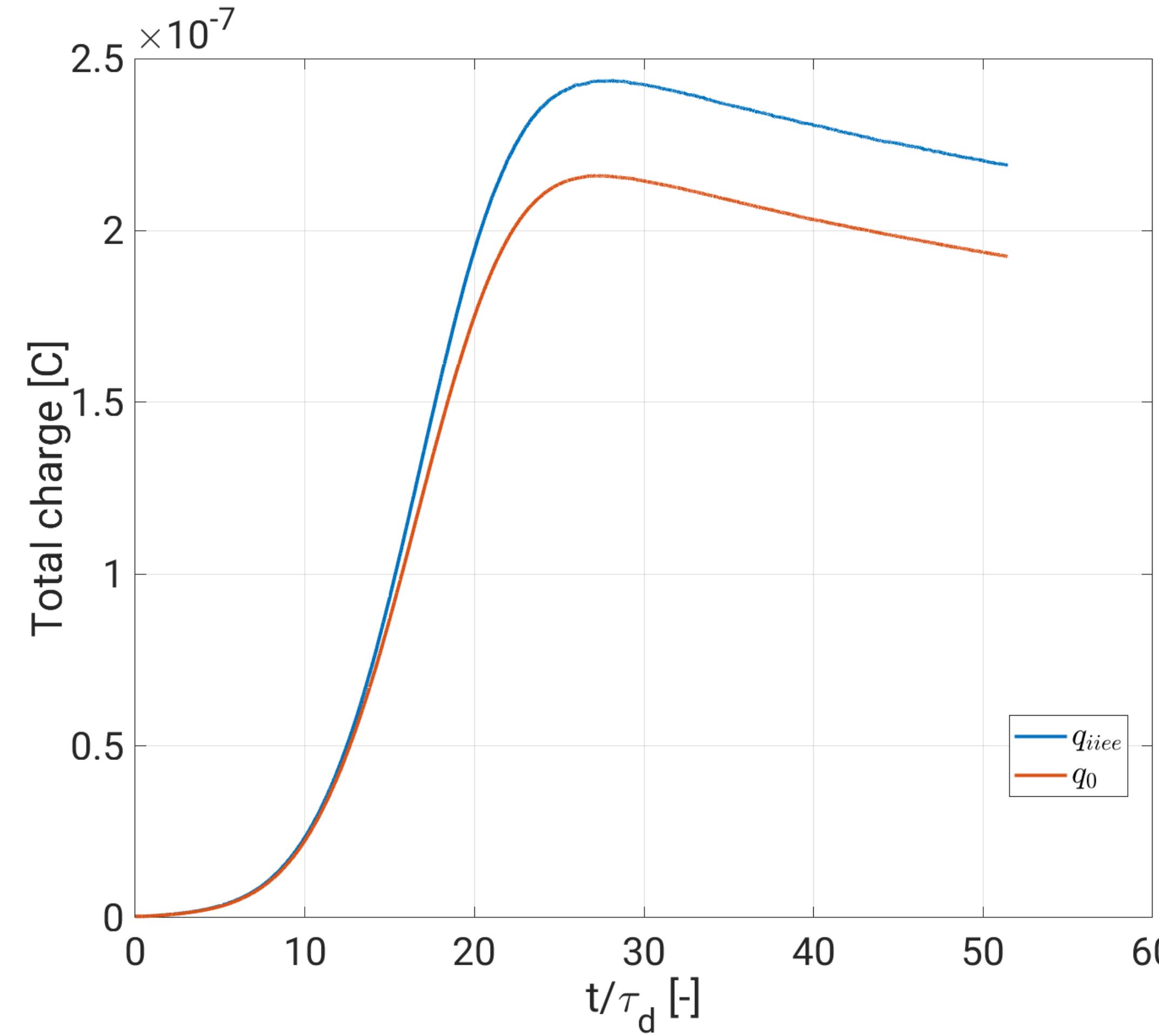
# EPFL Cloud formation and dynamics: The case TREX (slanted)

- Physical/numerical parameters

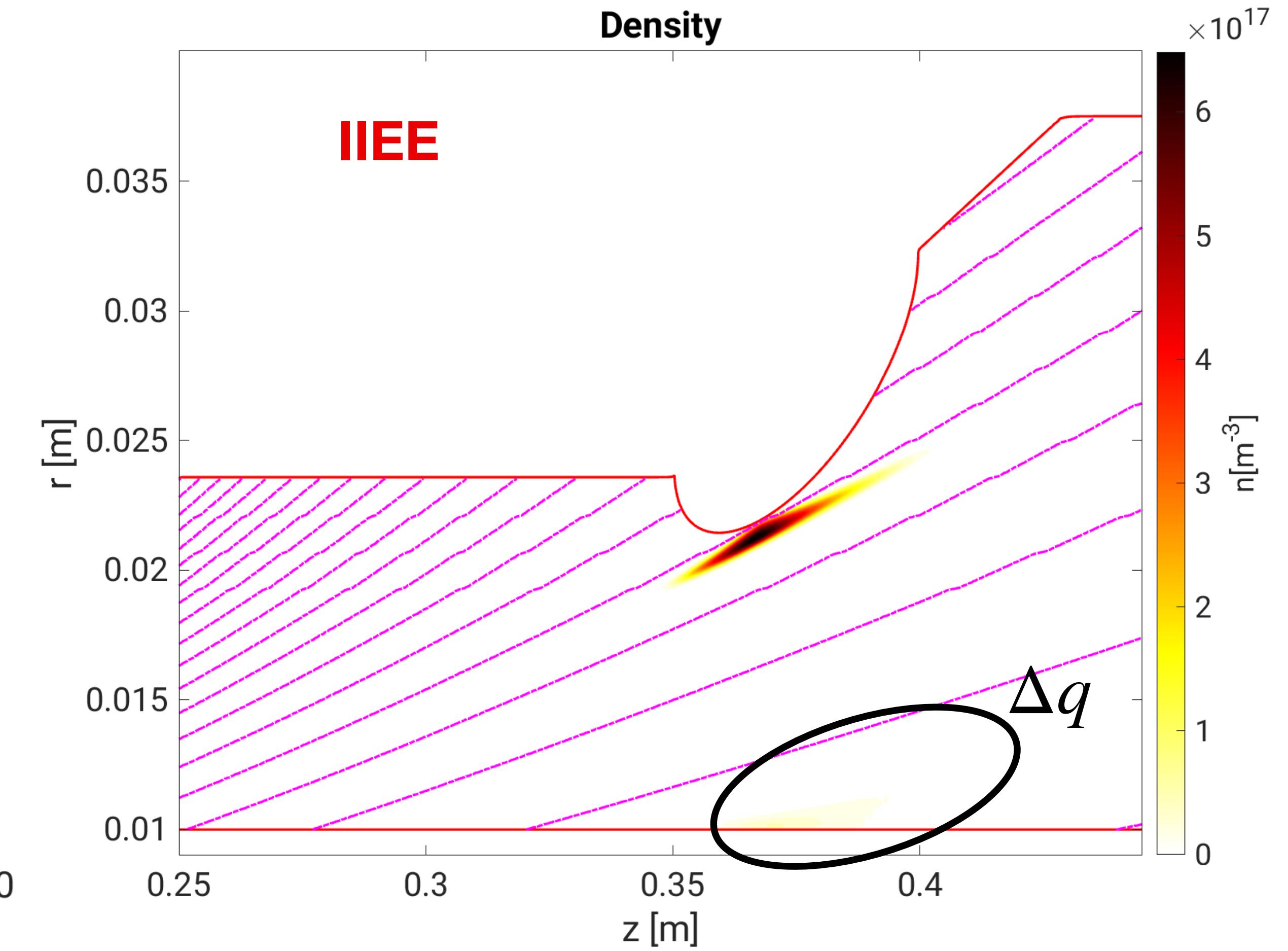
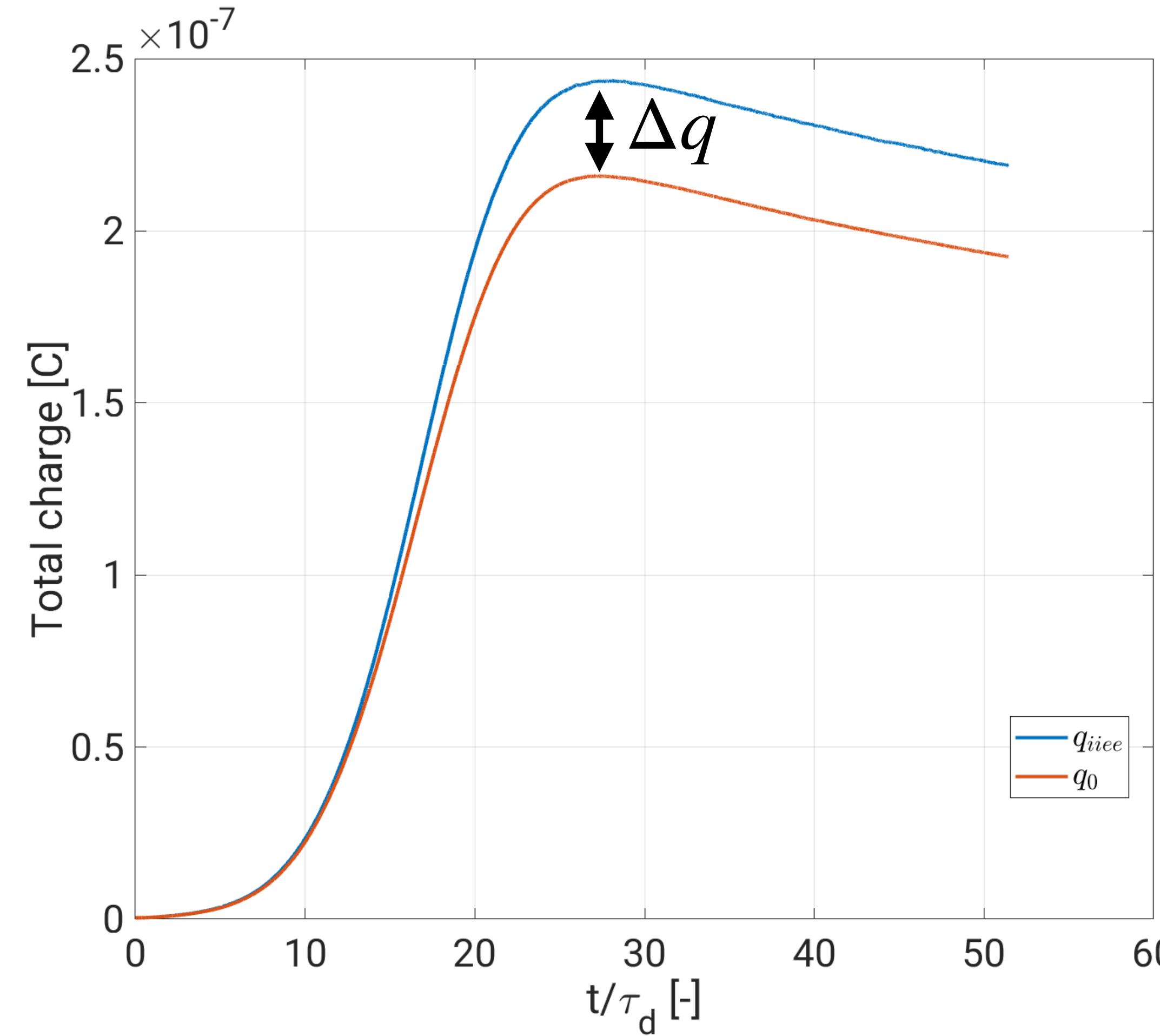
- $\Delta\Phi = 20 \text{ kV}$
- Neutral pressure  $P_n \sim 2 \cdot 10^{-2} \text{ mbar}$

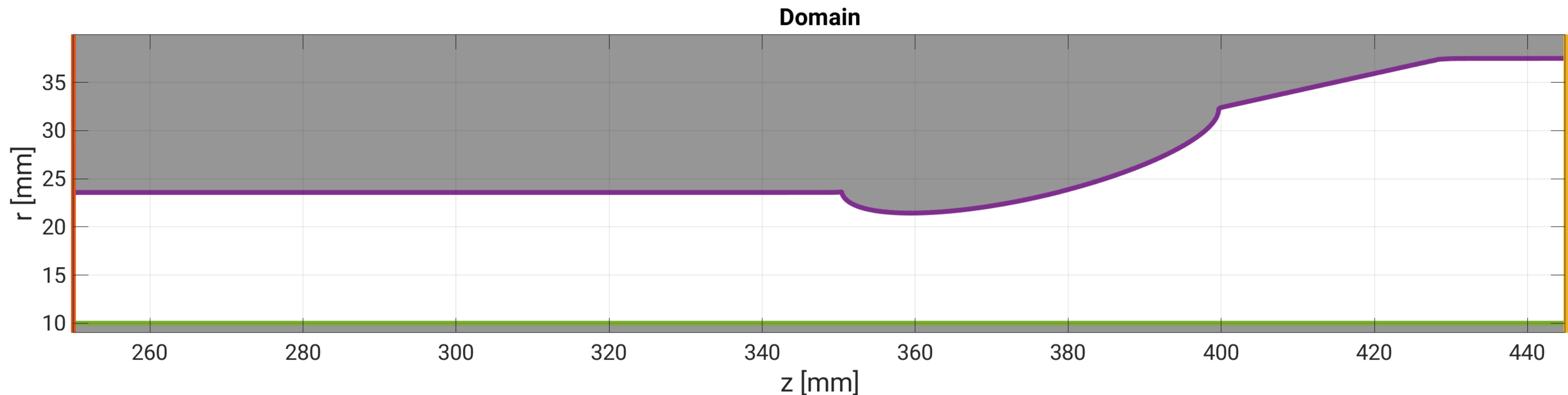
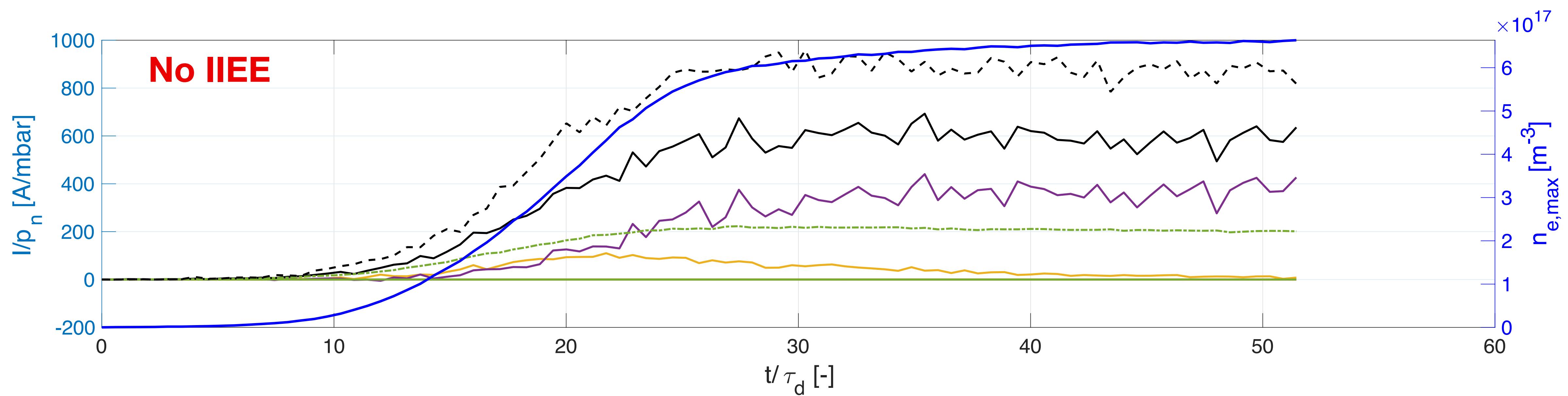


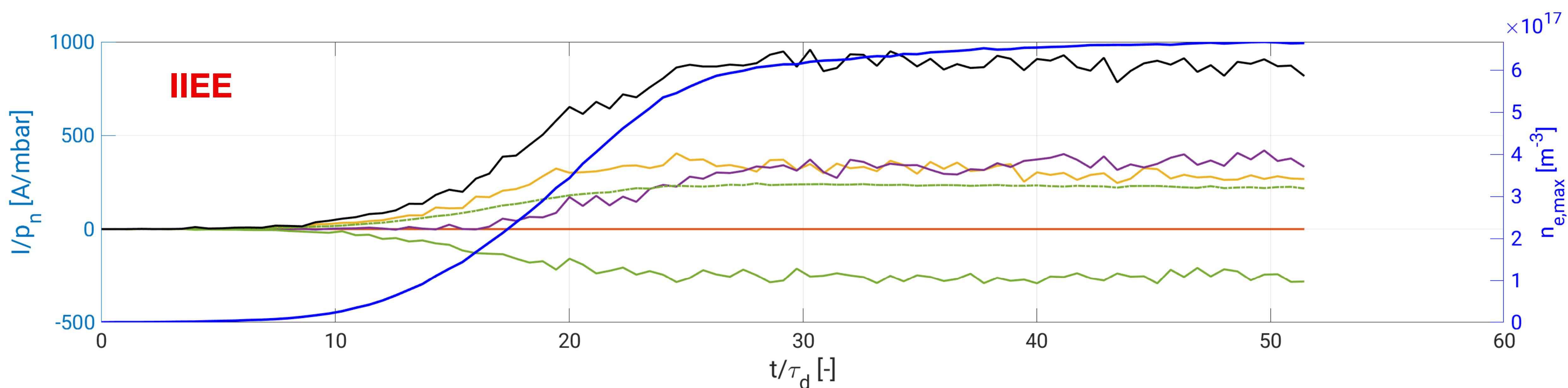
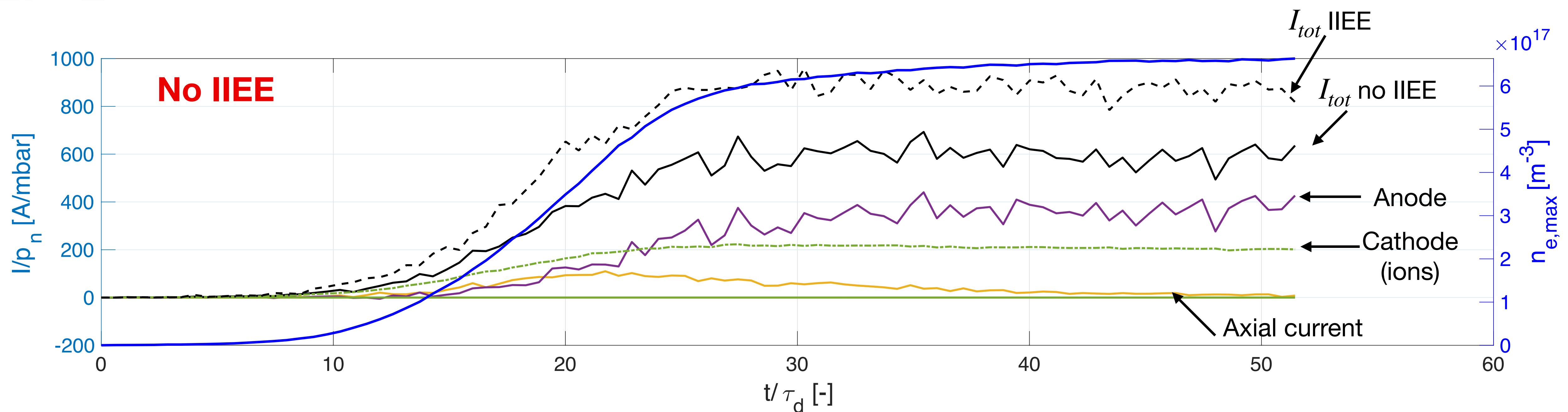
# EPFL Cloud formation and dynamics: TREX slanted geometry



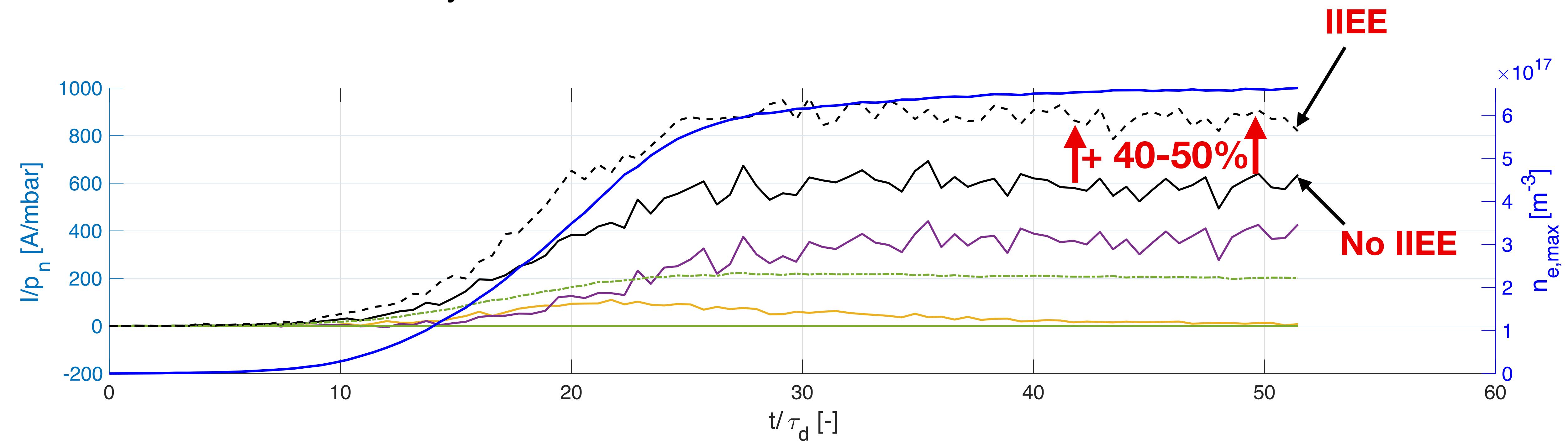
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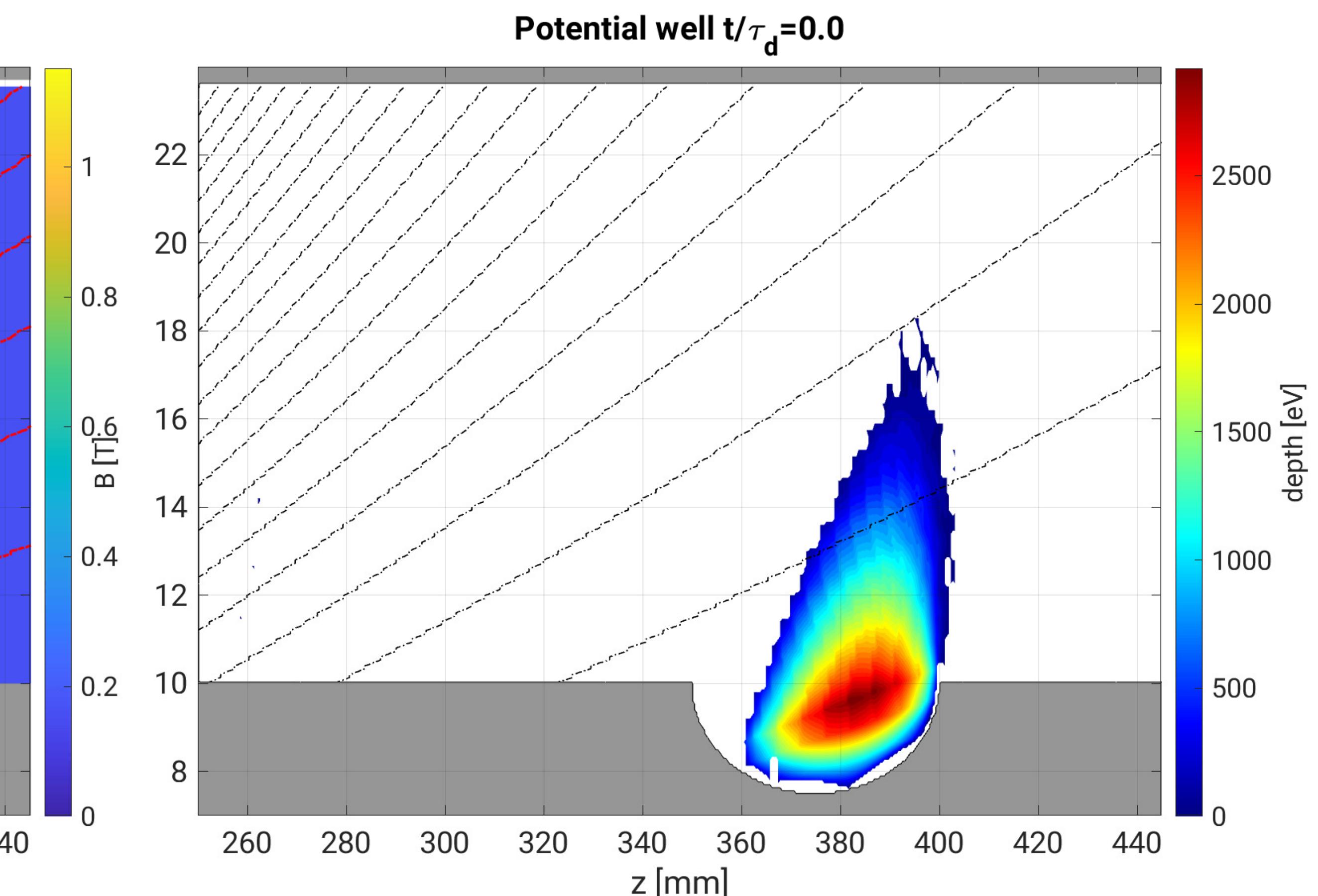
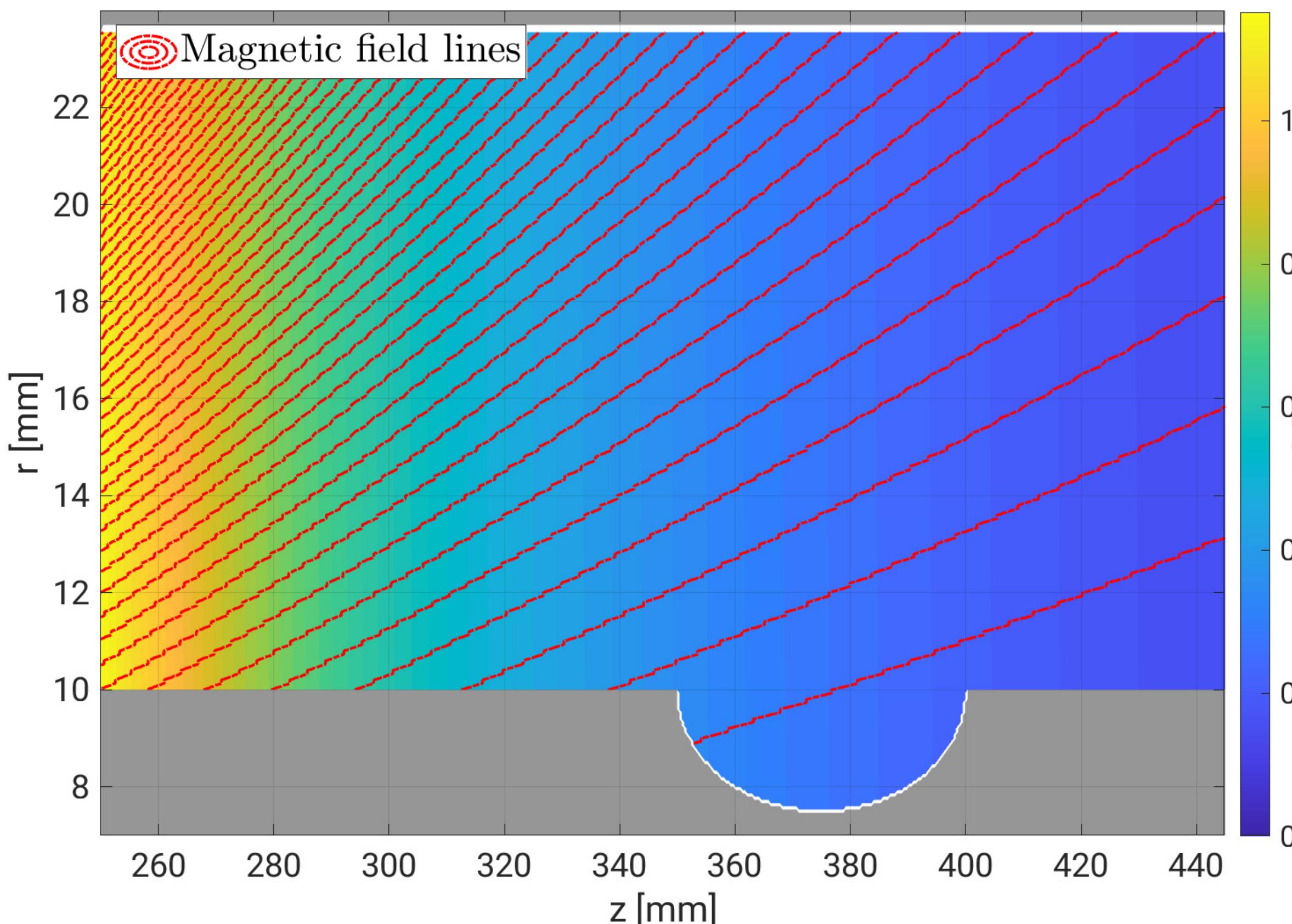
- Same cloud **densities**
- Same cloud **formation times**
- Current increased by  $\sim 40\text{-}50\%$



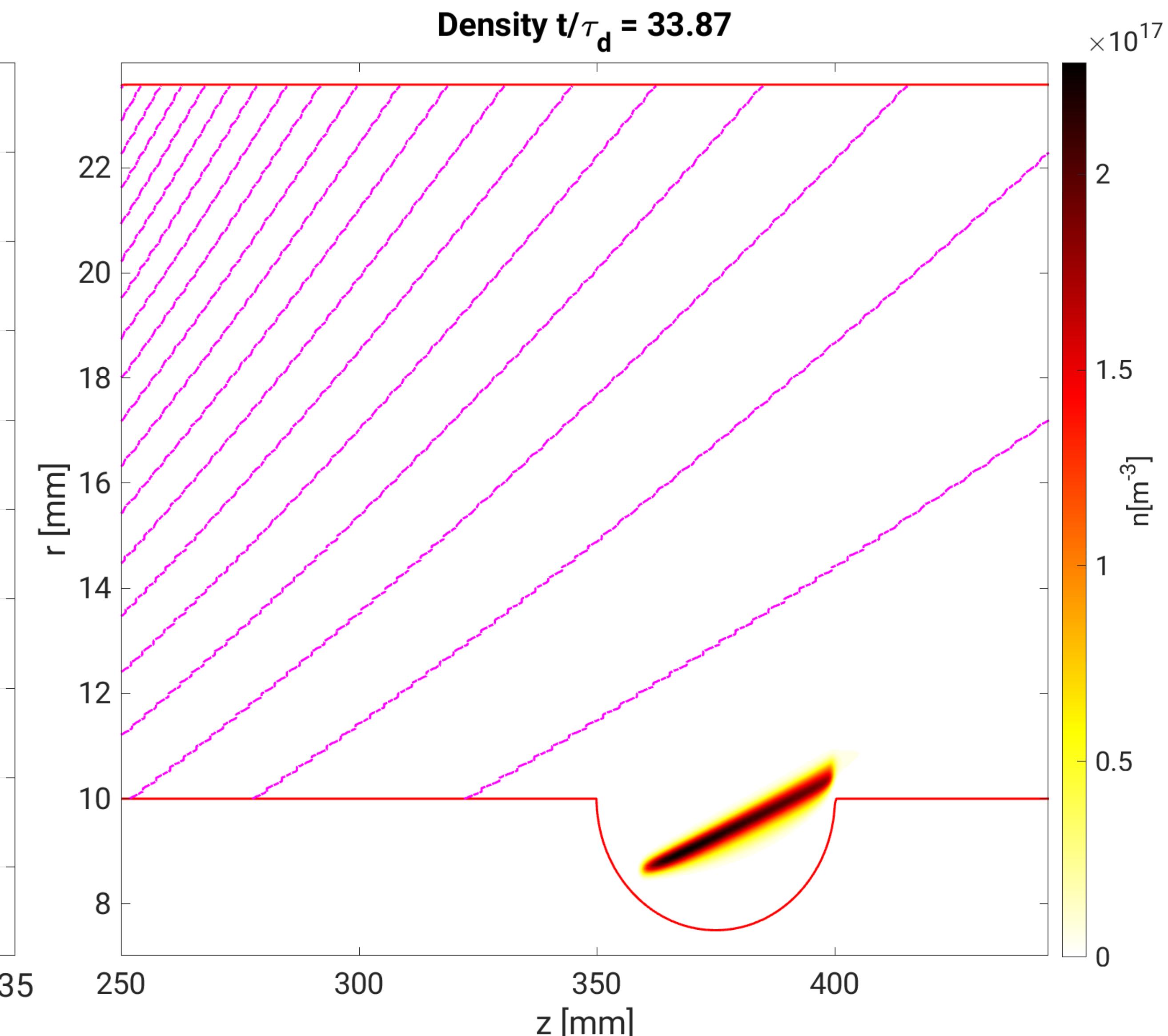
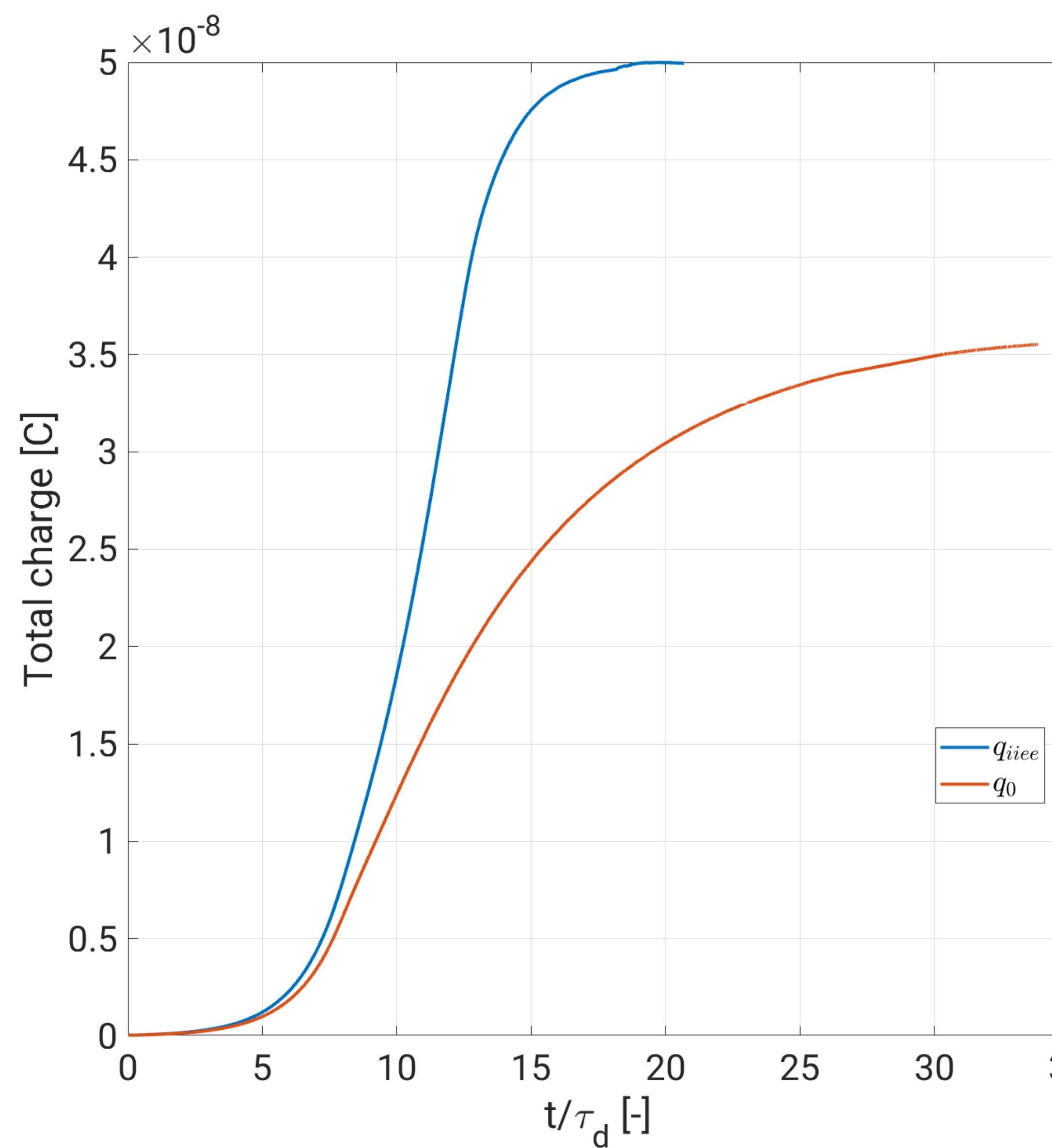
# EPFL Cloud formation and dynamics: TREX extrude geometry

- Physical/numerical parameters

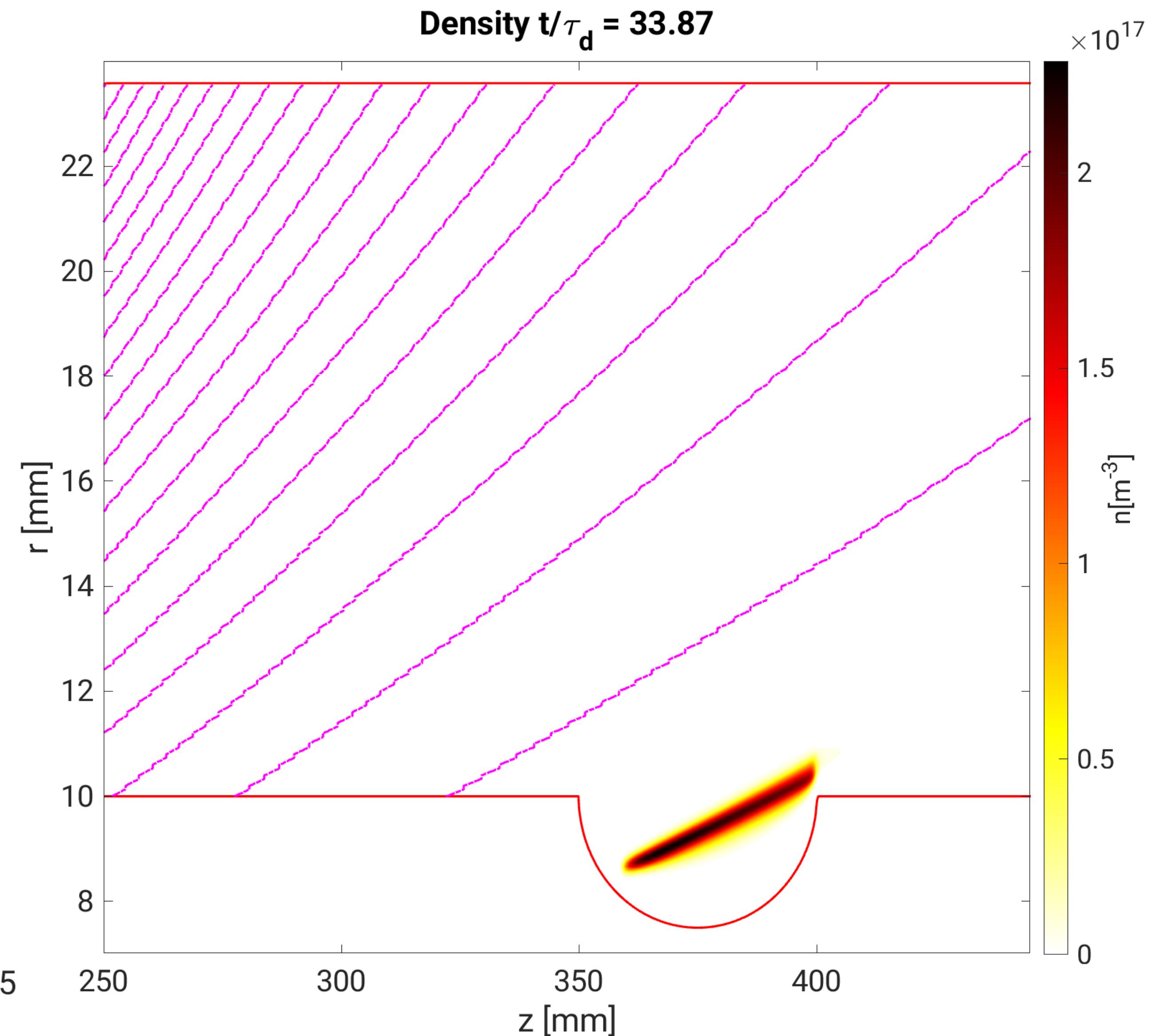
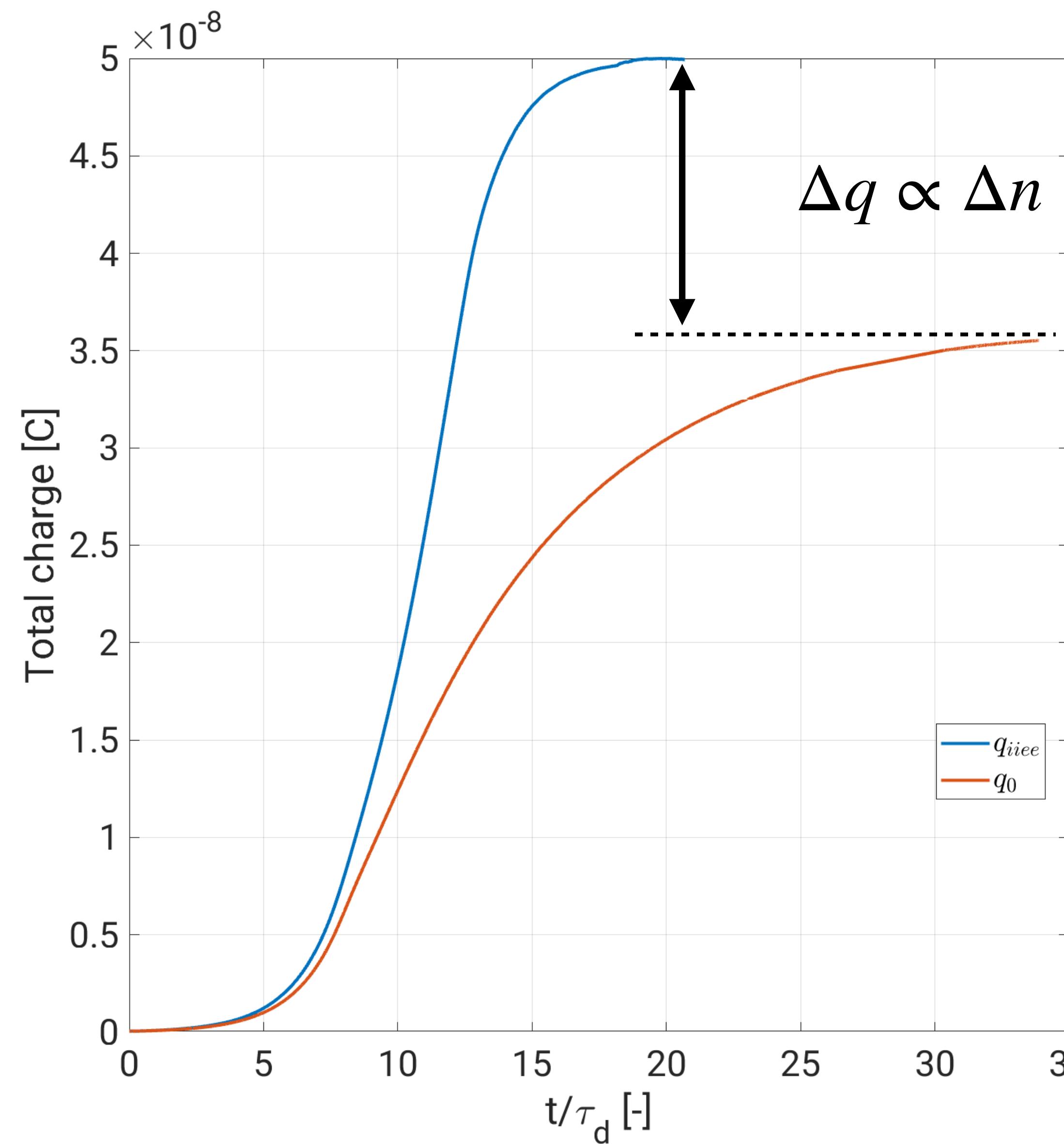
- $\Delta\Phi = 20 \text{ kV}$
- Neutral pressure  $P_n \sim 1 \cdot 10^{-2} \text{ mbar}$



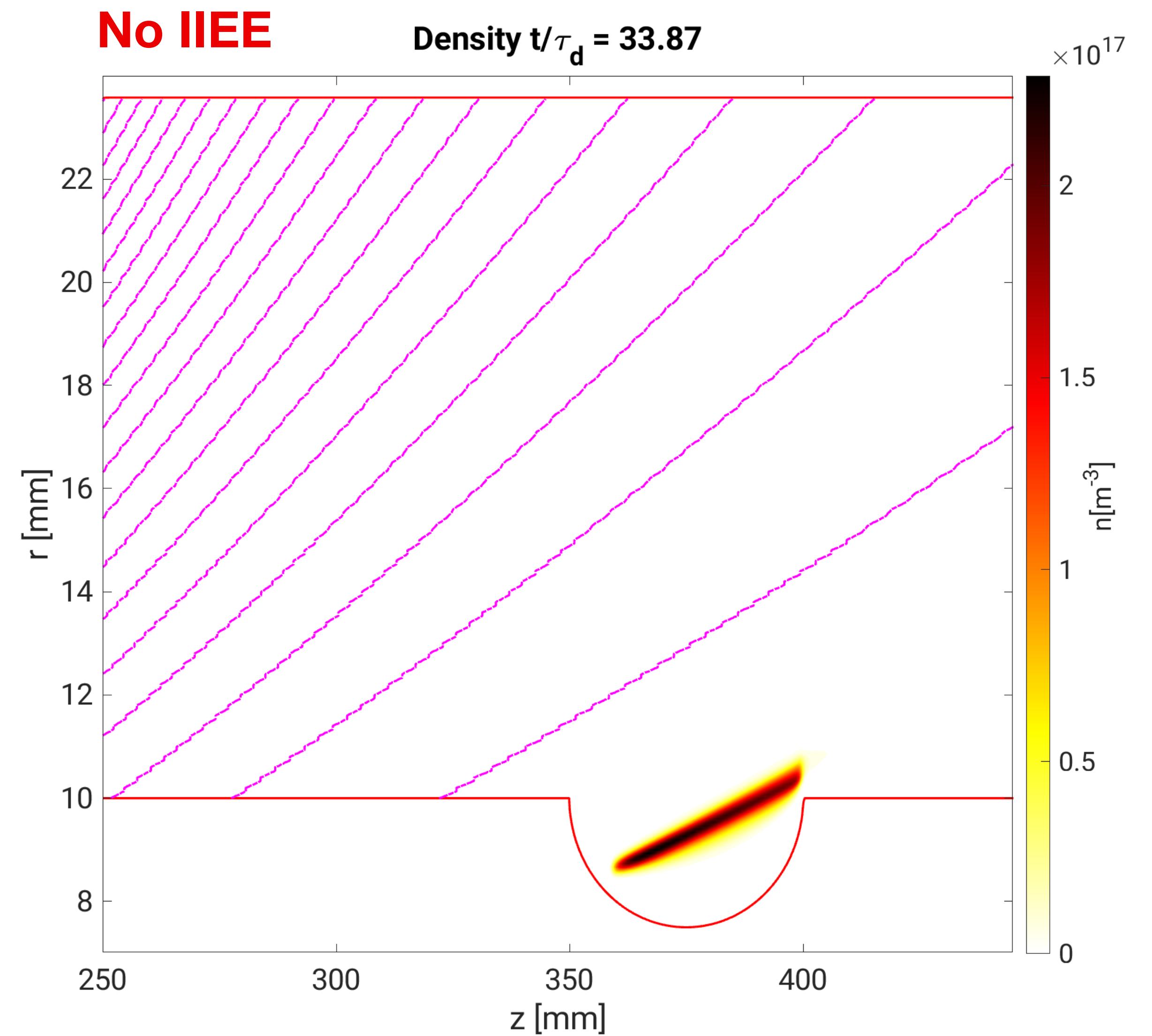
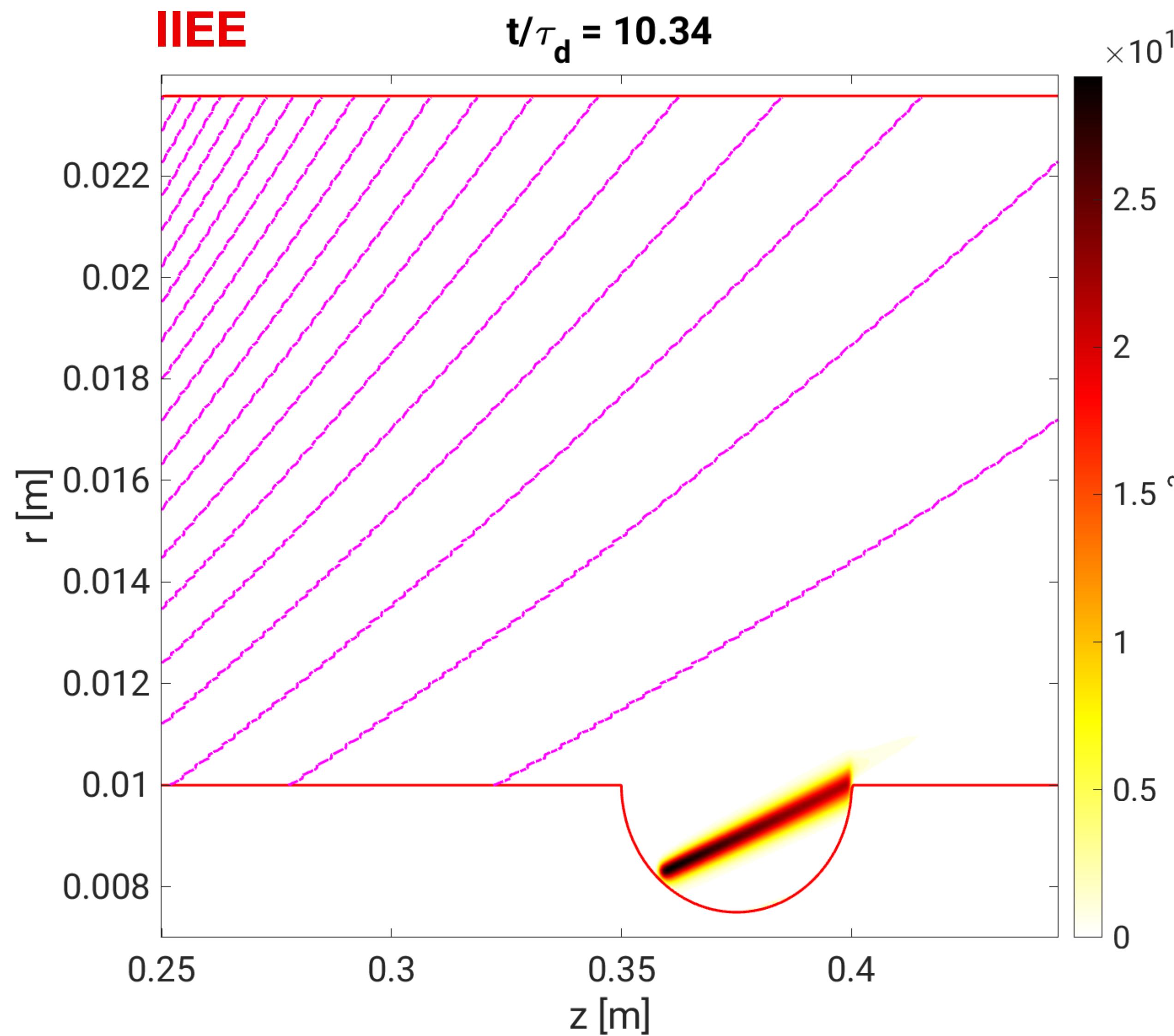
# EPFL TREX extrude geometry - total charge and cloud formation



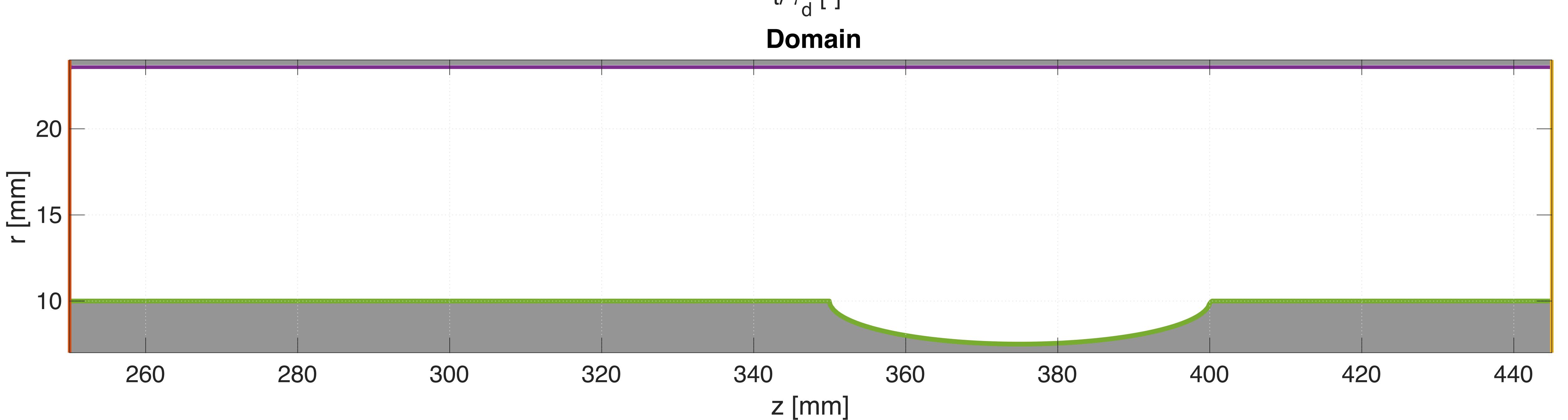
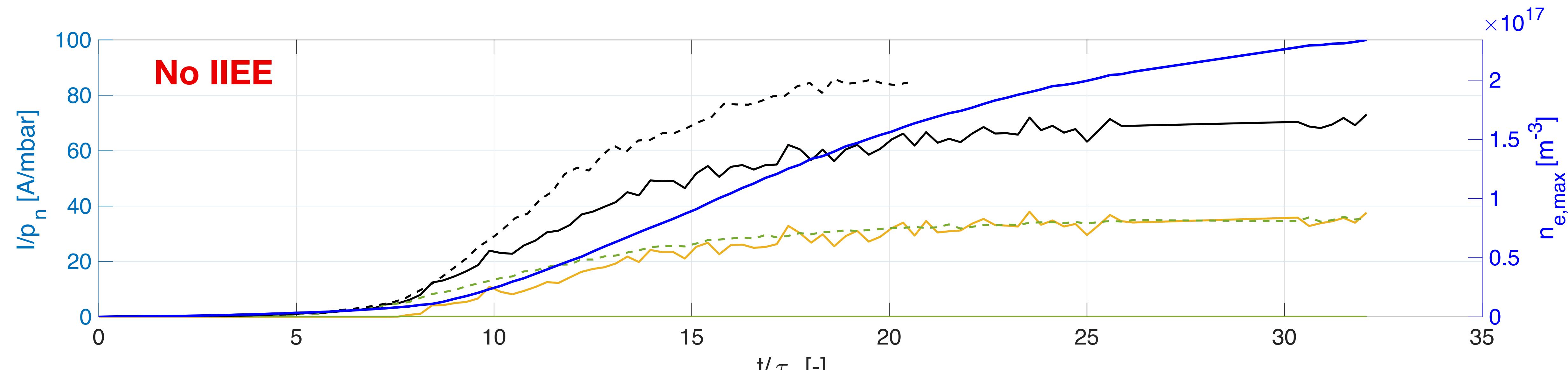
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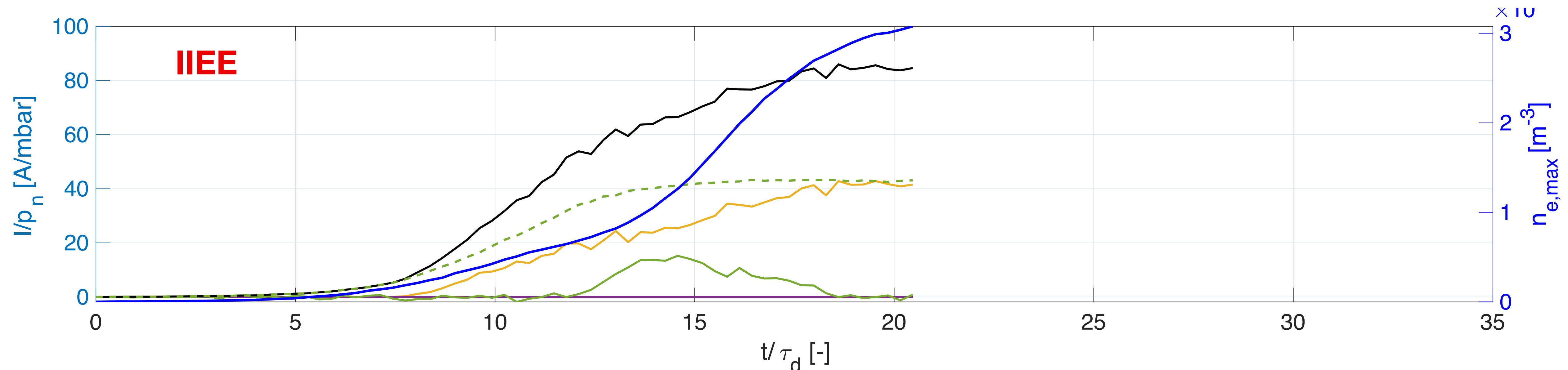
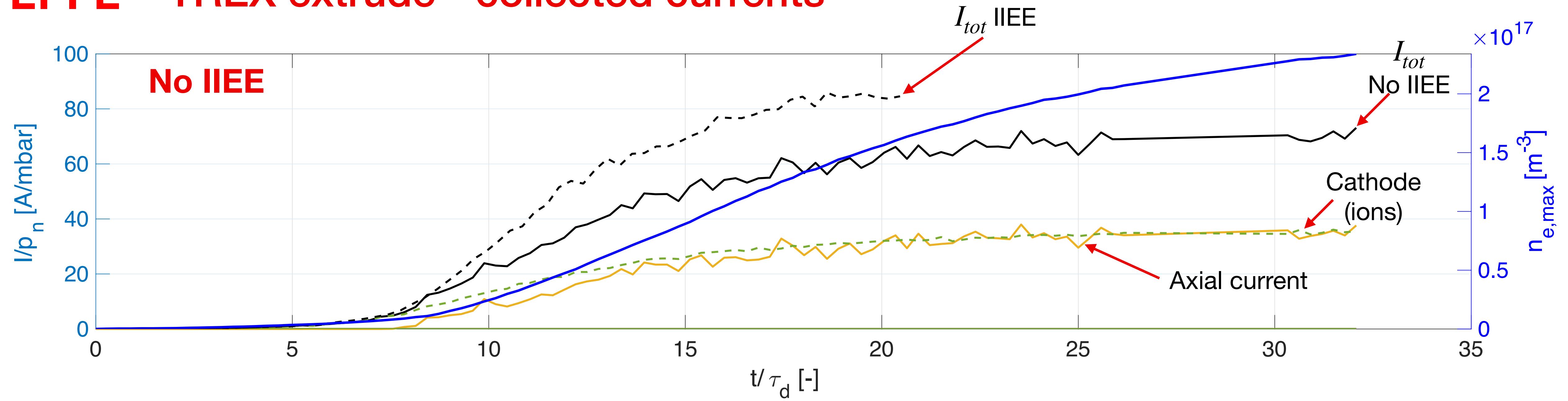
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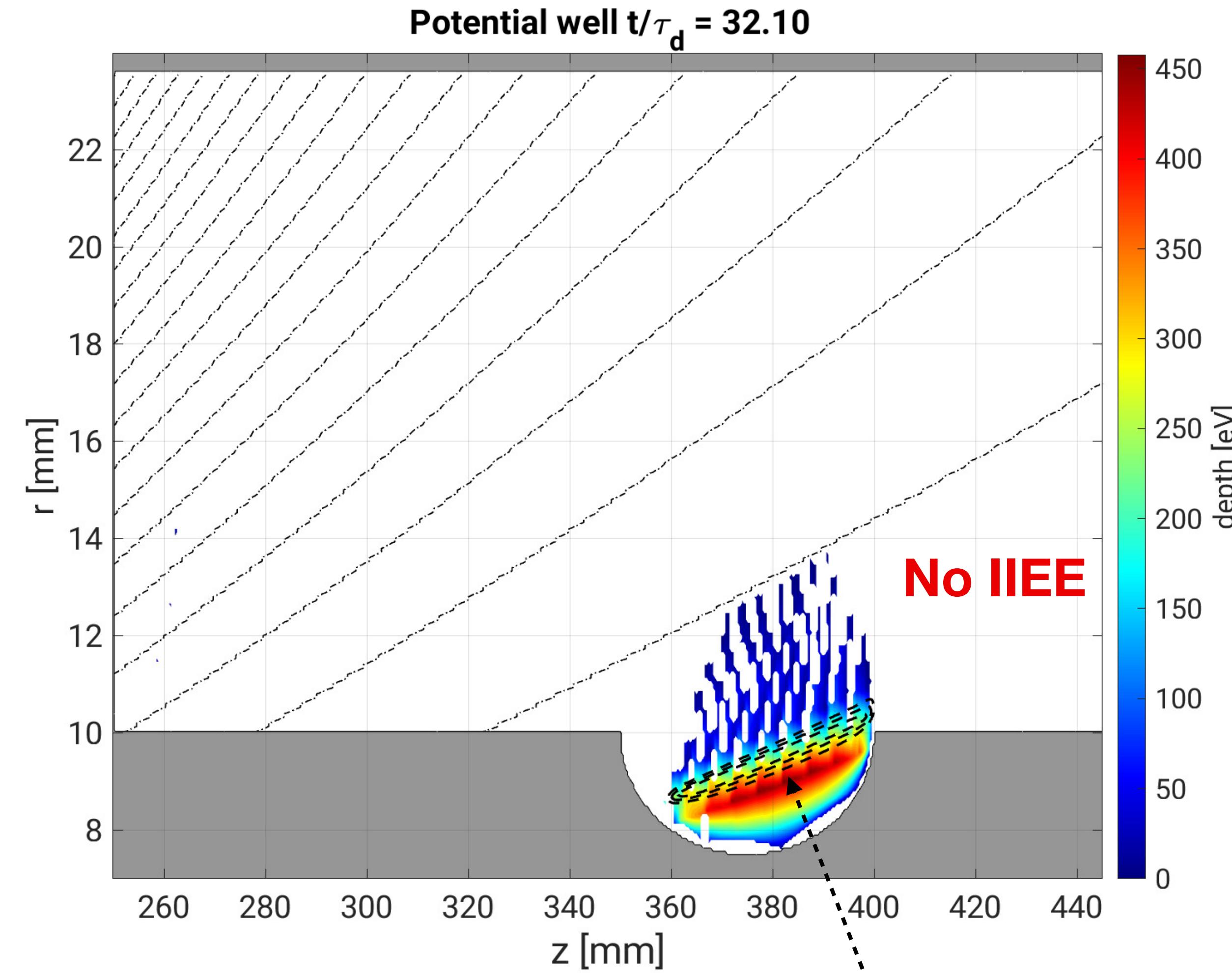
# EPFL TREX extrude - collected currents



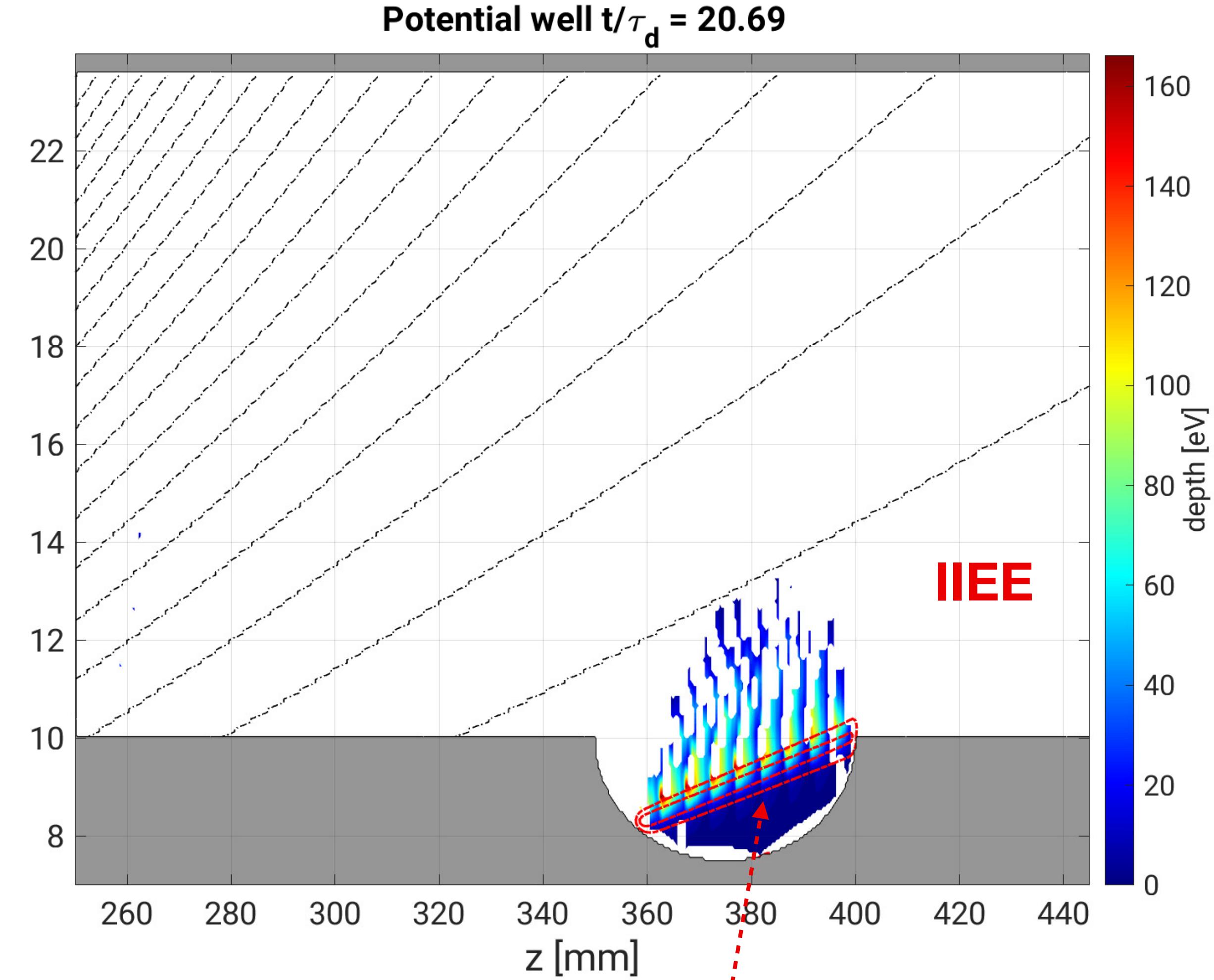
# EPFL TREX extrude - collected currents



# EPFL TREX extrude - potential wells and cloud contours

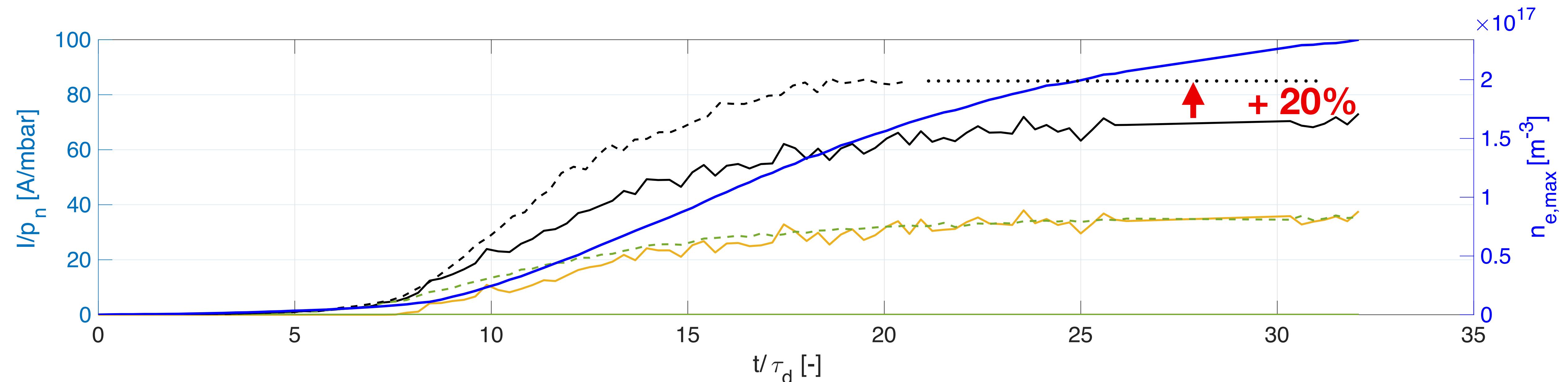


Cloud  
located higher



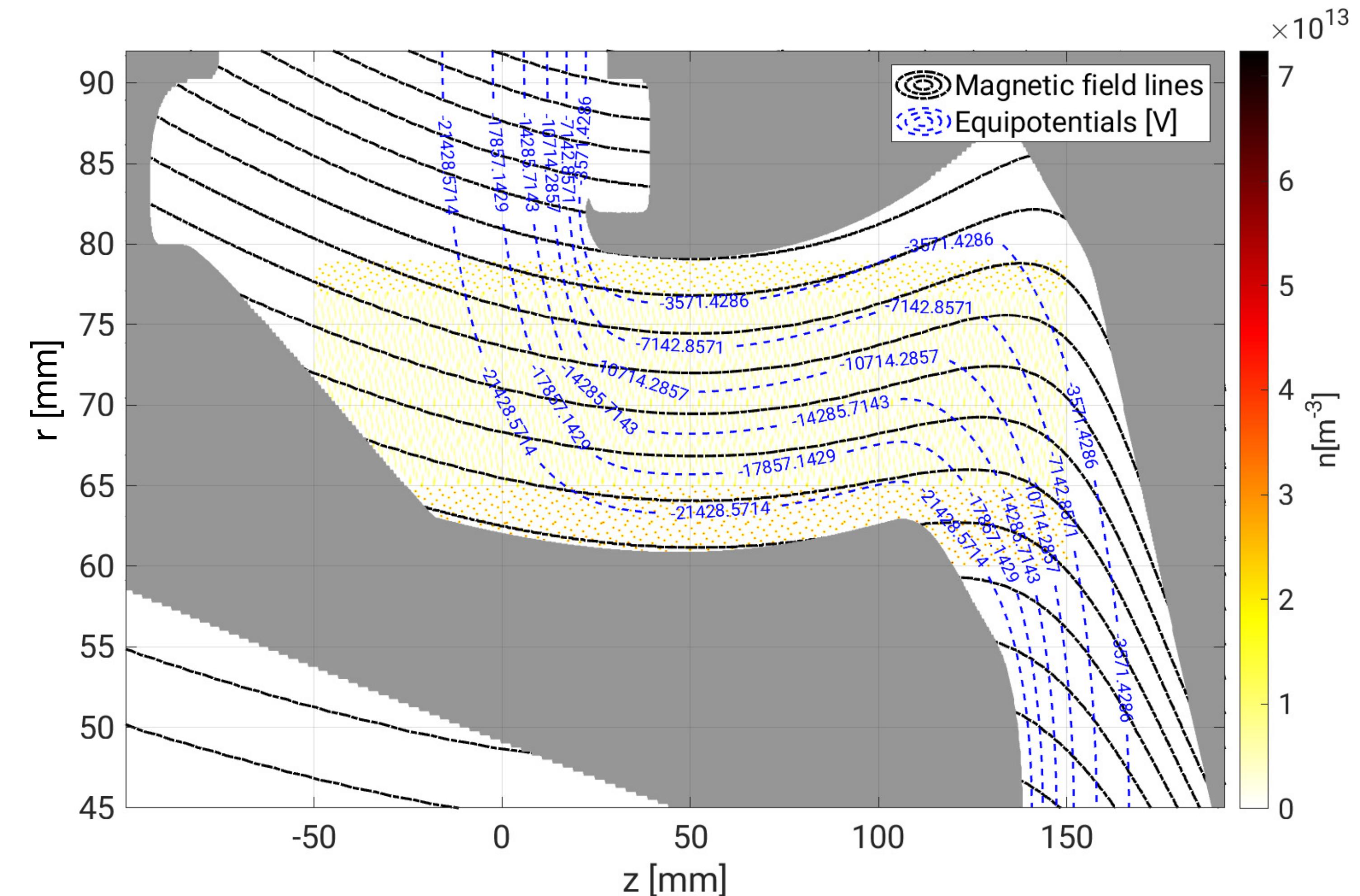
Cloud  
located lower

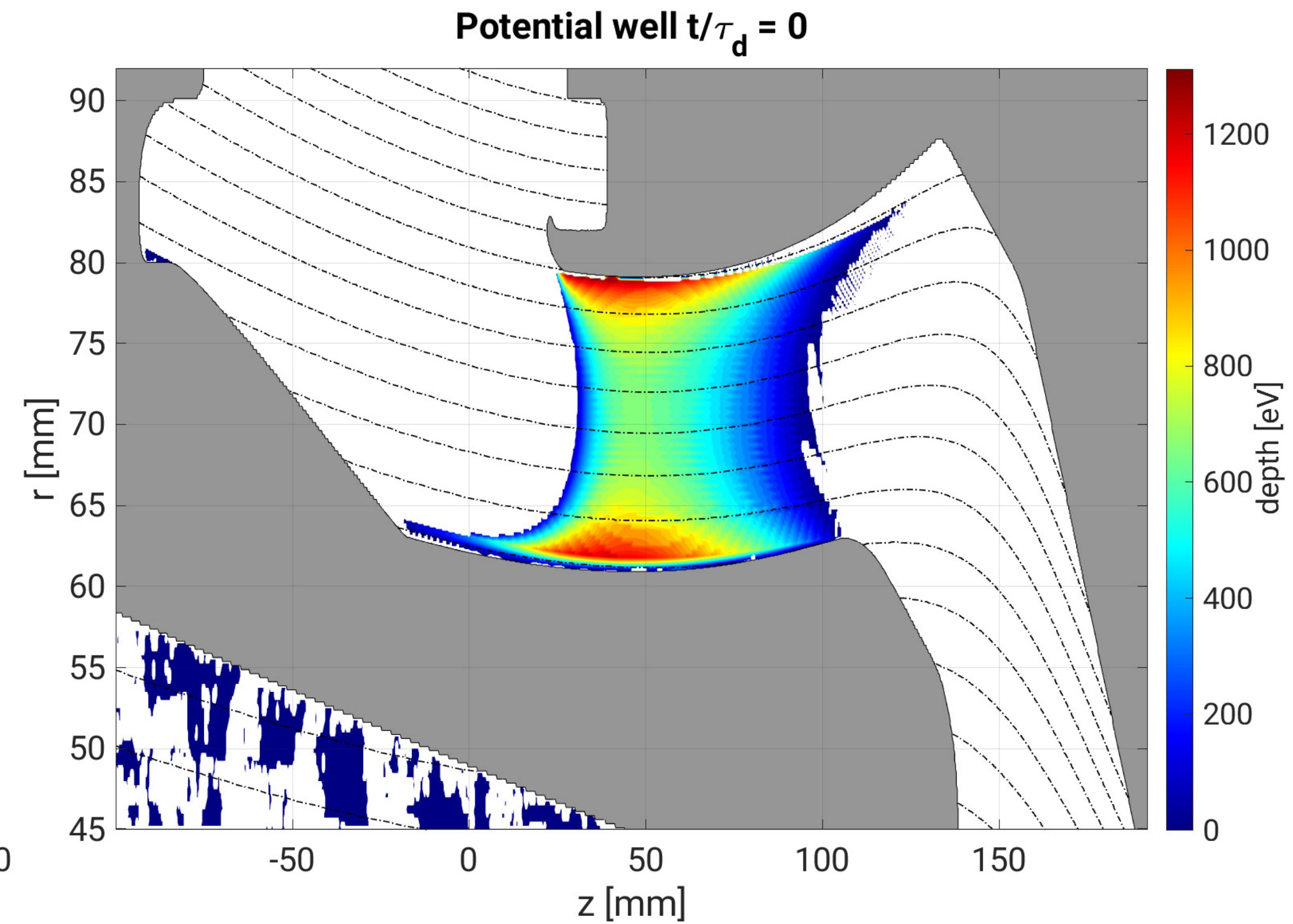
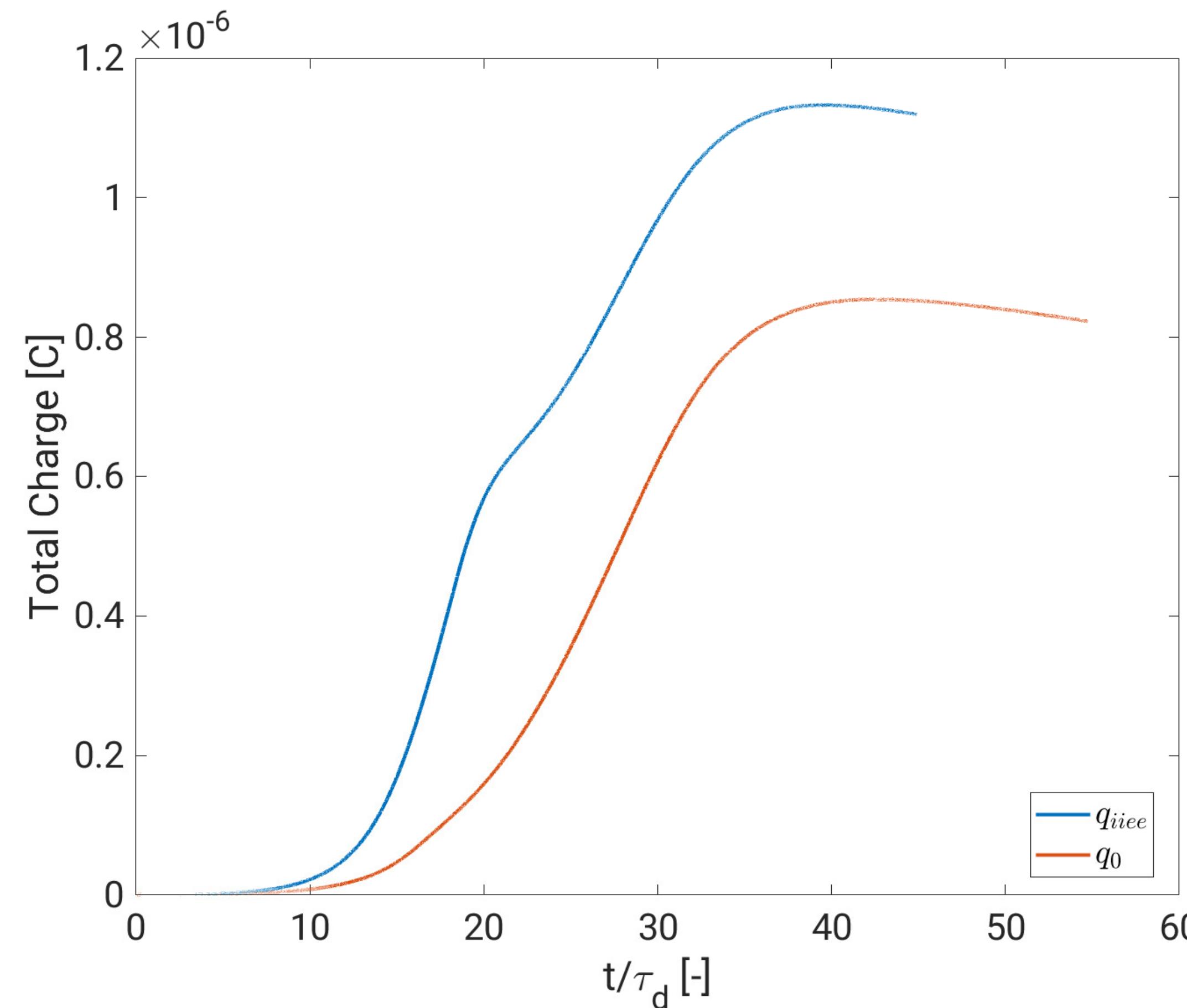
- Density increased by IIEE of 20%
- Cloud forming about 3 times faster
- Current increased by  $\sim 20\%$
- Cloud radially lower: well fills by bottom (IIE)

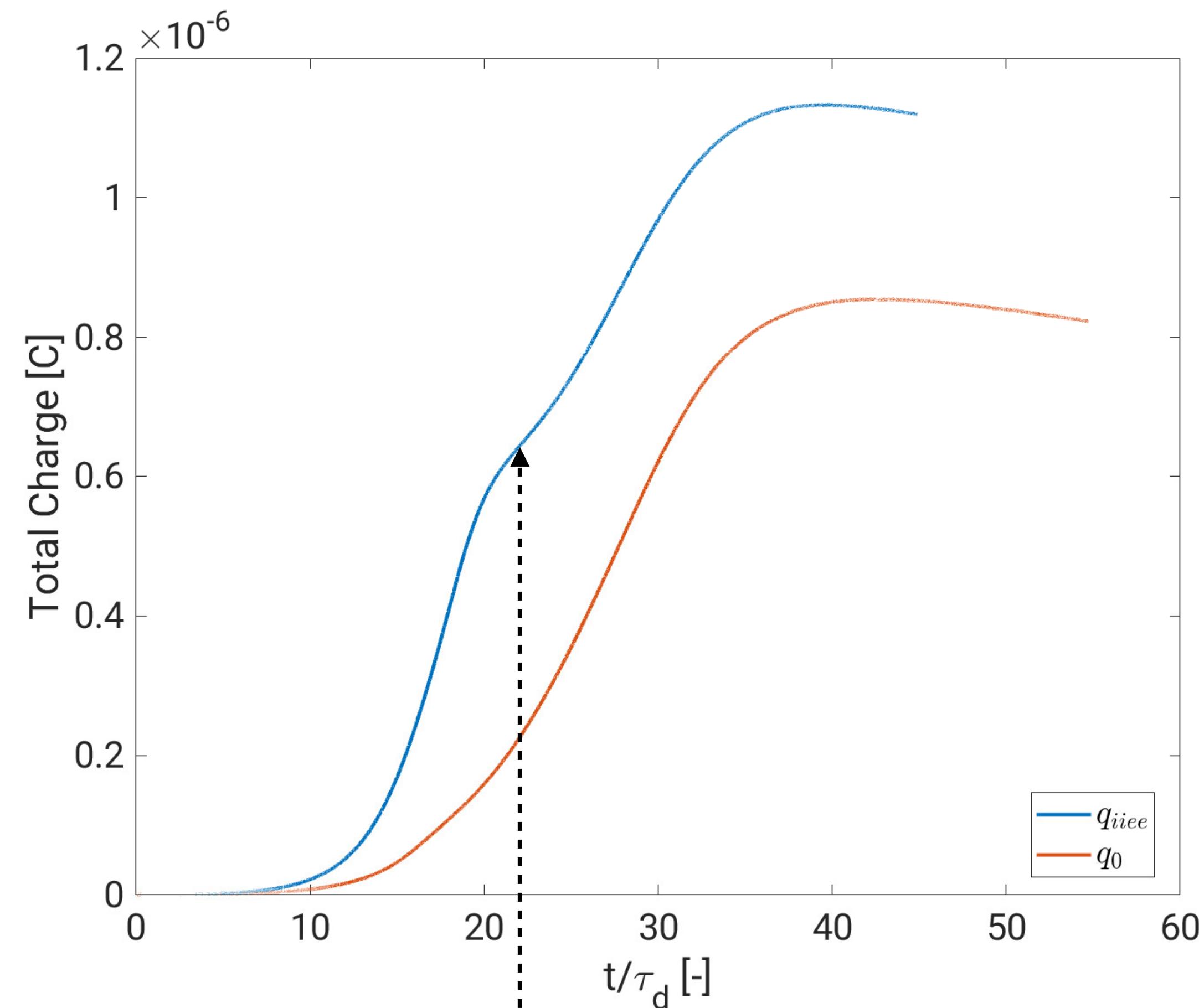


- Physical parameters

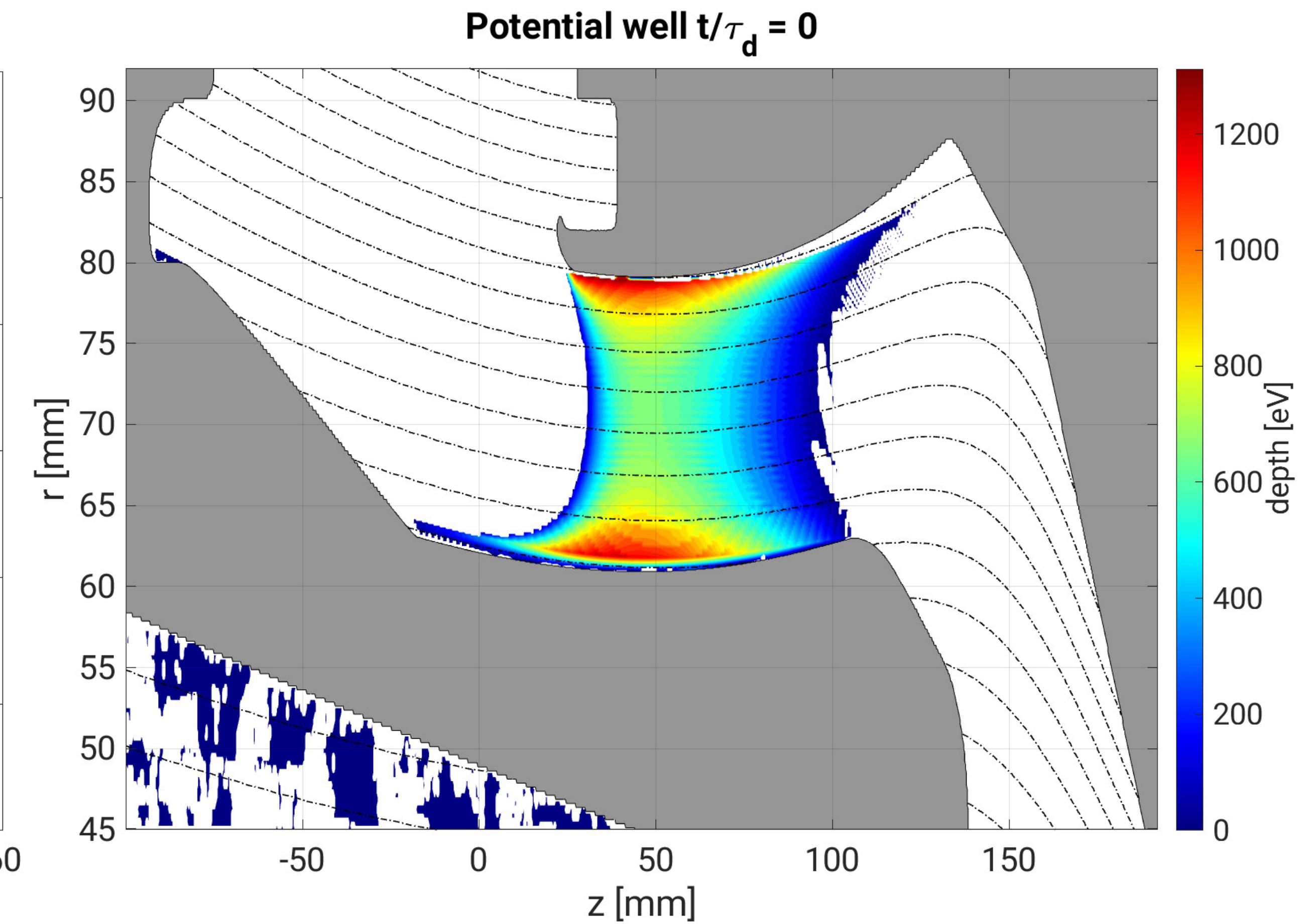
- $\Delta\Phi = 25 \text{ kV}$
- Neutral pressure  
 $P_n \sim 2 \cdot 10^{-2} \text{ mbar}$
- 2 potential wells formed by equipotentials and magnetic field lines



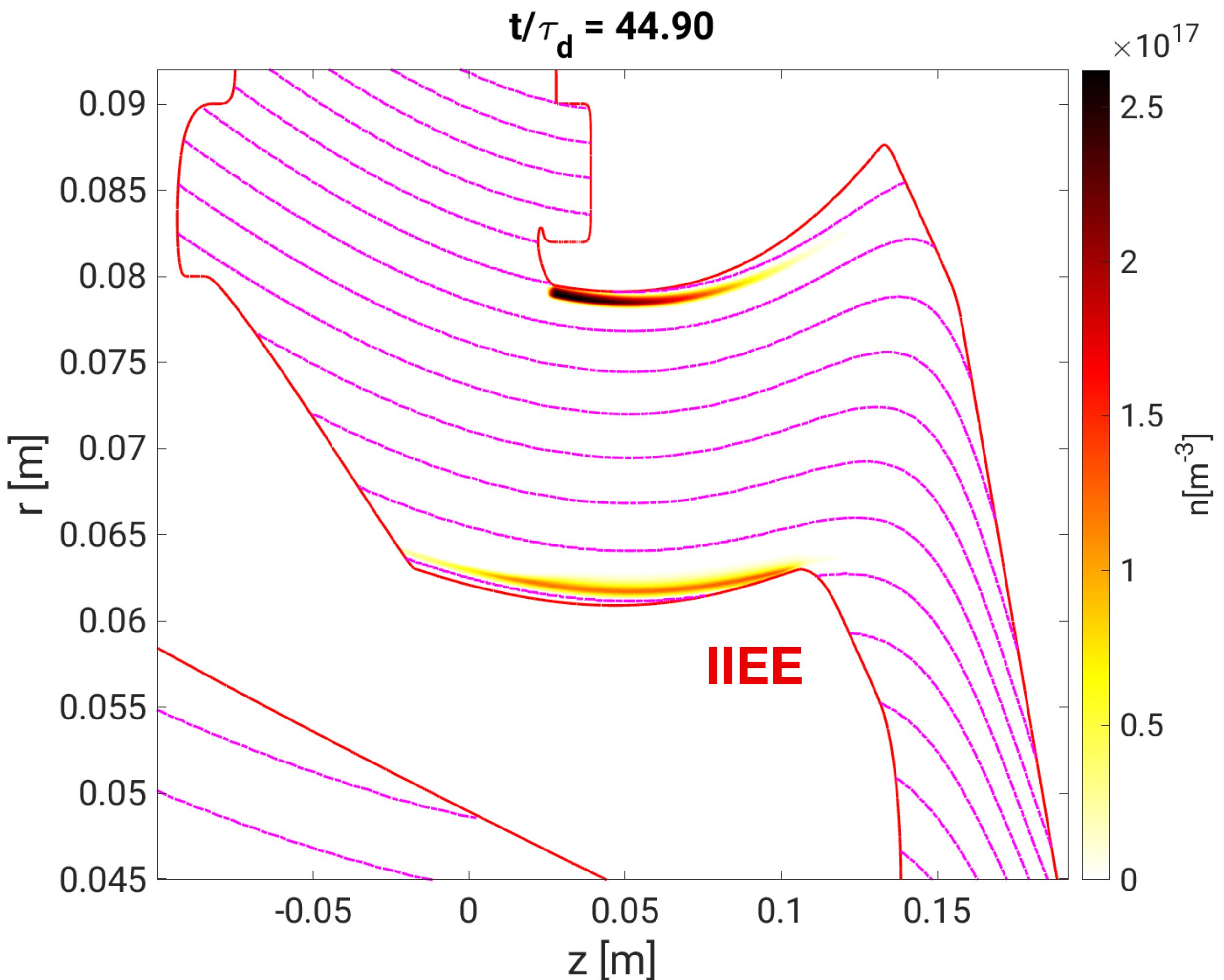
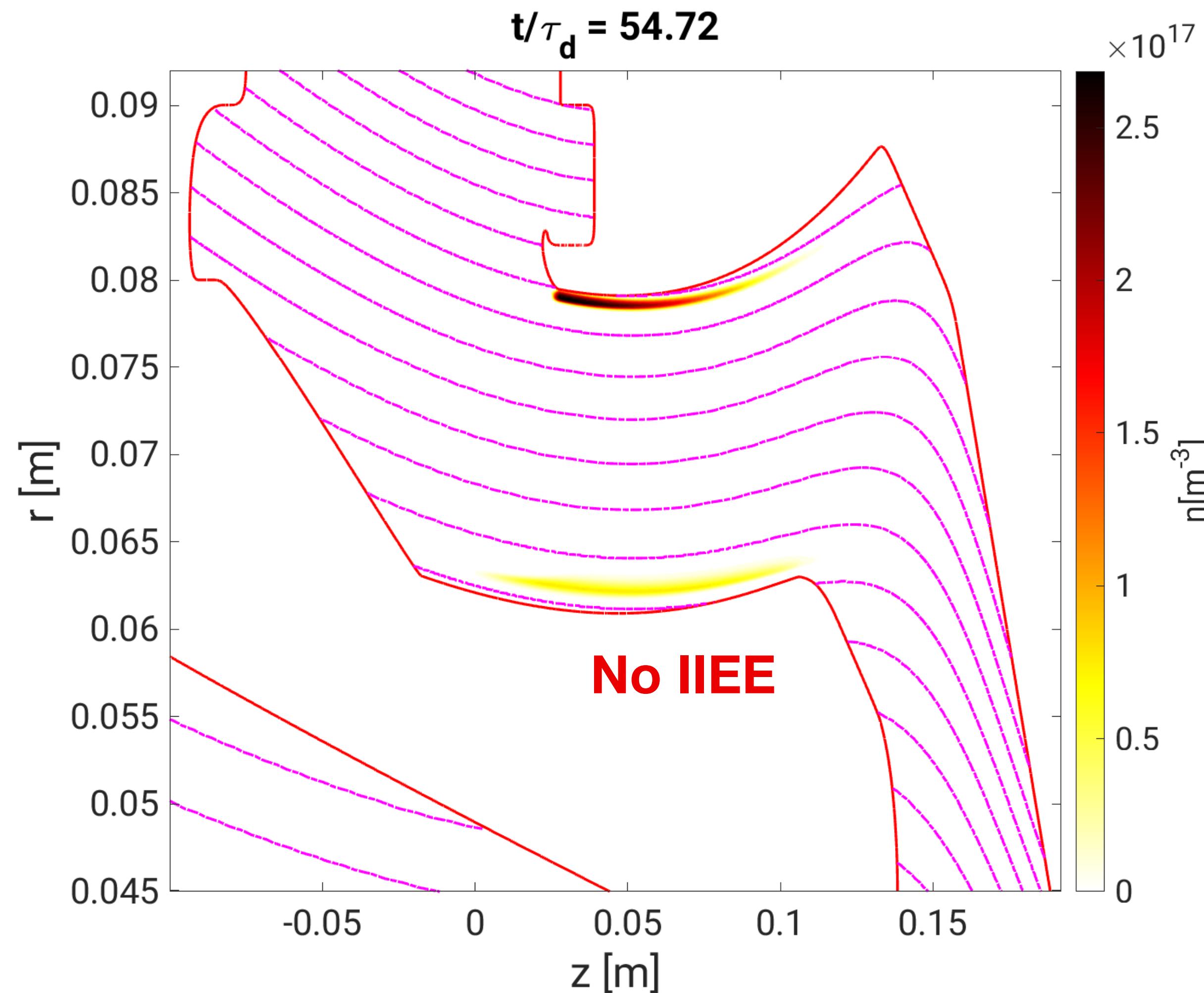




Bottom cloud filled first by IIE



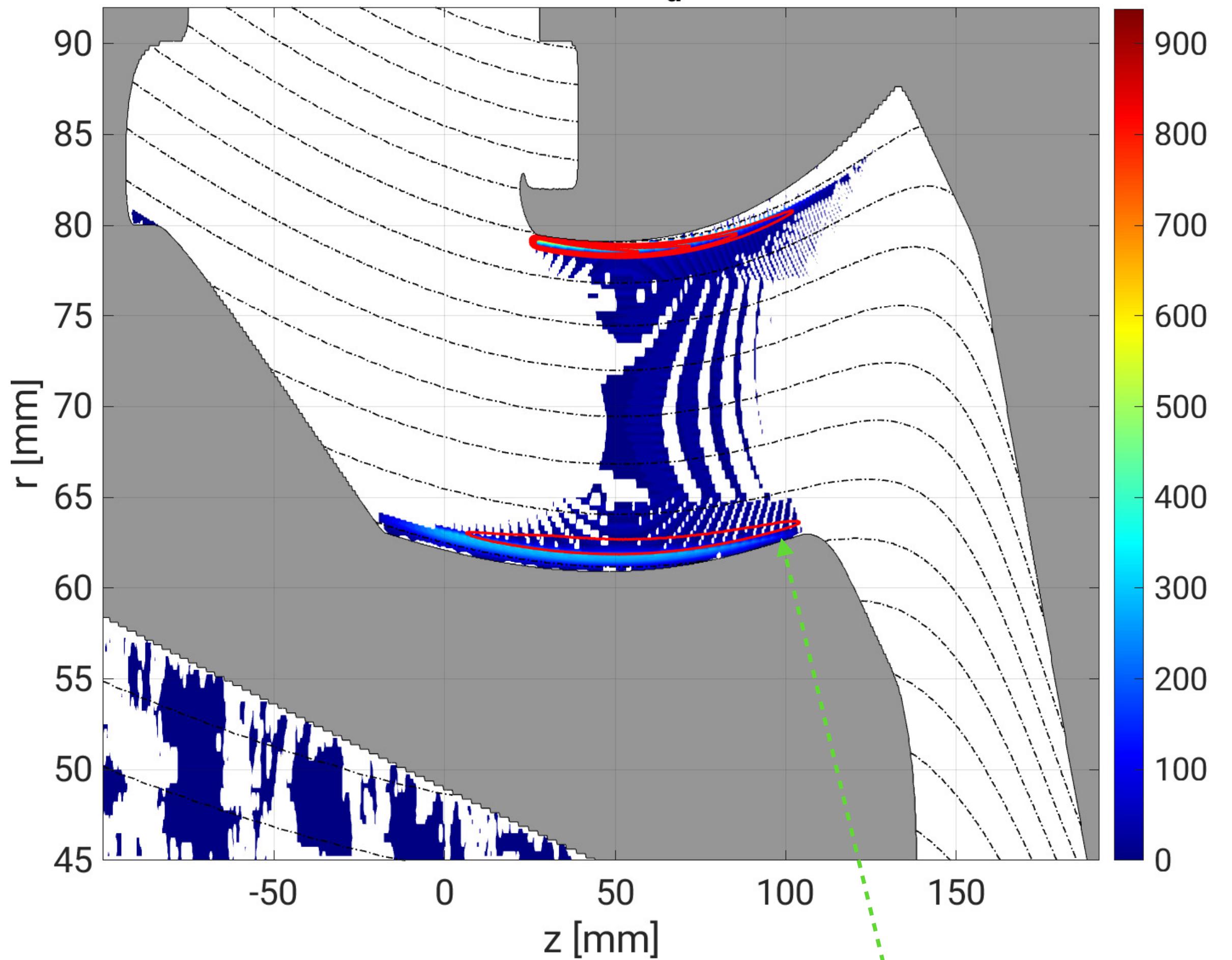
## Gt-170: Final densities (both)



# EPFL Gt-170: potential well and cloud contours

No IIEE

Potential well  $t/\tau_d = 54.72$

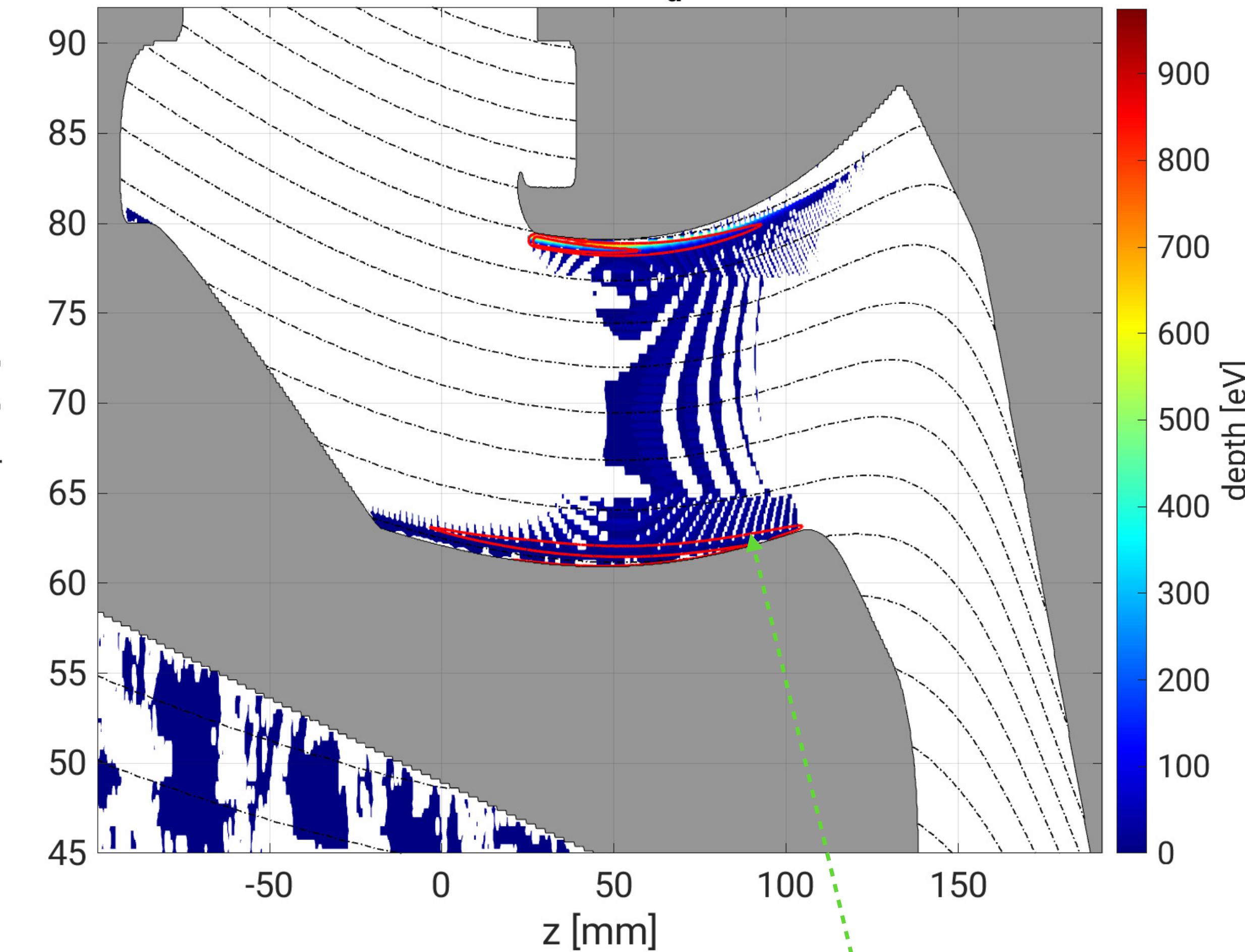


Bottom cloud  
located higher  
(See TREX extrude)

■ Swiss  
Plasma  
Center

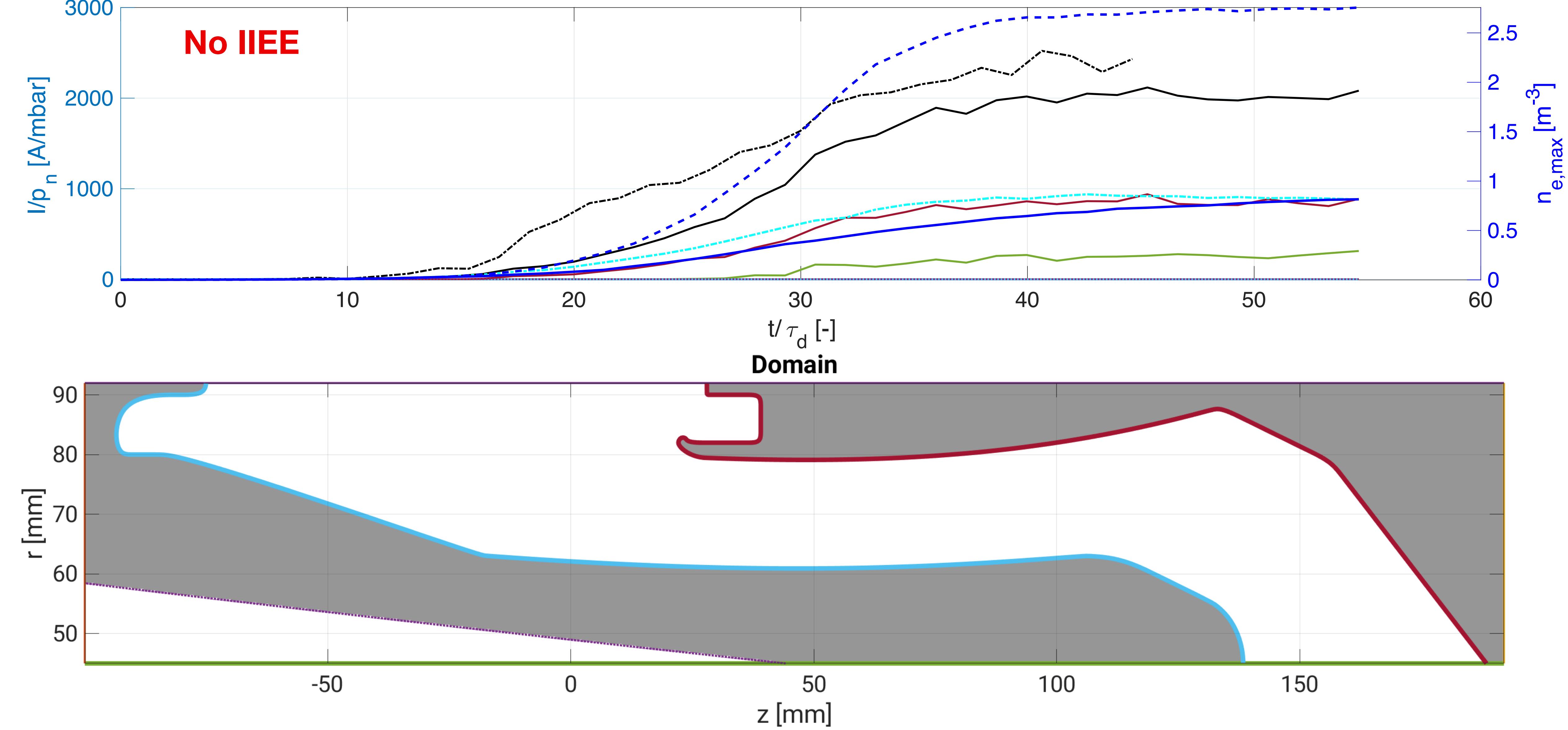
IIEE

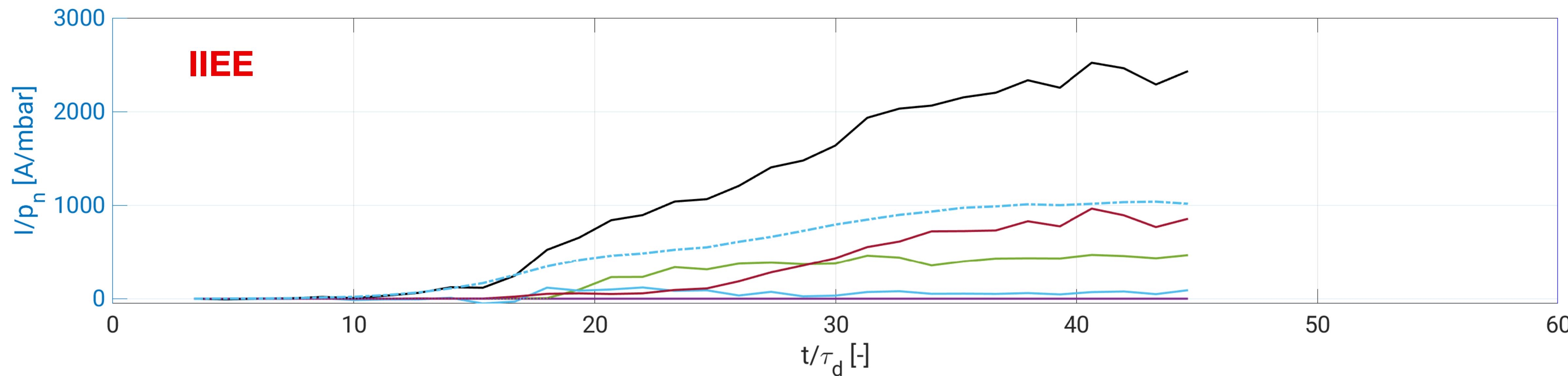
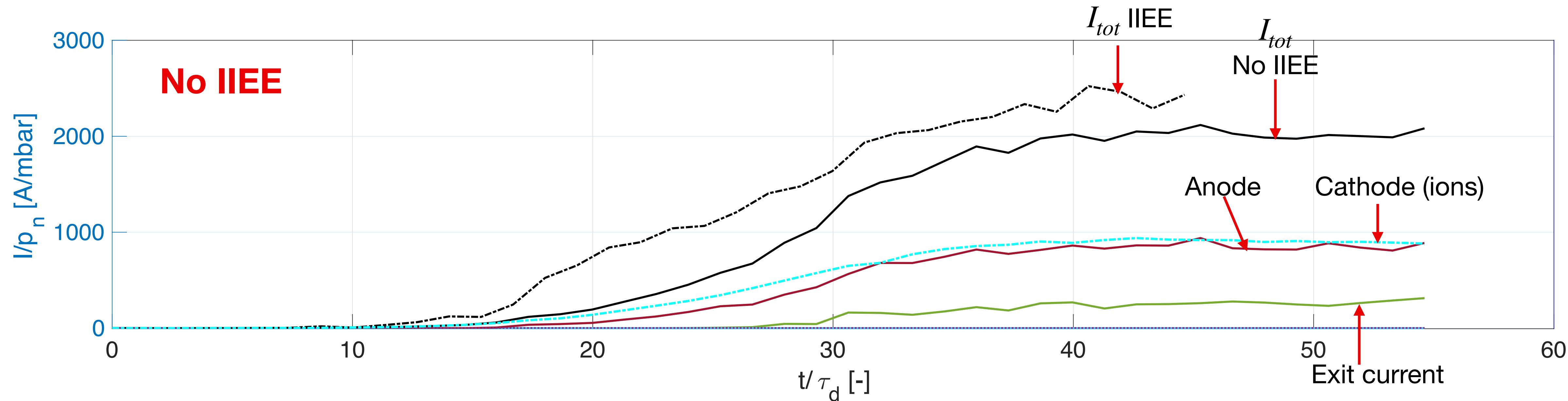
Potential well  $t/\tau_d = 44.90$



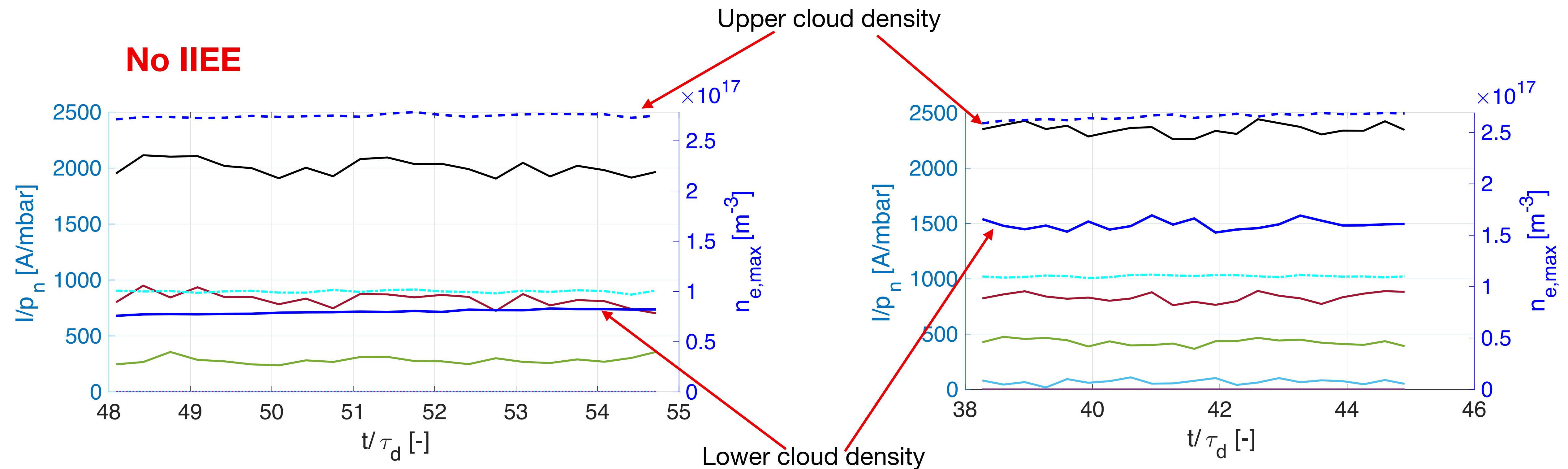
Bottom cloud  
located lower  
(See TREX extrude)

# EPFL Gt-170: collected currents (No IIIE)

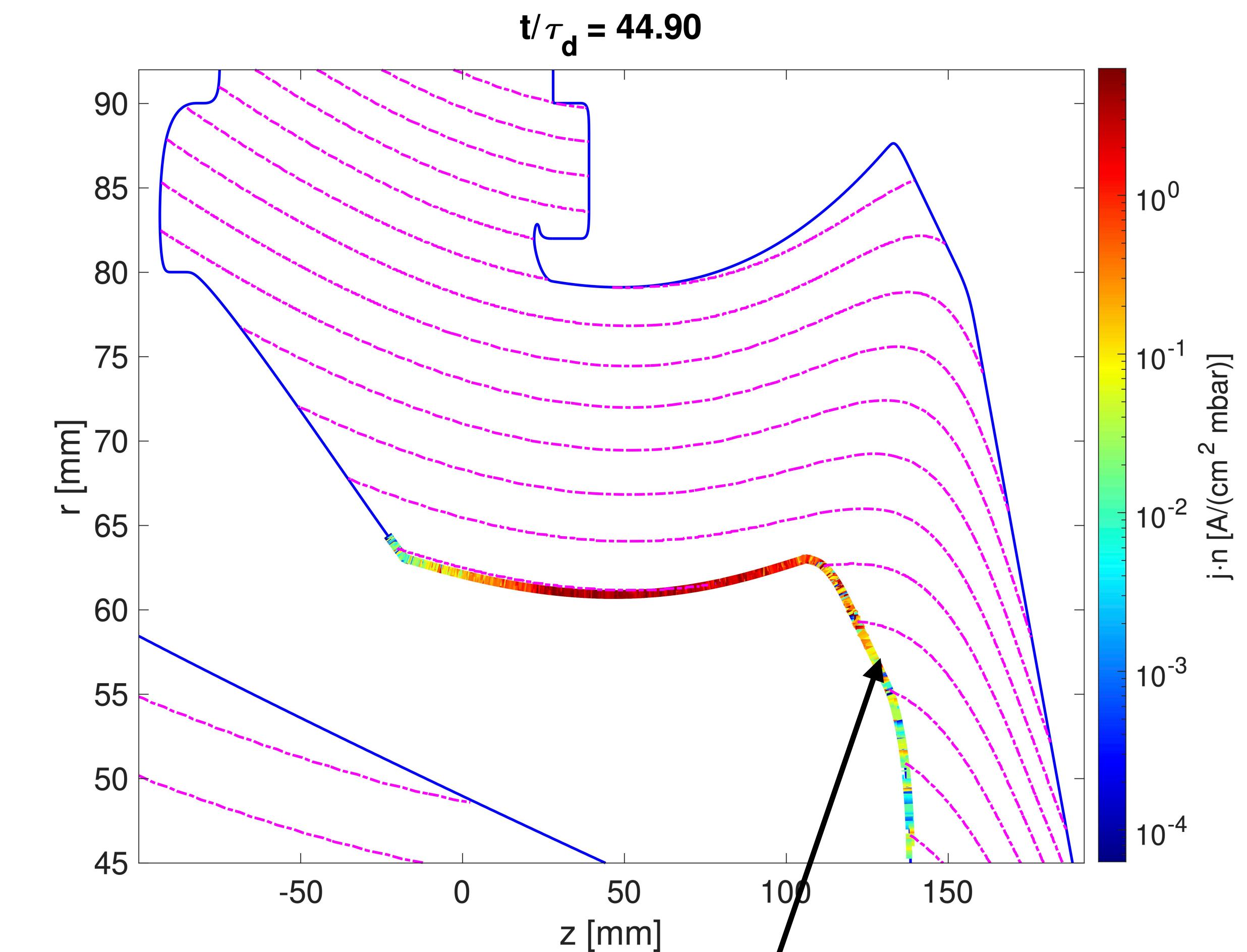
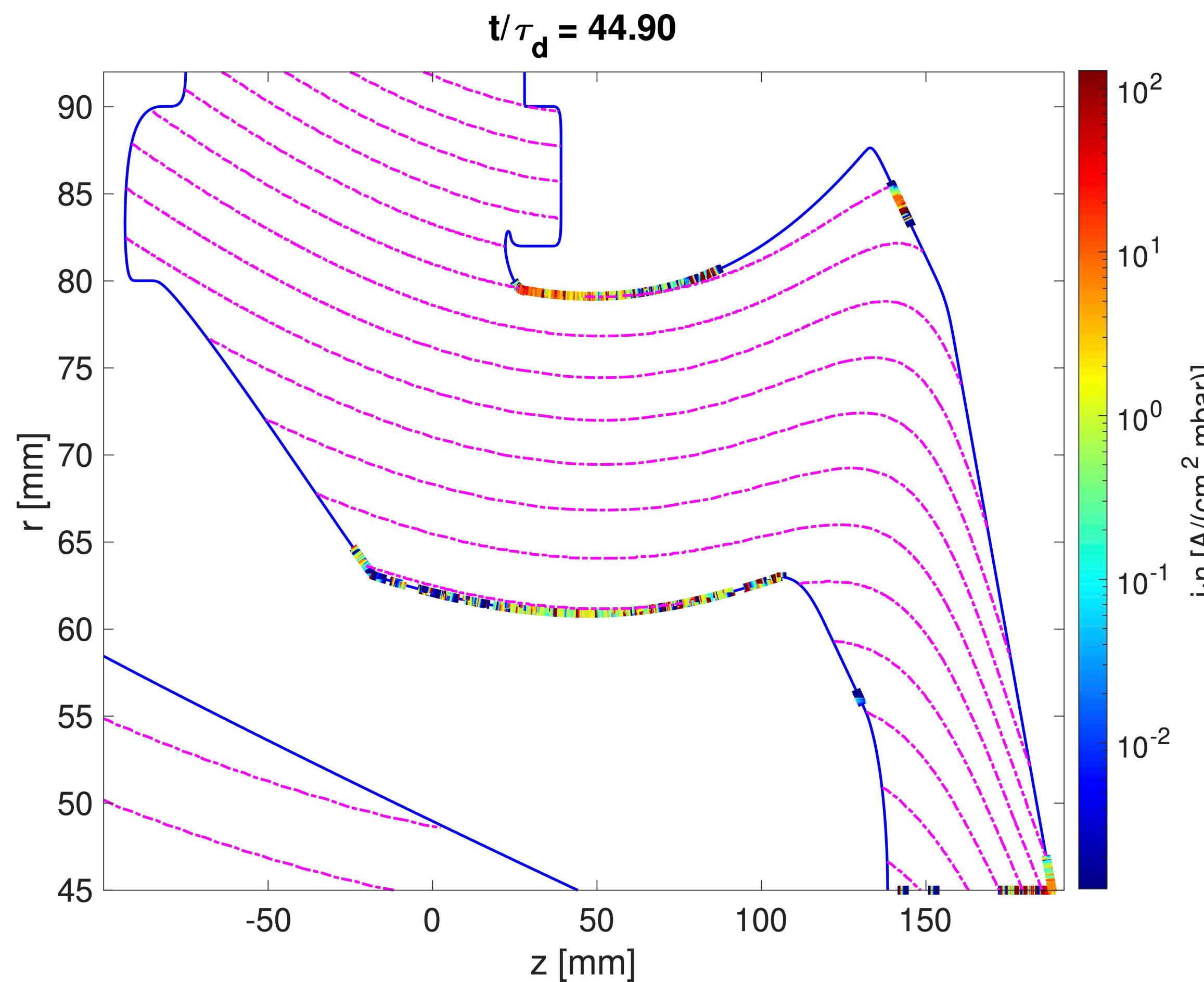




# EPFL Gt-170: Collected currents steady state (IIEE + no IIEE)



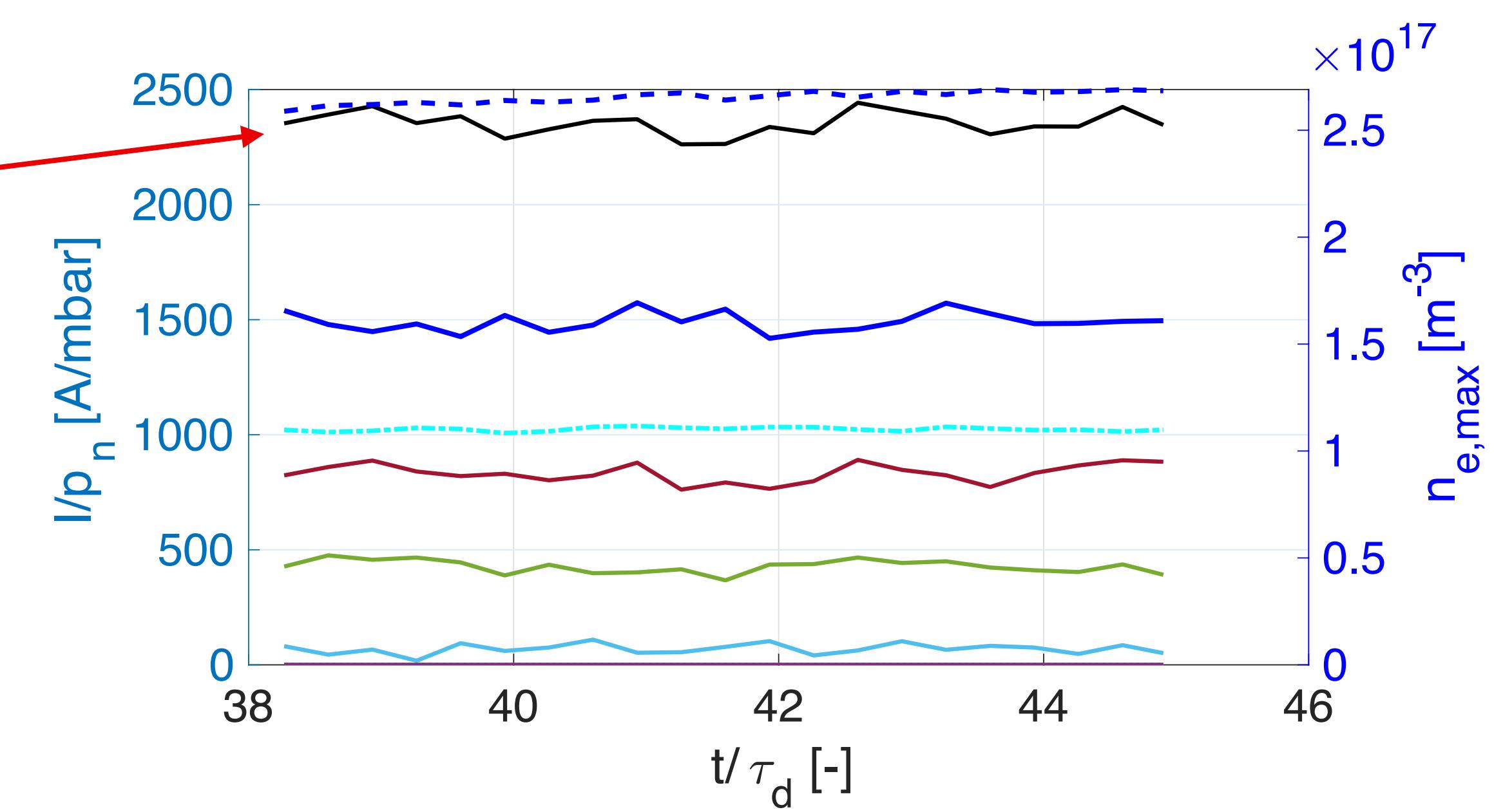
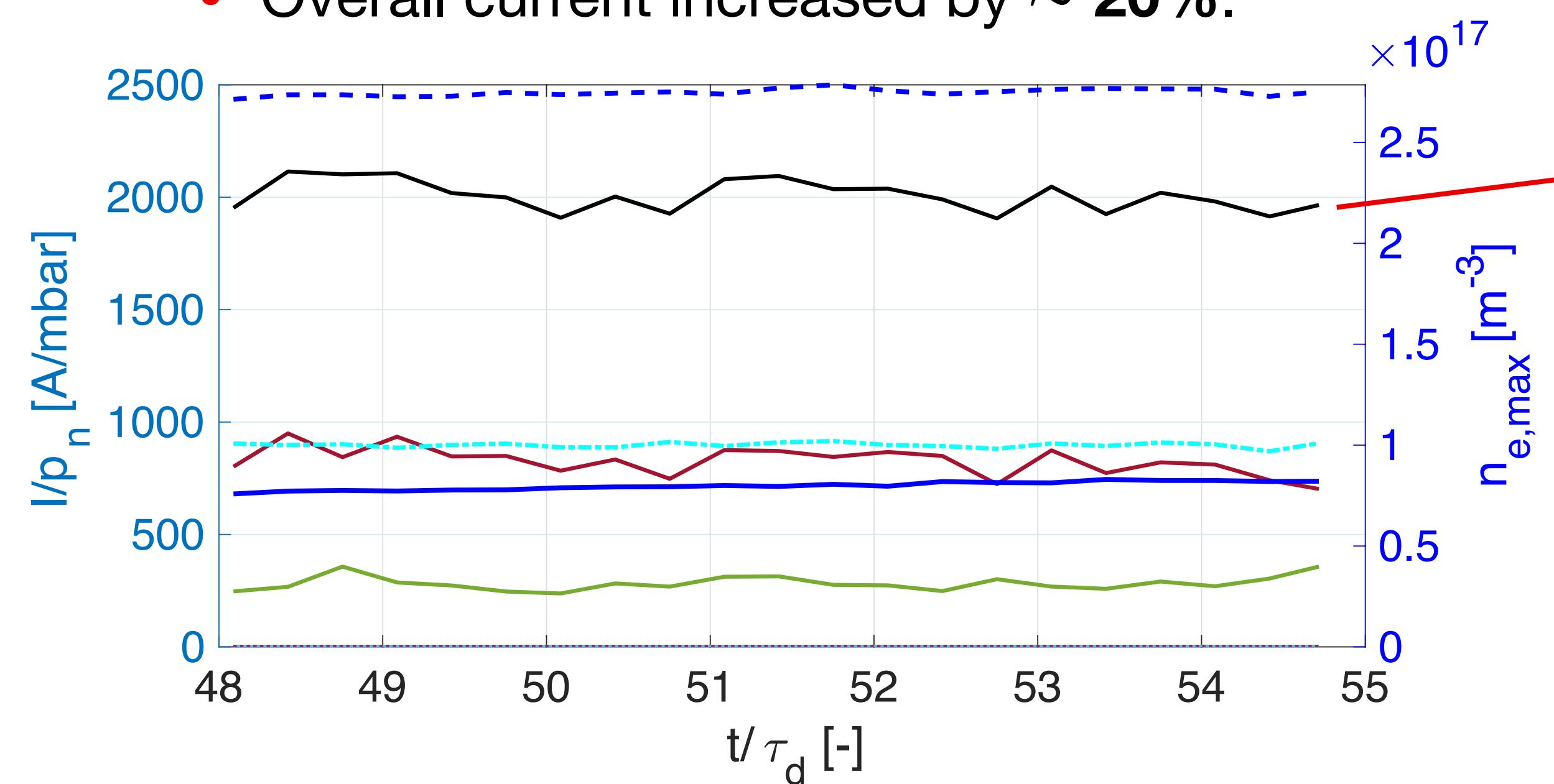
- Total current increased by about 20-25% (current from bottom well weaker).
- Bottom cloud density 2 twice as high as without IIEE.



- Potentially adiabatically trapped electrons generated ?

Emission of possibly  
adiab. trapped  $e^-$

- Density doubled in lower well.
- Bottom cloud lower (radially) - See TREX results.
- Same behavior for upper cloud.
- TREX design is appropriate to describe this type of MIG.
- Overall current increased by  $\sim 20\%$ .



- TREX slanted and extrude geometry succeeded at predicting results in more general MIG geometries (see GT-170).
- Overall, the total current measured was affected by IIEE, increasing (on average) by 20%.
- However, still same order of magnitude.
- Bottom cloud density (only) affected.
- Potentially some non-desired effects induced: generation of adiabatically trapped electrons ?

[DS]: Davidson. *Physics of Non Neutral Plasmas*.

[LB22]: Guillaume Le Bars. *Models, manual and validations for FENNECS code*, 2022.

[Kis73]: L. M. Kishinevsky. *Estimation of electron potential emission yield on metal and ion parameters*.

[DH]: D. Hasselkamp. *Particle Induced Electron Emissions II*. Springer Berlin. Heidelberg

[PPZ+16]: I. Gr. Pagonakis et al. *Electron trapping mechanisms in Magnetron Injection Guns*. Physics of Plasmas, 2016.

[Cern]: *A remedy against electron clouds inside particle colliders*, home.cern (online)

**Thank you !**